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INSTRUCTION MANUAL
MODEL 8210
F.M.-A.M. MODULATION METER

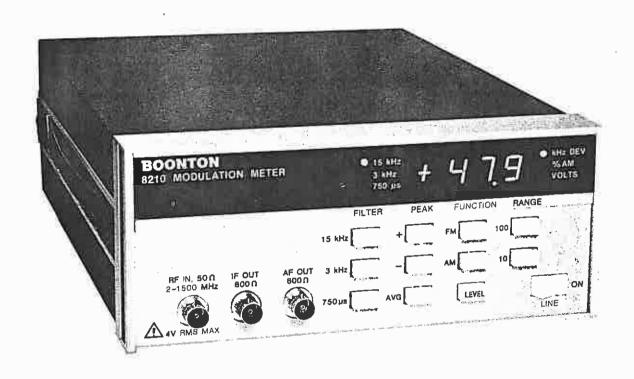


Figure 1-1. Model 8210 F.M.-A.M. Modulation Meter

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## S E C T I O N I

#### GENERAL INFORMATION

1-1. SAFETY NOTICE
The Model 8210 is furnished with a three-conductor power cable and threeprong plug so that, when the plug is inserted in a properly polarized a.c.
power receptacle, the instrument is grounded. The instrument depends upon
such connection to ground for equipment and operator safety.

\*\*\* WARNING \*\*\*

To avoid the possibility of electrical shock, before anything is connected to this instrument, and before you use this instrument, make certain that its power cable is plugged into a mating a.c. receptacle that has a grounded ("earthed") contact.

Never defeat the instrument's protective grounding. For example: Do not use an extension power cable if it is not equipped with a ground conductor; do not plug the instrument into an a.c. receptacle that does not provide a high-quality earth ground. If only a two-terminal a.c. power receptacle is available, use a three-prong-to-two-prong adapter and connect the ground wire of the adapter to the power-receptacle ground. Do not use such an adapter if the ground wire cannot be grounded.

#### 1-2. DESCRIPTION

The Model 8210 Modulation Meter, manufactured by Boonton Electronics Corp., is a versatile, solid-state instrument that measures and displays the deviation of frequency-modulated signals or the percentage modulation of amplitude-modulated signals over a carrier range of 2 MHz to 1.5 GHz. Both the a.m. and f.m. detectors of the 8210 are true peak-responding at all levels. Thus they conform to the basic definition of modulation depth or deviation. In addition, because the detectors are true peak-responding, the effect of any system noise will be accurately included in the measured value. Among the features of the Model 8210 are:

- a. Fully Automatic Tuning and Leveling. The Model 8210 will automatically acquire the largest signal present at the input connector and adjust its local oscillator, and the gain of its measurement channel, to provide a fully calibrated display of amplitude modulation or frequency modulation.
- b. Internal Calibration. Each time it is turned on, the 8210 calibrates both its a.m. and its f.m. detector.
- c. Digital Display. The 8210 presents recovered modulation on a 3-1/2 digit display, providing exceptional resolution and accuracy for modulation measurements.
- d. Pushbutton Operation. Selection of all operational parameters is made by means of pushbuttons, thus allowing fast measurement setup.
- e. Low Residual Modulation. The 8210's exceptionally low residual modulation permits accurate measurements of low-noise sources. Direct residual measurements are possible if an external r.m.s. detector is used.

The Model 8210 is intended for both laboratory and field application. It will also be especially useful in the design of, and for production-line and field-testing of, f.m. and a.m. transmitters and signal generators.

#### 1-3. ITEMS FURNISHED

The instrument is supplied complete with power cord. For making measurements the connection of various cables will be called for, depending upon the operating mode of the 8210. Required cable connections are discussed in paragraph 2.1d.

#### 1-4. OPTIONS AND ACCESSORIES

Option -01: With this option, the 15 kHz low-pass filter is replaced by a 30 kHz low-pass filter. See Specifications, below, for details.

Accessory 950027: This is a rack-mounting kit (not supplied as standard), for mounting a single 8210 to left or right of center.

1-5. ENVIRONMENTAL DATA, OPERATING AND STORAGE Temperature: Operating, 0 to +55°C Storage, -55°C to +75°C

### 1-6. SPECIFICATIONS R.F. INPUT:

Carrier-Frequency Range

2 MHz to 1.5 GHz

Tuning

Automatic

Sensitivity

10 mV, r.m.s., 2 MHz to 520 MHz 30 mV, r.m.s., 520 MHz to 1.5 GHz

Level Set

Automatic for levels up to 1 V

Maximum Safe Input

7 V, r.m.s.

Input Impedance

50 ohms, nominal

#### FREQUENCY MODULATION:

Maximum Deviation

150 kHz, peak

Deviation Ranges

10 and 100 kHz, full scale

Deviation Accuracy

1% of reading for modulation frequencies between 50 Hz and 5 kHz.

2% of reading, 5 kHz to 7.5 kHz.

NOTE: Peak residuals must be accounted for to obtain the above accuracies.

Modulation Bandwidth

<30 Hz to 15 kHz

Residual F.M.

(R.F. Level >100 mV)

With 3 kHz low-pass filter:

<150 Hz, r.m.s., at 1.5 GHz, decreasing

linearly to a floor of <5 Hz, r.m.s.

With 15 kHz low-pass filter:

<200 Hz, r.m.s., at 1.5 GHz, decreasing linearly to a floor of <15 Hz, r.m.s.

A.M. Rejection

<100 Hz deviation at 50% a.m. (modulation
frequency < 1 kHz) 3 kHz low-pass filter.</pre>

§1-6, Continued.

#### AMPLITUDE MODULATION

Modulation-Depth Ranges 10% and 100%, full scale

Depth Accuracy

	racy
10% to 90% A.M.	
1% of reading	3% of reading
2% of reading	6% of reading _
	0% to 90% A.M.

NOTE: Peak residuals must be accounted for to obtain the above accuracies. Carrier frequency <520 MHz; r.f. level between -10 and +10 dBm.

Modulation Bandwidth

<30 Hz to 15 kHz.

Residual A.M.

With 3 kHz low-pass filter: Less than 0.15% a.m., r.m.s., for input levels above 100 mV, r.m.s.

With 15 kHz low-pass filter: Less than 0.25% a.m., r.m.s., for input levels above 100 mV, r.m.s.

NOTE: Carrier frequency <520 MHz; above 520 MHz residuals increase linearly with frequency.

F.M. Rejection

Less than 1.0% a.m., peak, at 100 kHz peak modulation.

AUDIO-FREQUENCY RESPONSE

Filters

3 kHz low-pass, 15 kHz low-pass, & 750  $\mu$ s de-emphasis; corner accuracy is ± 4%. Jumper selects de-emphasis either before or after the display.

Audio Distortion

Less than 0.25% t.h.d., for 75 kHz peak deviation. <0.5% t.h.d., for 90% a.m.

Output Level

F.M.: 1 V, r.m.s., approx., into 600 ohms at 1000 counts on the display.

A.M.: 1 V to 1.2 V, r.m.s.

DISPLAY

Modulation

LED display; 1000 counts plus 50% overrange; true peak, positive peak, negative peak, or peak-average indications.

Annunciators

Display of settings of mode switch and of filter. Digital display indicates levelhigh, level-low and unlocked conditions.

I.F. OUTPUT

Frequency

400 kHz, nominal.

Level

300 to 360 mV, approx., into 600 ohm load

POWER REQUIREMENTS

100, 120, 220, or 240 volts, a.c., 50 to 400 Hz; 24 VA.

§1-6, Continued.

DIMENSIONS

103 mm high x 218 wide x 278 deep

 $(4.1 in. \times 8.6 \times 11.0)$ 

WEIGHT

3.18 kg (7.0 lbs.), approximately.

#### OPTIONAL MODEL 8210-01

This model is the same as the standard Model 8210 except as follows:

AUDIO-FREQUENCY RESPONSE

Filters

The 15 kHz low-pass filter is replaced by

a 30 kHz low-pass filter; corner accuracy

is ± 4%.

FREQUENCY MODULATION

Deviation Accuracy

1% of reading for modulation frequencies

between 50 Hz and 10 kHz.

2% of reading, 10 kHz to 15 kHz.

Modulation Bandwidth

<30 Hz to 30 kHz

Residual F.M.

(R.F. Level >100 mV)

With 30 kHz low-pass filter:

<400 Hz, r.m.s., at 1.5 GHz, decreasing

linearly to a floor of <25 Hz, r.m.s.

With 3 kHz low-pass filter:

<150 Hz, r.m.s., at 1.5 GHz, decreasing

linearly to a floor of <5 Hz, r.m.s.

AMPLITUDE MODULATION

Depth Accuracy

Modulation	Accu	racy
Frequency	10% to 90% A.M.	<10% & >90% A.M.
50 Hz to 10 kHz	l% of reading	3% of reading
10 kHz to 15 kHz	2% of reading	6% of reading

NOTE: Peak residuals must be accounted for to obtain the above accuracies.

Carrier frequency <520 MHz; r.f. level between -10 and +10 dBm.

Modulation Bandwidth

<30 Hz to 30 kHz.

Residual A.M.

With 30 kHz low-pass filter:

Less than 0.35% a.m., r.m.s., for input

levels above 100 mV, r.m.s.

With 3 kHz low-pass filter:

Less than 0.15% a.m., r.m.s., for input

levels above 100 mV, r.m.s.

NOTE: Carrier frequency <520 MHz; above 520 MHz residuals increase linearly with

frequency.

#### SECTION II

#### INSTALLATION & OPERATION

#### 2-1. INSTALLATION

a. Unpacking. The 8210 is shipped complete and ready for use. Unpack the equipment from the shipping container and inspect it for any damage that may have occured during shipment. Check that all connectors and switches operate without binding.

NOTE: Save the packing material and container for possible use in reshipment of the 8210. See Figure 2-10 (p. 2-14) for the repacking method.

- b. Mounting. For bench mounting, choose a clean, sturdy and uncluttered mounting surface. For rack mounting, an accessory package (Model Number 950027) is available; it consists of two angle-mounting brackets, two flat plates, four binder-head screws, and four lockwashers. To rack mount an 8210, proceed as follows:
  - (1) The 8210 has one extrusion at each end of the front panel. On the outside surfaces of these extrusions, where they join the cabinet, are two strips of green pressure-sensitive tape. Remove or perforate these tape strips to expose the tapped mounting holes for the rack-mounting brackets.
  - (2) Refer to the drawing in the accessory's package for the proper orientation of the two mounting brackets.
  - (3) Mount the 8210 in the rack with standard rack-mounting screws through the slotted holes in the angle brackets.

NOTE: If necessary, the feet and tilt bail may be removed from the cover in order to clear any adjacent rack-mounted units.

c. Power Requirements. The 8210 can be operated on a.c. power sources of 100, 120, 220 or 240 volts, 50 to 400 Hz, single phase. The power required is 24 VA at 120 or 240 volts, a.c.

#### CAUTION

Before connecting the 8210 to an a.c. power source, see that the voltage-selector switches on the rear panel are set for the available line voltage and that a fuse of the proper rating is in the instrument's fuse holder: 0.25 A for 100 or 120 V; 0.125 A for 220 or 240 V -- either fuse to be type MDL Slo-Blo.

- d. <u>Cable Connections</u>. Depending on the operating mode of the 8210, various cables will have to be connected to it; these cables are not supplied with the instrument. Connections that may be required are:
  - (1) R.F. Input. The RF IN connector of the 8210 is a type BNC. The input impedance is 50 ohms, nominal.
  - (2) I.F. Output. The 8210's i.f. output is available at the front-panel BNC marked IF OUT. The level varies between 300 and 360 mV, r.m.s.; the source impedance is 600 ohms, nominal.
  - (3) A.F. Output. The recovered audio signal appears at the front-panel BNC connector labeled AF OUT. For f.m., the level is approximately 1 volt, r.m.s., into 600 ohms at 1000 counts on the digital display. For a.m., the level is 1 to 1.2 volts.

2-2. OPERATING CONTROLS, INDICATORS AND CONNECTORS
All controls, indicators and connectors used during operation of the 8210 are shown in Figures 2-1 and 2-2. They are described in Table 2-1, below.

Table 2-1. Operating Controls, Indicators, and Connectors

ITEM	FIGURE	INDEX NO	. FUNCTION
FILTER switches	2-1	1	Select low-pass or de-emphasis filters.
PEAK switches	н	2	Select display of + peak, - peak or peak average.
FUNCTION switches	n	3	Select AM, FM or LEVEL display functions.
RANGE switches	11	4	Select desired full-scale modulation range.
LED display	ı,	5	Indicates modulation or i.f. levelas determined by the FUNCTION switch setting.
LINE switch	H	6	Turns line power on and off.
RF IN connector	<b>11</b>	7	Input signal connection point.
IF OUT connector	**	8	Allows connection of 8210's i.f signal to external circuits.
AF OUT connector	11	9	Allows connection of 8210's recovered audio signal to external circuits.
Power connector	2-2	1	Input connector for a.c. power cable.
Line-voltage switches	п	2	Permit selection of appropriate a.c. operating voltage.
Fuse holder	н	3	Contains replaceable line fuse.

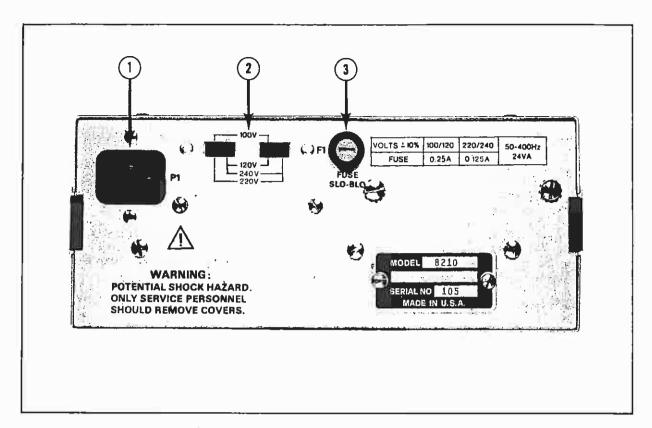


Figure 2-1. Model 8210, Front View

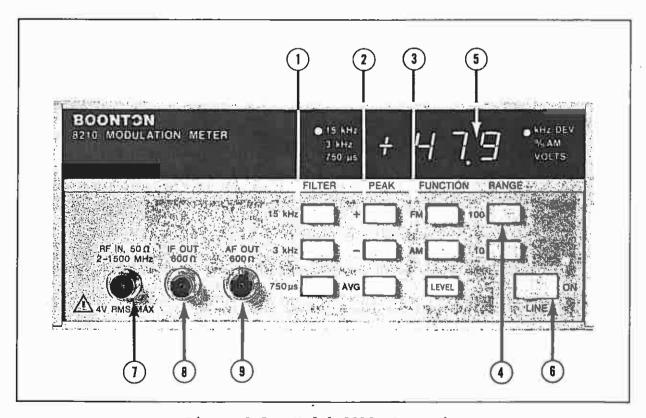


Figure 2-2. Model 8210, Rear View

2-3. PRELIMINARY CHECK

NOTE: The following preliminary check procedure is intended only to ensure that all circuits are operating. If a detailed performance check against specifications is desired, refer to subsection 2-6.

Before using the Model 8210, perform a preliminary check as follows:

- a. Set the LINE switch to the "on" position. The LED display should indicate "CAL," which means that the calibration sequence has begun. After about 30 seconds, a series of dashes should appear on the LED display, indicating an unlocked condition.
- b. Apply a 100 mV (r.m.s.) unmodulated test signal, at a frequency between 2 and 520 MHz, to the RF IN connector of the 8210. The LED display on the 8210 should now indicate residual modulation. Note that two dashes on the LED indicate that the 8210 is executing an a.g.c. cycle.
- c. Reduce the test signal to 5 mV. The display should indicate "IFLO."
- d. Increase the test signal to 1.5 V. The display now should read "IFHI."
- e. Decrease the test signal to approximately 0 dBm. The display should read as in Step (b).
- f. In turn, depress the three FILTER switches, and see that the associated annunciators indicate the switch selection correctly.
- g. Repeat Step (f) for the FUNCTION switches.
- h. Depress in turn the three PEAK switches. A plus sign (+) will be shown for the + PEAK switch, a minus sign (-) for the PEAK, and no sign when the AVG switch is depressed.
- i. Depress in turn the RANGE switches. The decimal-point indication of the display should move to left or right as each switch is depressed.
- j. Connect an oscilloscope to the 8210's IF OUT connector. Set the 'scope so that it displays the  $400\ \text{kHz}$  i.f. signal of the 8210.
- k. Modulate the test signal with approximately 50% a.m. Depress the AM FUNCTION switch, the 100 RANGE switch, and the 15 kHz FILTER switch. The display should indicate approximately 50% a.m.
- 1. Remove the amplitude modulation, and frequency-modulate the test signal with approximately 50 kHz peak deviation. Depress the FM FUNCTION switch. The display should indicate approximately 50 kHz deviation.
- 2-4. APPLICATION NOTES
  The following paragraphs describe some typical applications for the Model 8210. The use of the 8210 is not restricted to these applications, however.
- a. F.M. Measurements. High-accuracy f.m. measurements are possible with the 8210, for modulating frequencies from less than 30 Hz to 15 kHz, and deviations up to 300 kHz p-p. To achieve maximum accuracy, the signal level applied to the RF IN connector should be greater than 100 mV, r.m.s. Such signal levels reduce residual f.m. in the 8210 to a minimum value. To further reduce residuals, the minimum measurement-bandwidth consistent with the modulation frequency should be used. For instance: for measurements at a 400 Hz modulation rate, the 3 kHz low-pass filter should be used.

Typical residuals for the 8210 are plotted in Figures 2-3 and 2-4; audio response curves are plotted in Figure 2-5. Because the audio detectors in the 8210 are true peak-responding, the residual noise is added to the recovered signal being measured. Peak-detector response to a signal plus

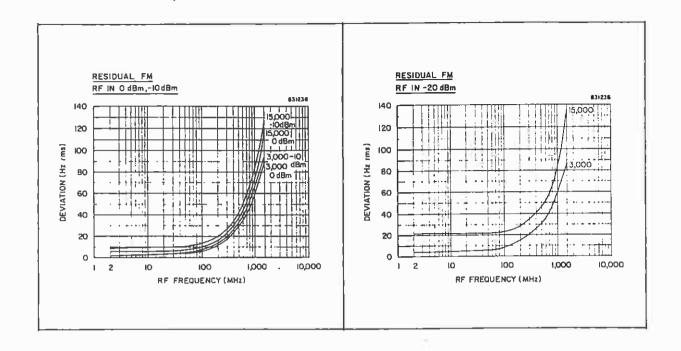


Figure 2-3. Residual F.M., Typical

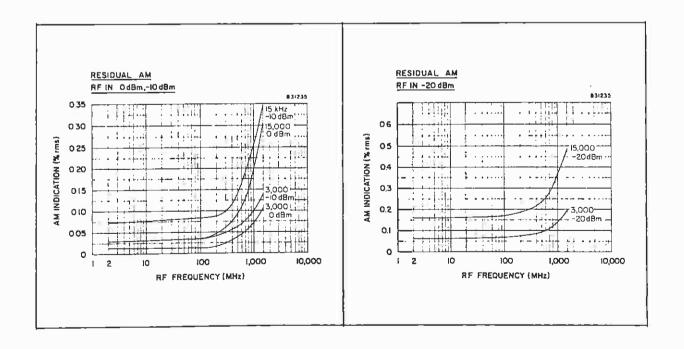


Figure 2-4. Residual A.M., Typical

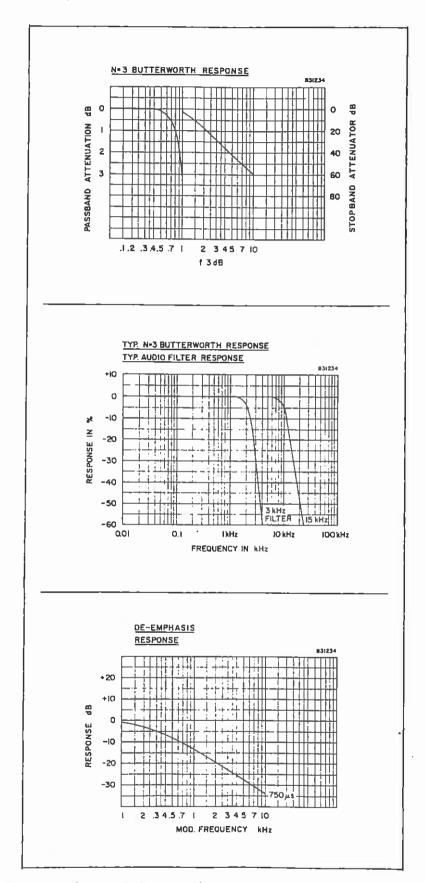


Figure 2-5. Audio Response, Typical

12-4a, Continued.

noise is not linear, and is a function of the carrier-to-noise ratio and the modulation waveshape. In most measurement situations involving sinusoidal modulation, noise suppression is approximately 30%.

For example, if the peak residual indicated without modulation is 100 Hz, and 10 kHz deviation is added, the resulting display would be 10.07. (Since the 0.7 multiplier is an approximate value, there will be variation. However, the use of that figure guarantees that the resulting display will always be within specification.) The assumption made is that the noise is gaussian and that the carrier-to-noise ratio exceeds 20 dB.

True r.m.s. measurements of the recovered audio signal will provide a more precise indication of modulation in the presence of large amounts of noise.

- b. A.M. Measurements. The 8210 makes possible fast, accurate indications of amplitude modulation. Optimum accuracy is achieved with input signal levels between -10 and +10 dBm (for lowest residuals), and the minimum bandwidth consistent with the modulation frequency. As discussed above for f.m., noise suppression does occur, and the 0.7 multiplier is used to subtract added noise.
- c. <u>Spurious Responses</u>. Most frequency-translating devices rely on a non-linear circuit element to produce the multiplication required for frequency translation. This non-linearity produces spurious mixing products, which tend to "cross over" the desired i.f. and change its character. In contrast, the 8210 converts frequency by using a sampler, which is very linear and which produces few spurious responses in the usual sense.

There are, however, a few points to remember when applying a sampling instrument like the 8210. If the input signal contains significant harmonic power above the third harmonic, an i.f. heat can occur and thus produce unwanted a.m. and f.m. indications.

Signals that are not harmonically related can interfere if, when they are mixed with any local-oscillator harmonic, the resulting sum frequency or difference frequency appears near the 8210's intermediate frequency.

EXAMPLE: Assume two input signals—the larger at 100 MHz, the smaller at 501.6 MHz. The local oscillator might be at 2.51 MHz so that its 40th harmonic (100.4 MHz), when mixed with the 100 MHz signal, produces a 400 kHz i.f. However, the 200th harmonic of 2.51 MHz is 502 MHz—which converts the 501.6 MHz carrier to 400 kHz also. Since the two signals are not phase coherent, a low-frequency beat will occur at the i.f. and produce spurious a.m. and f.m. indications. The offending input signal should be filtered in order to eliminate this interference.

d. Additional Applications. Information relevant to further applications of the 8210 will be found in Boonton Electronics' Application Note #19:

#### High Accuracy AM-FM Measurements

#### with the Boonton 82AD Modulation Meter.

The Application Note is available free upon request to Boonton Electronics,

Inquiries regarding application of the 8210 to specific customer requirements are invited. Please direct any such inquiries to the Applications Engineering Department of Boonton Electronics Corporation.

2-5. OPERATING INSTRUCTIONS
The operation of The Model 8210 is essentially automatic, requiring only that the operator select the proper display function and baseband filter. Paragraphs 2-5a and 2-5b summarize operating steps for a.m. and f.m. measurements, respectively.

#### a. A.M. Measurements.

- (1) Set the LINE switch to ON, and connect to the RF IN connector the r.f. signal that is to be measured.
- (2) After the 8210 has completed its calibration cycle, select the desired measurement bandwith. Use the minimum bandwidth consistent with the modulation frequency.
- (3) Depress the appropriate PEAK switch, as determined by the amplitude modulation measurement to be made.
- (4) Depress the AM FUNCTION switch and the 100 RANGE switch.
- (5) Read the percentage of a.m. modulation from the LED display. The 10 RANGE may be selected if the modulation is less than 15%.
- b. <u>F.M. Measurements</u>. Operation of the Model 8210 for f.m. measurements is basically the same as for a.m., except for the selection of Function and Filter. For f.m. measurements, depress the FM FUNCTION switch and the appropriate RANGE and PEAK switches.

Either a low-pass filter or the 750  $\mu s$  de-emphasis filter may be selected for the measurement. The de-emphasis filter may be placed before or after the modulation display, according to an internal jumper selection. Units shipped from the factory are normally wired for de-emphasis before the display.

c. Level Function. The "Level" function is included in the Model 8210 to indicate the relative a.m.-detector operating point; it is required only when an external indicator is used for making an a.m. measurement. When the 8210 is operating properly, depressing LEVEL should always result in a number between 0.95 and 11.5 on its digital display. If the reading on the external indicator is now multiplied by 10.00, then divided by the Level indication, the external indicator will be properly scaled.

The LEVEL pushbuton serves another purpose. If a malfunction occurs during calibration, a condition code (the letters cc, followed by a number), will appear on the digital display. It means that proper calibration could not be accomplished. (Refer to Section IV for the meaning of each condition code.) Depressing the LEVEL pushbutton releases the error condition, and measurements can be made. Note, however, that the detector that malfunctioned will not be properly calibrated.

In addition, the LEVEL button is utilized in several of the test routines provided for troubleshooting the 8210. These routines are described in detail in Section IV.

2-6. PERFORMANCE VERIFICATION
The following tests may be performed when the Model 8200 is first received.
Thereafter, performance verification should be needed only after repair to the instrument.

NOTE: In these verification procedures, some settings or results are followed by data in parenthesis. These parenthetical entries apply to instruments with the -01 Option installed

a. Test Equipment Required. Table 2-2 lists all test equipment required for verification of performance of the 8210. Other models of test equipment that meet or exceed the Critical Specifications may be used instead.

Table 2-2. Recommended Test Equipment for Performance Verification

EQUIPMENT	CRITICAL SPECIFICATIONS	SUGGESTED MODEL	
Signal Generator	A.MF.M., 0.01 to 520 MHz, -30 to +10 dBm level. T.H.D. <0.05% at 75 kHz Deviation at 100 MHz	Boonton Electronics 102E-19	
Signal Generator	C.W., 1.5 GHz, -30 to +7 dBm	Hewlett-Packard 8660C & 86603A	
Crystal- Controlled Source or Synthesizer	< 3 Hz residual f.m. at 500 MHz in 15 kHz bandwidth	Ailtech 460	
Voltmeter	True r.m.s., 10 mV full- scale sensitivity, 100 kHz bandwidth	Boonton Electronics 93AD	
Double-Balanced Mixer	+7 dBm, l.o. Range of l.o. & r.f.: 0.5 - 500 MHz	Mini-Circuits ZAD-1	
Audio Oscillator	Range: 20 Hz - 20 kHz < 0.1% t.h.d.	Hewlett-Packard 204C	
Resistor Resistor	10 kΩ, 1/4 W, 5% 620 Ω, 1/4 W, 5%	Allen Bradley AB-EB	
Power Supply	+10 V, d.c.	Power Designs 5015T	
Capacitor	1000 pF, 6 w.v.d.c.		
Distortion Analyzer	Range: 20 Hz - 20 kHz Resolution: 0.1% t.h.d.	Radiometer BKF10	

#### b. R.F. Input Sensitivity.

- (1) Connect the 8210 and test equipment as shown in Figure 2-6.
- (2) Depress the switches of the 8210 as indicated in Figure 2-6.
- (3) Apply a 10 MHz, 10 mV r.m.s. signal from the Model 102E-19 signal generator to the RF IN connector of the 8210. The 8210 should indicate "lock" and adequate signal level for a measurement.
- (4) Change the r.f. input to 500 MHz. Indications should be the same as in Step (3).
- (5) Connect the Model 8660C signal generator to the RF IN connector of the 8210. Set the signal generator's controls to provide an r.f. input of 30 mV, r.m.s., at 1500 MHz. Indications as in Step (3).

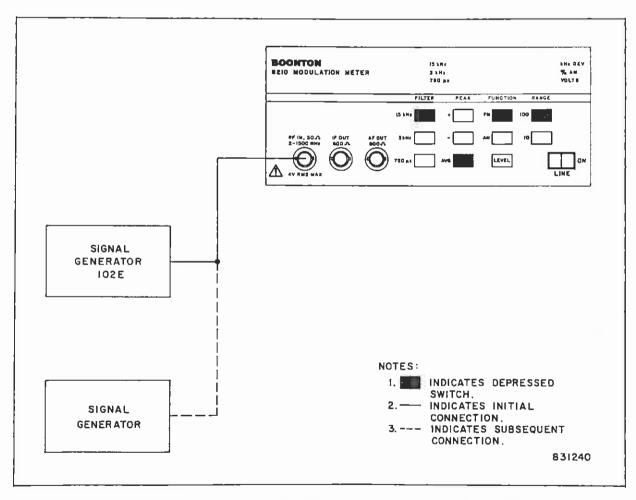


Figure 2-6. Test Setup: R.F. Input Sensitivity

c. <u>Deviation Accuracy</u>. Verification of the deviation accuracy of the 8210 is not usually required. If there is any doubt as to the operation of the internal calibrators, refer to Section IV for maintenance instructions, or to Appendix A for operation of the calibrators.

§2-6, Continued.

#### d. Residual F.M.

- (1) Connect the 8210 and test equipment as shown in Figure 2-7.
- (2) Apply the 500 MHz signal, at 0 dBm, from the test source to the RF IN connector of the 8210.
- (3) Depress the switches of the 8210 as indicated in Figure 2-7.
- (4) Connect the r.m.s. voltmeter (without 600  $\Omega$  termination) to the AF OUT connector on the 8210.
- (5) Set the voltmeter for 100 kHz bandwidth and 30 mV full-scale sensitivity. The voltmeter should indicate less than 13.3 mV (26.6 mV).
- (6) Depress the 8210's 3 kHz FILTER switch. The voltmeter should read less than 10 mV.

NOTE: The display of the 8210 indicates true peak deviation; therefore the display's readings will always be two to three times higher than the r.m.s. readings of the voltmeter.

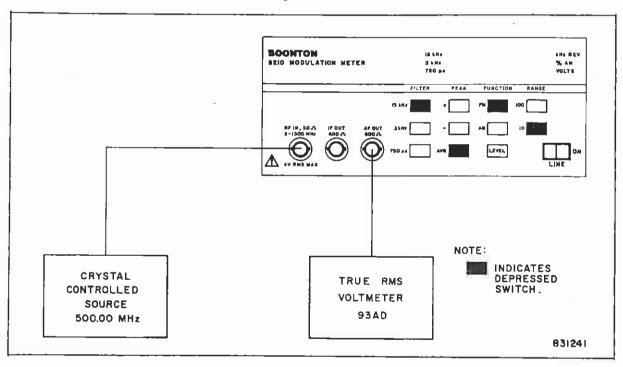


Figure 2-7. Test Setup: Residual F.M. and Residual A.M.

#### e. Residual A.M.

- (1) Connect the equipment as shown in Figure 2-7.
- (2) Set the 8210's controls as indicated, but select the AM FUNCTION.
- (3) Set the voltmeter to 100 kHz bandwidth and 100 mV sensitivity.
- (4) The voltmeter should indicate less than 50 mV (70 mV).
- (5) Set the 8210's FILTER to 3 kHz, and voltmeter sensitivity to 30 mV.
- (6) The voltmeter should indicate less than 30 mV.

#### §2-6, Continued.

#### f. A.M. Rejection.

- (1) Connect the 8210 and test equipment as shown in Figure 2-8.
- (2) Set the 8210's controls as shown in Figure 2-8.
- (3) Apply a 30 MHz signal, at 0 dBm, from the generator to the mixer.
- (4) Adjust the power-supply output voltage to +10 V d.c. Adjust the audio source for approximately 50% indicated a.m. at a 1 kHz rate.
- (5) Change the 8210's FUNCTION to FM.
- (6) Vary the r.f. level between 0 and +10 dBm for a deviation null. The display should indicate less than 100 Hz peak f.m. (Residual noisemodulation must be subtracted.)
- g. A.M. Audio Distortion. NOTE: Step 2-6f, the A.M. Rejection check, should be completed before performing this verification. Leave the equipment set up as in Figure 2-8.
  - (1) Adjust the audio oscillator for 90% a.m. at a 1 kHz rate.
  - (2) The distortion analyzer should indicate less than 0.5%.
  - (3) Vary the audio oscillator frequency from 50 Hz to 10 kHz.
  - (4) The distortion should be less than 0.5% at all frequencies.
- h. Audio-Frequency Response, 15 kHz. NOTE of Step 2-6g applies here also.
  (1) Depress the AM FUNCTION button.
  - (2) Adjust the frequency of the audio oscillator to 1 kHz; adjust its amplitude for an indication of 60.0% a.m.
  - (3) While maintaining a constant audio-oscillator amplitude, vary the modulation frequency between 50 Hz and 5 kHz (10 kHz).
  - (4) The indicated a.m. should be between 59.4% and 60.6% for all modulation frequencies.

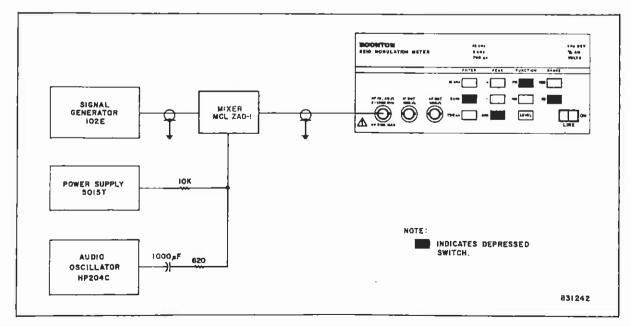


Figure 2-8. Test Setup: A.M. Rejection, A.M. Frequency Response, and A.M. Audio Distortion

#### §2-6h, Continued.

- (5) Increase the frequency to 7.5 kHz (15 kHz). The indicated a.m. should be between 58.8% and 61.2%.
- (6) Increase the frequency to 15.0 kHz (30 kHz). The indicated a.m. should be between 40.4% and 44.3%.

#### i. F.M. Audio Distortion.

- (1) Connect the 8210 and test equipment as shown in Figure 2-9.
- (2) Set the controls of the 8210 as shown.
- (3) Set the signal generator to 100 MHz, 0 dBm, and external f.m.
- (4) Adjust the level of the audio oscillator for 75 kHz peak deviation at a 1 kHz rate.
- (5) The indicated distortion should be less than 0.25%.
- (6) Repeat Step (4) for modulation rates of 50 Hz and 10 kHz.

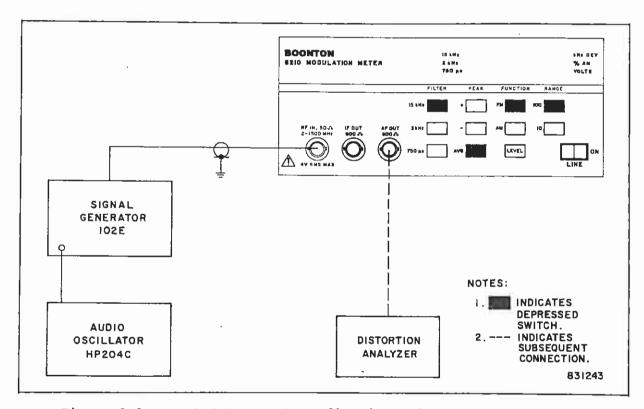


Figure 2-9. Test Setup: F.M. Audio Distortion and F.M. Rejection

#### j. F.M. Rejection.

- (1) Connect the equipment as shown in Figure 2-9.
- (2) Set the controls of the 8210 as indicated.
- (3) Adjust the audio oscillator's frequency to 1 kHz; adjust its amplitude for a 100 kHz peak deviation.
- (4) Change the 8210's FUNCTION to AM and its RANGE to 10.
- (5) The display should indicate less than 1.0%, peak.

#### \$2-6, Continued.

#### k. Audio-Frequency Response, 3 kHz.

- (1) Connect the equipment as in Figure 2-9.
- (2) Set the 8210's controls as shown.
- (3) Adjust the audio oscillator's frequency to 300 Hz, then adjust its amplitude until the 8210 reads 100.0 kHz.
- (4) Without changing the audio oscillator's level, adjust its frequency to exactly 3.00 kHz.
- (5) The Model 8210 display should indicate between 67.5 and 73.8 kHz.

#### 1. Audio-Frequency Response, 750 μs De-emphasis.

- (1) Connect the equipment as in Figure 2-9.
- (2) Set the 8210's controls as shown.
- (3) Adjust the audio oscillator's frequency to 212.2 Hz, then adjust its amplitude until the 8210's display indicates 100.0 kHz.
- (4) Change the 8210's FILTER to 750 us.
- (5) The display should read between 68.0 and 73.5 kHz deviation.

m. A.M. Depth Accuracy. Verification of the a.m. depth accuracy of the 8210 is not required. If there is any doubt as to the operation of the internal calibrators, refer to Section IV for maintenance instructions, or to Appendix A for operation of the calibrators.

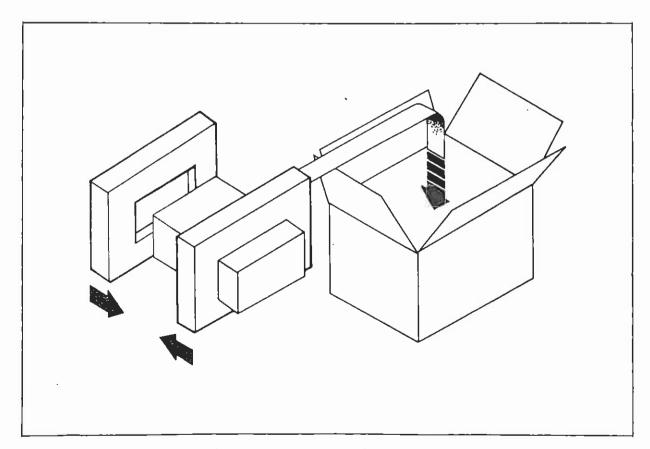


Figure 2-10. Packaging Diagram

# S E C T I O N III THEORY OF OPERATION

#### 3-1. INTRODUCTION

The 8210 is a compact, microprocessor-controlled, internally calibrated, a.m.-f.m. modulation meter that covers the carrier-frequency range of 2 MHz to 1.5 GHz. Amplitude modulation or frequency modulation is displayed on a four-digit LED display that provides a maximum resolution of 0.01% a.m. or 10 Hz deviation. Signal acquisition, display operation, calibration, and instrument control is accomplished using a microprocessor.

Operation of the 8210 is fully automatic. The largest signal present at the RF IN connector is converted to a 400 kHz intermediate frequency, which is adjusted to a convenient level for a.m. measurements. The modulation depth of a.m. signals is equal to the peak amplitude of the recovered audio signal divided by the d.c. level of the a.m. detector. The deviation of an f.m. signal is equal to the peak amplitude of the recovered signal. The recovered modulation is converted into a proportional d.c. level, then into a digital display, by microprocessor-controlled detectors and an analog-digital (A-D) converter.

3-2. CIRCUITS: GENERAL DISCUSSION For this discussion the circuits of the 8210 are grouped by function, as follows: r.f., i.f., calibrator, a.f., logic, and power-supply circuits. Refer to Figure 3-1, a simplified block diagram of the 8210.

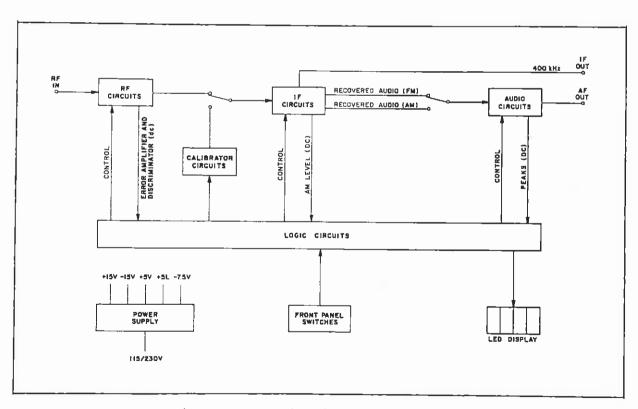


Figure 3-1. Simplified Block Diagram

a. R.F. Circuits. The r.f. input signal to be measured is applied to the r.f. circuits through the front-panel RF IN connector. This signal passes through a fixed 3 dB pad to a zero-order hold sampler. The sampler is fully bootstrapped to accept signals as large as 1 V, r.m.s., without overload.

- A sampling pulse, generated from a tunable local oscillator, converts the r.f. signal into an i.f. signal at approximately 400 kHz. The i.f. signal is passed to the i.f. circuits and also through a filter to a limiter, a discriminator, and an error amplifier. Automatic frequency control is accomplished by these circuits in conjunction with the microprocessor.
- b. I.F. Circuits. The i.f. signal from the sampler is filtered and amplified, then coupled to a.m. and f.m. detectors through a digital-to-analog (D-A) converter configured as a variable-gain element. The logic circuitry adjusts the converter so as to maintain a convenient d.c. level at the output of the a.m. detector. The last-mentioned is a linear active detector, which recovers the amplitude modulation of the i.f. and provides a d.c. signal proportional to the i.f. level. A portion of the a.m. detector output signal is used to drive a monostable multivibrator, which detects the f.m. modulation of the i.f. signal. Both a.m. and f.m. signals are amplified and applied to the a.f. circuits through a switch. During calibration, the signal from the r.f. circuits is disconnected from, and the calibrator signal is connected to, the i.f. circuits.
- c. Calibrator Circuits. The calibrator circuits, which are activated when the 8210 is turned on, consist of a variable-modulus counter circuit and a precision attenuator. The variable-modulus counter is alternately programmed to divide the output of a 3.579 MHz crystal-controlled oscillator by eight or by ten. The resulting signal has an average frequency of 402 kHz, approximately, and a peak deviation of 44.74 kHz. This signal is used to calibrate the f.m. detector. In addition, a fixed-frequency signal is applied to a switchable attenuator, which is alternately programmed to attenuate by two-thirds and by one-third. The signal from the attenuator has an amplitude variation of two to one, and therefore is equivalent to a signal with 33.33% a.m.
- d. A.F. Circuits. The recovered audio signal from the a.m. or the f.m. detector (as determined by the FUNCTION switch), is filtered by an active-filter circuit to remove i.f. components. Baseband processing circuitry, in the form of selectable low-pass filters, additional gain, and precision peak detectors—all under the control of the logic circuity—convert the recovered signal into a digital display.
- e. Logic Circuits. The logic circuits consist of a central processing unit (CPU), read-only memory (ROM), random-access memory (RAM), peripheral interface adapters (PIA), and a digital-to-analog converter (DAC). The CPU operates under control of a microprogram, stored in ROM, to monitor the frequency control, level control, peak-detector circuits, and the front-panel switches. In addition, the CPU controls and updates the front-panel displays, and operates all internal control circuits.
- f. Power-Supply Circuits. The power-supply circuits convert the a.c. line voltage into well regulated d.c. voltages. Five power-supply voltages are used to operate the circuits in the 8210:  $\pm$ 15,  $\pm$ 15,  $\pm$ 7.5, and separate  $\pm$ 5 supplies for the analog and for the digital circuits.
- 3-3. CIRCUITS: DETAILED DISCUSSION

  a. R.F. Circuits. The r.f. circuits convert the r.f. input signal that is to be measured into a 400 kHz i.f. signal. With the assistance of a microprocessor, a local-oscillator signal is generated and controlled so as to maintain this intermediate frequency. (Refer to Figure 3-2, a detailed block diagram of the r.f. circuits.)
  - (1) The input signal applied to the front-panel RF IN connector, Jl, is passed through connectors J2 and Pl to a fixed 3 dB pad, which consists of R2-R4. This pad reduces the r.f. level, and improves the impedance match to the incoming signal. The output of the pad is connected to a sampling gate consisting of diodes CR2a-CR2d. The sampling gate and sampler amplifier, consisting of transistors Q2

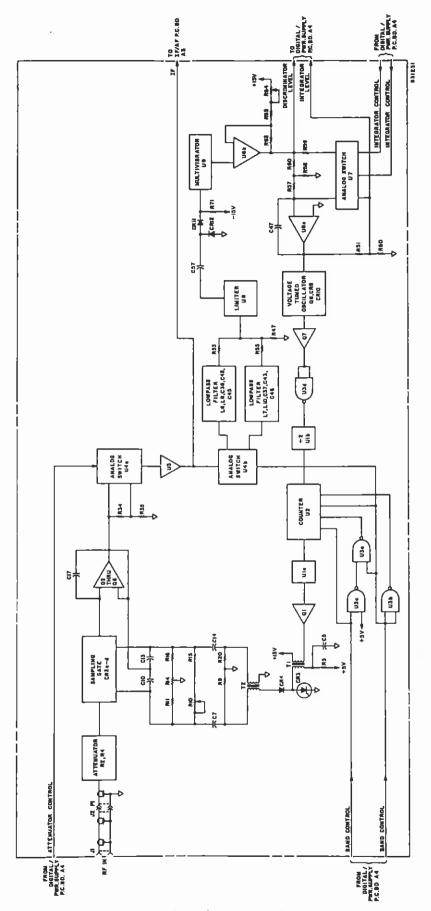


Figure 3-2. R.F. Circuits: Detailed Block Diagram

- through Q6 and associated components, constitute a zero-order hold sampler.
- (2) The operation of the sampling gate is shown in simplified form in Figure 3-3. Each time the sampling gate is closed, by a short-duration pulse, the input capacitance of the sampler amplifier plus any stray capacitance is charged to a voltage that is less than the instantaneous r.f. input voltage. Before the next sample is taken, positive feedback from the sampler amplifier causes additional charge to be placed on this capacitance. Charge is added until the output voltage of the sampler amplifier is equal to the r.f. input at the time the sample was taken. This output voltage is held constant until the next sample is taken. Successive samples are taken until the r.f. waveform is reconstructed at 400 kHz. Additional feedback from the sampler amplifier maintains symetrical reverse bias on the sampling gate. R10 adjusts the bias magnitude, and R14 adjusts the bridge balance.

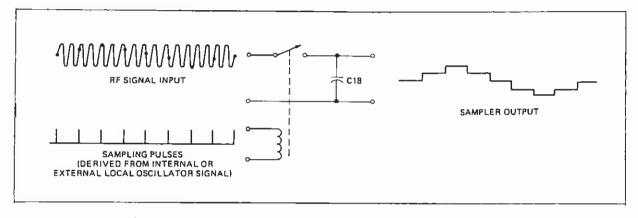


Figure 3-3. Sampling Gate: Simplified Operation

- (3) The output of the sampler amplifier is connected to a switchable 20 dB attenuator, consisting of R34, R-35, and U4a. The attenuation is selected by the control program whenever the r.f. input level exceeds approximately 100 mV. Amplifier U5 increases the signal level about four times before it is coupled to the i.f. circuits. The output of U5 is connected also to a switchable low-pass filter composed of U5b, L6, L7, L9, L10, C36, C37, C42, C43, C45 and C46. This filter eliminates most of the local-oscillator signal at the input of the limiting amplifier U8. A level-shift circuit, which consists of CR11, CR12, C57 and R71, translates the limited i.f. signal to TTL levels in order to operate U9--a monostable multivibrator. The duty cycle, and thus the average value, is proportional to frequency. R64 sets the operating level of U6b to zero volts, d.c., when the intermediate frequency is 400 kHz.
- (4) The output of U6b is connected to integrating amplifier U6a through a voltage divider formed by R58, R60. This attenuation is needed to preserve low-frequency f.m. response at high carrier frequencies. CMOS switch U7 can be programmed to "dump" the integrator or to bypass the input voltage divider on command from the logic circuits. The output of the integrator is resistively coupled to the varactor diodes CR9 and CR10.
- (5) The local oscillator, composed of FET Q8 and associated components, is voltage-tuned. The frequency is determined by a tuned circuit consisting of L2 and varactor diodes CR9 and CR10. As the voltage at the ouput of U6a varies from +11 to -11 volts, the oscillator's

frequency changes from less than 30 MHz to approximately 40 MHz. Level shifter Q7 increases the signal to TTL-compatible levels to drive both U3d (a buffer), and U1b (a divide-by-two stage). U2 and U3a-c are configured as a programmable counter, able to divide by four, by five, or by six, as controlled by the logic circuitry. By successively changing the divide modulus, three overlapping bands (extending together over one octave), are generated.

- (6) The sampling pulses are generated by the step-recovery diode CR3, amplifier Ql, and transformer Tl. Initially, diode CR3 is forward biased from the +5 volt supply through R5. Ula generates a narrow pulse from the output of the counter. This pulse, amplified by Ql, drives the step-recovery diode into reverse conduction; however, CR3 does not "open" until all of its stored charge is depleted. At that time the diode recovers and produces a large narrow pulse, which is coupled to the sampling bridge through T2, a balun transformer. The output of T2 is two nearly equal opposite-polarity pulses. If the two pulses were exactly equal and opposite, they would cancel one another at the input and ouput of the sampling bridge. Since such equality is never the case, however, R14 is adjusted to null the bridge-input signal—and thereby the signal fed out of the RF IN connector.
- (7) Frequency acquisition occurs in the following manner: If no carrier is present at the input (RF IN), the discriminator level indicates that the frequency is high. The integrator ramps toward the negative supply rail until it has exceeded 11 volts. At that time the integrator is reset to 0 volts, the integrator attenuator is bypassed, and the count-modulus of the band counter is changed. This process continues until a carrier signal is applied to the RF IN connector.
- (8) When a carrier is applied, an i.f. signal will be produced at a frequency that is between zero and one-half of the sampling rate. This signal is hard-limited, then applied to a discriminator which, in turn, causes the integrator to move toward one or the other of the supply rails—depending on whether the i.f. is high or is low. If a valid 400 kHz i.f. is produced the integrator stops, and the by-pass of the integrator attenuator is removed. If no valid i.f. occurs, the integrator output will eventually exceed either +11 or -11 volts. Then the integrator will be reset, and the band-counter modulus will be either increased or decreased. In this way, all possible input frequencies can be made to produce a valid i.f.
- (9) The capture performance of the system is determined principally by the limiter's gain and the bandwidth of the sampler. Weaker signals at the r.f. input (non-harmonically related to the signal of interest) will be supressed, since the largest signal present will drive the limiter to a low-gain state. These weaker signals will appear as f.m. sidebands at the output of the limiter.
- b. I.F Circuits. The i.f. circuits recover the a.m. and f.m. signals from the frequency-shifted input signal. These circuits also provide a sample i.f. signal to the front-panel IF OUT connector; in addition, for a.m. measurements, they provide a d.c. signal proportional to the i.f. level. (Refer to Figure 3-4, a detailed block diagram of the i.f. circuits.)
  - (1) The 400 kHz i.f. signal from the r.f. circuits is connected to amplifier U2 through a low-pass filter that consists of inductors Ll through L3, capacitors Cl-C2, and resistors R3, R5 and R6. Variable resistor R5 reduces the filter's amplitude-response variations, which are due to component tolerances. It is adjusted so as to give minimum a.m. indication when an f.m. signal is applied. Amplifier U2 has a closed-loop gain of four (approximately), as determined by

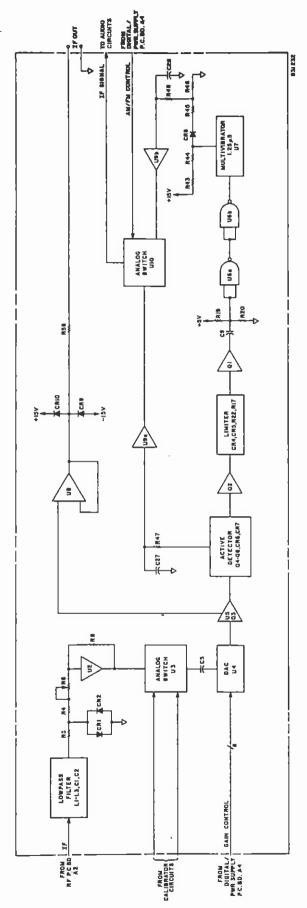


Figure 3-4. I.F. Circuits: Detailed Block Diagram

- R3, R5, R6 & R8. The signal is then connected to calibrator switch U3, and a.c.-coupled to DAC U4. The gain of the DAC is determined by the digital byte appearing at inputs Bl-B8. The logic circuitry varies this byte in order to maintain the d.c. output of the a.m. detector between 0.5 and 0.6 volts. The amplifier that consists of U5, Q3, and associated components, increases the i.f. level and provides the high output impedance necessary for driving the linear active detector circuit. The signal at the emitter of Q3 is buffered by U8 and routed to the IF OUT connector.
- (2) The active detector circuit, which comprises transistors Q4 through Q6, diodes CR6-CR7, and associated components, converts the input current into two half-wave-rectified signals. The circuitry of Q4-Q6 yields maximum gain and a high output impedance for driving the feedback network. The two half-wave-rectified signals at the outputs of CR6 and CR7 are added to complete the feedback path.
- (3) The output at detector diode CR7 is a signal that contains a d.c. component proportional to i.f. level, and an a.c. component proportional to modulation depth. This signal is lightly filtered by R47 and C27, and amplified by U9a. The output of U9a is connected to the a.m.-f.m. switch U14.
- (4) A portion of the linear active detector's output is coupled to a limiter circuit via impedance transformer Q2 and associated components. The limiter, consisting of CR4, CR5, R22 & R17, removes most a.m. from the i.f. signal. The resulting signal is amplified to TTL levels by amplifier Q1, then differentiated by C9, R19 and R20. The TTL gates U6a and U6b amplify the differentiated signal into a narrow TTL pulse to drive U7, a monostable multivibrator.
- (5) The period of U7 is 1.25 µs, approximately. The network consisting of R43-R46 and CR8 confines the peak-to-peak amplitude of U7's output to four volts. As the intermediate frequency changes, the duty cycle of the multivibrator—and consequently the average value of the waveform—changes proportionally.
- (6) The signal is lightly filtered by R48 and C28, then amplified and level-shifted by U9b. The signal is routed to the a.m.-f.m. switch U10, and to the audio circuits.
- c. <u>Calibrator Circuits</u>. The calibrator circuits provide the reference calibration signals for the 8210's a.m. and f.m. detectors. See Figure 3-5. (In addition to the circuit description given below, technical information on design and operation of the calibrator circuits appears in Appendix A.)
  - (1) The 1.79 MHz signal from U5a, pin 8, is connected to the clock input of synchronous counter U9. The counter is configured to self-load its data inputs at the end of each count cycle. By varying the input data with an 874 Hz signal from Ulf, pin 2, the divide modulus is changed from four to five. The signal that results synchronously switches from 357.9 to 447.4 kHz, producing an average frequency of 402.6 kHz and deviation of 89.48 kHz, p-p. This signal is used to calibrate the f.m. discriminator. The signal is connected to data selector U12, along with a signal at 447.4 kHz from U3, pin 6, and an 874 Hz signal from Ulf, pin 2. The outputs of the data selector are controlled by the signals from U-16, pins 39 and 17. During the calibration cycle U16, pin 17, is "low;" pin 36 is set "high" for a.m. calibration, and "low" for f.m. calibration.
  - (2) When the calibration routine initially selects AM FUNCTION, the outputs of the data selector are the signal from U3, and the 874-Hz signal from U1f, pin 2. The 447.4 kHz signal is routed through a low-pass filter consisting of L1, L2, C6, C8 and C10 to the i.f.

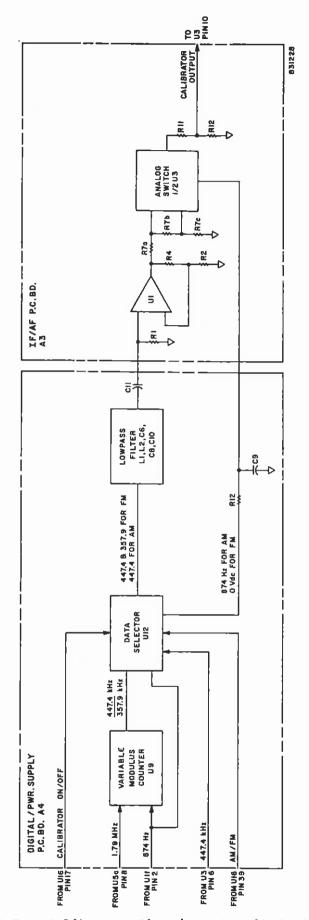


Figure 3-5. Calibrator Circuits: Detailed Block Diagram

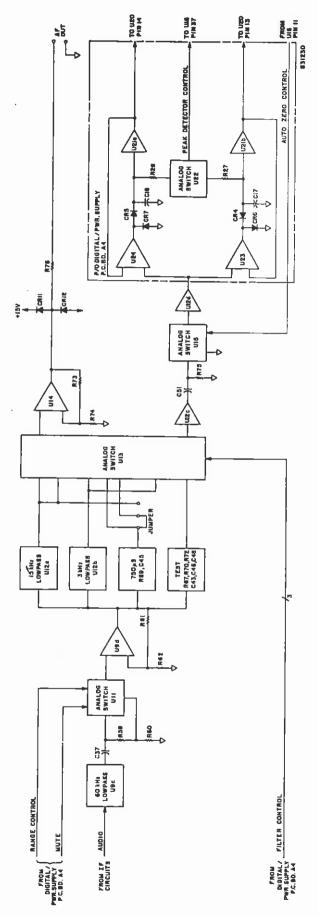
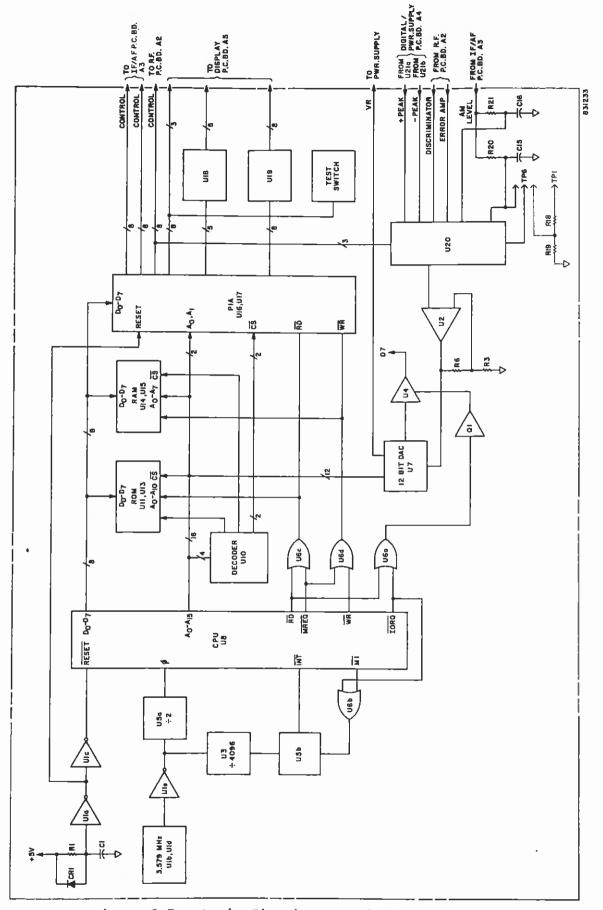


Figure 3-6. A.F. Circuits: Detailed Block Diagram

circuits. This signal is amplified (×2) by A3Ul and applied to the voltage divider A3R7. The analog switch A3U3 is controlled by the 874-Hz signal from A4Ul2 so as to switch between two taps of the divider. The voltage ratio is exactly two, therefore the equivalent a.m. is 33.33%. This signal is coupled through an attenuator (R11 and R12) and the second half of switch A3U3 to the i.f. circuitry.

- d. A.F. Circuits. The audio circuits process the recovered modulation signal supplied from the a.m. or the f.m. detector circuits—as determined by the front-panel FUNCTION switch. The recovered signal is filtered and converted to a d.c. level, which is then measured; the result is presented on the front-panel LED display. Refer to Figure 3-6.
  - (1) The signal from the output of the a.m.-f.m. switch UlO, is filtered by active filter U9c and associated components. This filter is part of a three-pole 60 kHz filter, which removes most of the i.f. component from the recovered signal. The filtered signal is then a.c. coupled to a 20 dB attenuator: R59, R60. CMOS switch Ull selects either the signal, or the attenuated signal, as determined by the front-panel RANGE switch. Additionally, the logic circuitry can program Ull to disconnect the recovered signal in order to prevent audio-circuit overload when the instrument is unlocked.
  - (2) The signal is then amplified (×11) by U9d and is coupled to the 15 kHz filter, the 3 kHz filter, and the 750 μs de-emphasis network. U12a and associated components form the 15 kHz filter; U16b and associated components form the 3 kHz filter. Both are three-pole Butterworth types. The 750 μs de-emphasis network is a single RC section: R69, C45. A jumper circuit is provided to give the option of connecting the de-emphasis network either before or after the measuring circuits.
  - (3) CMOS switch Ul3 selects one of the three filters, as determined by the front-panel FILTER switch. In addition, the logic circuitry can program Ul3 to select--during calibration--a filter consisting of R67, R70, R72, C43, C46 and C48. One of the outputs of Ul3 is amplified (× 2.8) by Ul4 and routed to the front-panel AF OUT connector. The other output is buffered by voltage-follower Ul2c and a.c. coupled to Ul5, an auto-zero switch. Ul5 is operated by the logic circuitry to disconnect the recovered signal for a period of time adequate to determine the output of the peak detectors with no input. The switch is then closed, and the modulation signals are connected through buffer Ul2d to the peak detectors.
  - (4) The positive-peak detector consists of U24, U21a, CR1, CR3 and C18. During the positive excursion of the modulating signal, the output of U24 is driven positive; C18 then charges through CR1. U21a buffers the voltage across C18, and adds a small offset. When the output of U21a reaches a value equal to the peak of the waveform plus a small increment, the output of U24 goes negative and thus terminates the charging. The voltage at the output of U21a is then equal to the positive peak of the modulating signal.
  - (5) Similarly, U23, U21b, CR4, CR6 and Cl7 constitute a negative-peak detector. In addition, U22 provides a means for resetting both detectors for auto-zero measurements.
- e. Logic Circuits. The logic circuits generate all control and display functions in the 8210. The logic circuits consist of a CPU, 4096 bytes of ROM, 256 bytes of RAM, two PIA's, a DAC, and several IC gates and drivers.

The CPU, U8, is controlled by a program stored in ROM (Ull, Ul3). Temporary program variables and subroutine return addresses are stored in RAM (Ul4, Ul5). The 8210's control functions are directed by Ul6, a PIA; keyboard



Pigure 3-7. Logic Circuits: Detailed Block Diagram

and display functions are directed by the PIA U17. See Figures 3-7 and 3-8.

(1) The control program initializes the RAM and PIA circuits and checks the status of the test switch during the power-up sequence. The display is then enabled, and interrupt processing of the keyboard and the display begins. As each digit of the display is updated,

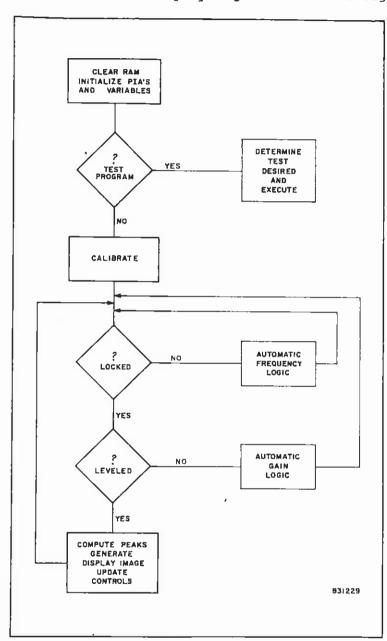


Figure 3-8. Program Flow Diagram

each row of keys is tested simultaneously, and any key closures are detected. The calibration sequence then starts; when it ends, the main program loop begins. The latter places the highest priority on successful frequency acquisition, then on establishing the proper i.f. level, and finally on measuring the recovered signal. The program checks level and frequency each time through the main loop, so i.f. errors are detected immediately. When proper operating parameters are established, the recovered signal is processed.

- (2) The program executes an auto-zero cycle each time a measurement is made. audio signal is turned off, the peak detectors are reset and released, and both detectors are read. The information is stored temporarily. The peak detectors are reset, audio is turned on, and the detectors are released. They are read again and the "zero" information is subtracted. The display is then updated with the data determined by the setting of the frontpanel PEAK switch.
- (3) All d.c. voltage measurements are made by the successive approximation A-D converter consisting of U7, U4, Q1, and associated components. The successive trial values are software generated, and sent to the 12-bit DAC (U7) via the address bus of the CPU. An

I-O read cycle (signalled by IORQ = RD = LO) returns the comparison (made by U4) of the DAC value and the input d.c. signal on data line D7. A complete conversion requires 12 succesive tests to converge within 1 LSB. U2 serves as a fixed-gain buffer to isolate U2O, the CMOS multiplexer, from the A-D converter circuit's low input impedance.

(4) The CMOS multiplexer, U20, is operated by the program to select various voltages from the 8210's circuits. Both peak detectors are

connected to it, as are the outputs of the integrator and the discriminator from the r.f. circuits, and the d.c. level from the a.m. detector. The a.m. detector output is filtered by R21 and C56 to provide one a.m.-level input and by R20 and C15 to provide another. The two a.m. detector inputs are used during i.f. level setting and a.m. depth measurements: the moderately filtered one for testing the level, the heavily filtered one for computing a.m.

- (5) Ulb, Uld, and U5e constitute a crystal-controlled oscillator, with the 3.58 MHz crystal frequency divided by a factor of two by U5a. The output of U5a is connected to the clock input of the CPU. The 3.58 MHz signal is also divided by a factor of 4096 by U3, to generate the 1.1 ms interrupt signal. Ulb is clocked by this signal going high, which activates the INT line of the CPU and causes an interrupt to occur. The CPU recognizes the interrupt; it acknowledges by setting lines IORQ and M1 low. Thus U5b is reset, and the interrupt condition is cleared. The interrupt program updates the display and interrogates the keyboard, then returns to the main program.
- (6) UlO decodes the address lines to enable the IC's of ROM, RAM, and PIA. The program ROM is located from adress 0 to FFF hex; the RAM is located at addresses 1000 to 10FF hex; the display PIA, IC7, is located at address 3000 hex; and the control PIA, IC6, is located at address 2000 hex.
- (7) A circuit composed of Ula, Ulc, Rl, Cl and CRl resets the CPU and PIA IC's at power-up.
- f. Power-Supply Circuits. The power-supply circuits provide d.c. operating power for all other circuits of the instrument. Regulated output voltages of +15, -15, +5(L), +5, and -7.5 volts are provided. The power supplies are designed to operate from a 100, 120, 220, or 240 volt (nominal) a.c. power source. Refer to Figures 6-1 and 6-2.
  - (1) Power is applied to the primary windings of power transformer TI through the power connector PI, line fuse FI, line-voltage selector switch SI, and the front-panel LINE switch. SI is set by the user in accordance with the available a.c. power source.
  - (2) Two separate secondary windings of T1 supply a.c. voltages to the rectifier circuits, through connector J6. Bridge rectifier CR8 and capacitor C23 generate an unregulated d.c. output, which supplies power to U26 (a five volt, three-terminal regulator). CR10 and CR15 protect the regulator from reverse voltages during power-on and power-off transients. C26 and C33 improve the transient response of the regulator. The unregulated output of CR8 also is connected to a second regulator, U25, which is enclosed in the feedback loop of U29c. This connection produces a precision +5 volt supply for the analog circuitry of the 8210.
  - (3) The reference output of U7 is filtered by R31b and C34, and applied to pin 3 of U29a. This provides a reference for the generation of the +15 volt supply. R31 is actually an array of eight matched 10 kΩ resistors, three of which are connected in series between +15 volts and ground. Since the junction of R31a and R31c is connected to pin 2 of U29a, the feedback loop will cause the voltage at this point to be +10.00 volts within the offset of U29a. Consequently, the voltage at the junction of R31c and R31e will be +5.00 volts. This voltage becomes the reference for U29c, which generates the precision +5 volt supply.
  - (4) The -15 volt supply is generated by U28 and U29b, and associated components. A sample of the regulated output voltage of the supply,

## 13-3f(4), Continued.

developed by the resistive divider composed of R3ld and R3lf, is compared to ground. Error voltages are amplified by U29b, and are coupled to regulator U28 in order to adjust the output voltage so as to reduce the error. In this manner the -15 volt supply is made to track the +15 volt supply.

- (5) One additional supply voltage is generated; its components are a resistive divider (R31h and R31g), and U29d. The latter is connected as a voltage follower in order to buffer the -7.5 volts at pin 5.
- (6) All regulators are protected from reverse bias by diodes both from their outputs to ground, and from their outputs to inputs.
- (7) Capacitors at input and output terminals improve the transient response of the supplies.
- (8) Diodes CR12, CR14 and CR16 ensure proper start-up of the supplies.

# SECTION IV

# MAINTENANCE AND ADJUSTMENT

#### 4-1. INTRODUCTION

This section contains maintenance and adjustment instructions for the Model 8210. Symptomatic and systematic troubleshooting procedures for localizing a malfunction are given, as well.

# 4-2. TEST EQUIPMENT REQUIRED

The test equipment that is required for maintenance and adjustment of the Model 8210 is listed in Table 4-1, below. Other models of test equipment that meet or exceed the Critical Specifications may be used instead.

Table 4-1. Required Test Equipment for Maintenance and Adjustment

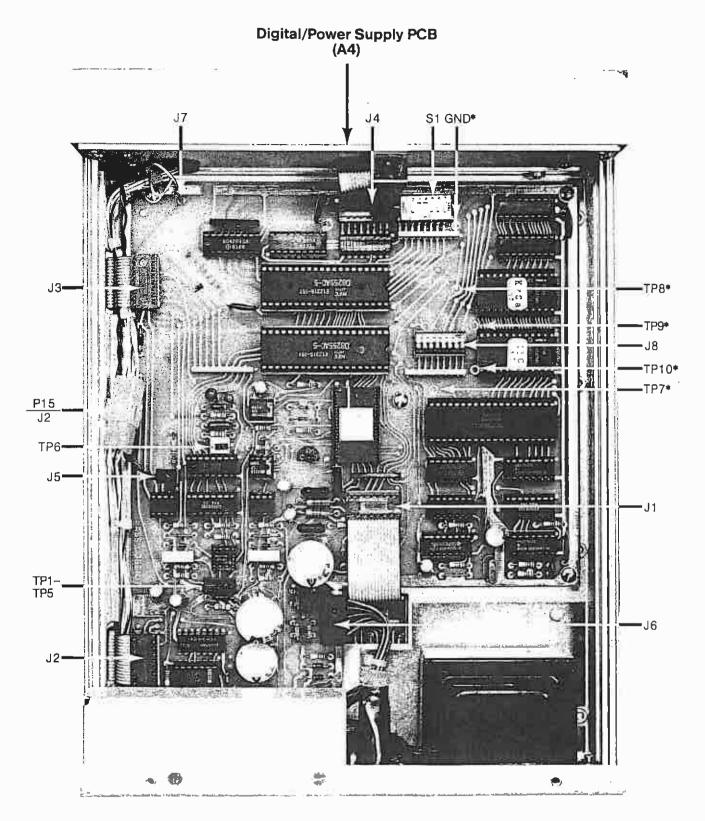
EQUIPMENT	CRITICAL SPECIFICATIONS	SUGGESTED MODEL
Signal Generator	A.MF.M. 0.01 to 520 MHz. -30 to +10 dBm.	Boonton Electronics
Oscilloscope	100 MHz Bandwidth. 5 mV Sensitivity,	Hewlett-Packard 1740A
Audio Oscillator	20 Hz to 75 kHz. Constant level of 110 mV, with low distortion.	Hewlett-Packard 204C
A.C. Voltmeter	10 mV to 2 V. Accuracy 1%, 50 Hz to 1 kHz.	Boonton Electronics 93AD
Digital D.C. Voltmeter	100 mV to 20 V. Accuracy 0.15% at 15 V.	Data Precision 1350
Frequency Counter	20 Hz to 5 MHz. Sensitivity 100 mV.	Data Precision 5740
Signature Analyzer	> 3.5 MHz Operating Frequency.	Hewlett-Packard 5004A

4-3. LOCATION OF MAJOR ASSEMBLIES
See Figures 4-1 and 4-2 for the location of the major assemblies of this instrument.

# 4-4. REMOVAL OF MAJOR ASSEMBLIES AND PARTS

# a. Instrument Covers.

- (1) Disconnect all signal cables and the power cord from the 8210.
- (2) Remove two  $\pm 4-40$  screws securing the top cover at the rear panel.



\* Not present in early models

Figure 4-1. Model 8210: Top View with Covers Removed

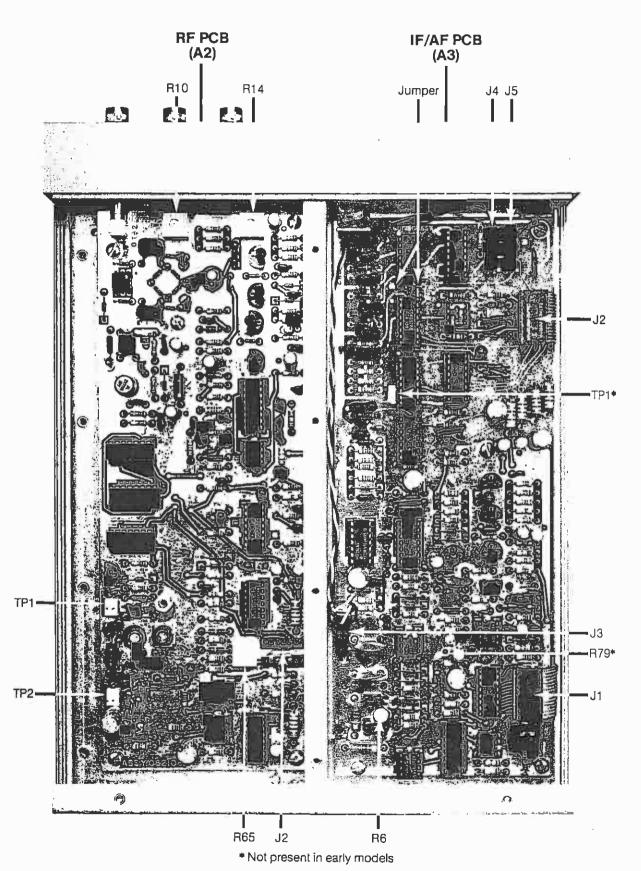


Figure 4-2. Model 8210: Bottom View with Covers Removed

# ¶4-4a, Continued.

- (3) Remove the cover by lifting up and toward the rear of the unit.
- (4) Turn the instrument over and remove the two #4-40 screws securing the bottom cover.
- (5) Remove the bottom cover as in Step (3).

## b. R.F.-Assembly Cover.

- (1) Remove the 8210's covers as in ¶4-4a.
- (2) Place the instrument on a smooth working surface, with the bottom side up.
- (3) Remove the nine #4-40 screws that secure the R.F.-Assembly cover.
- (4) Push the cover toward the rear of the instrument and lift the front of the cover upwards.
- (5) Pull the cover toward the front of the instrument and remove it.

## c. R.F. Circuit Board.

- (1) Remove the instrument's covers (¶4-4a).
- (2) Remove the cover of the r.f assembly (¶4-4b).
- (3) Remove the i.f. connection at the r.f. circuit board.
- (4) Turn the instrument over and disconnect ribbon connector AlP4.
- (5) Remove the five #4-40 screws and the one hex standoff securing the circuit board.
- (6) Carefully slide the circuit board toward the rear of the instrument to disengage the r.f. input connector.
- (7) Lift the circuit board out of the instrument.

#### d. I.F .- A.F. Circuit Board.

- (1) Remove the instrument's covers (44-4a).
- (2) Remove the i.f. connection at the rear of the i.f.-a.f. circuit board.
- (3) Disconnect both ribbon connectors on the left edge of the circuit board.
- (4) Disconnect both two-pin connectors at the front edge of the circuit board; disconnect the two-pin connector at the right edge of the circuit board.
- (5) Remove the five #4-40 screws securing the circuit board, and lift out the board.

#### e. Rear-Panel Assembly.

- (1) Remove the instrument's covers (¶4-4a).
- (2) Disconnect the power connector, AlP14.
- (3) Disconnect the power-switch connector, AlP15.

#### ¶4-4e, Continued.

- (4) Remove three #6-32 screws securing the rear panel to the chassis.
- (5) Remove two #4-40 screws securing the rear panel to the power-supply heat sink.

1.

(6) Pull the rear panel away from the chassis.

# f. Digital Circuits and Power-Supply Board.

- (1) Remove the instrument's covers (¶4-4a).
- (2) Disconnect the four ribbon connectors AlP7, AlP8, AlP9 and AlP11.
- (3) Disconnect pin connector AlPl3.
- (4) Disconnect two-pin connector AlPlO.
- (5) Remove the rear-panel assembly (¶4-4e).
- (6) Remove seven #4-40 screws securing the circuit board, and lift the board out of the chassis.

# g. Display Circuit Board (Access or Removal).

- (1) Remove the instrument's covers (44-4a).
- (2) Remove three #4-40 screws securing the top trim-strip extrusions and grounding clip.
- (3) Grasp the trim strip by its edges and pull it away from the instrument's frame.
- (4) Carefully remove the plexiglass display window.
- (5) Turn the instrument over and remove the bottom trim-strip extrusion as in Steps (2) and (3), above.
- (6) Tilt the bottom of the front trim panel away from the instrument until all switches are cleared, then pull the front panel up and out to clear the center trim extrusion.
- NOTE: This completes the procedure for gaining access to the Display Circuit board. If it is necessary to remove the board, carry on as follows:
- (7) Disconnect the ribbon-cable connector from the rear of the board.
- (8) Disconnect the power-switch connector, AlPl5.
- (9) Disconnect the power-indicator connector, AlPl3.
- (10) Remove the two #4 flat-head screws securing the center trim extrusion. Lift out the extrusion.
- (11) Remove the four #4-40 screws securing the circuit board, and lift the board out of the instrument.

# 4-5. REMOVAL OF DETAIL PARTS In the design of the 8210, much thought was given to maintainability. Most detail parts are readily available for checking and replacement once the instrument's covers and shields are removed. Solid-state components, on plated-through circuit boards, are used throughout the instrument. Sockets are used for all active components except for the power-supply regulators.

#### §4-5, Continued.

Standard printed-circuit-board maintenance techniques are required for the removal and replacement of parts. Excessive heat must be avoided; a low-wattage soldering iron, together with suitable heat sinks, should be used for all soldering and unsoldering operations.

# 4-6. PRELIMINARY CHECKS

a. Visual Check. If equipment malfunction occurs, perform a visual check of the 8210 before performing electrical tests. Visual checks often help to isolate, quickly and simply, the cause of a malfunction. Inspect for signs of damage caused by excessive shock or vibration, such as: broken wires, loose hardware, and loose electrical connections. Then check for signs of overheating, which may be caused by an electrical short-circuit or an accumulation of dirt and other foreign matter.

Correct any problems discovered through the visual check. If the trouble persists, proceed with the electrical checks.

b. <u>Power-Supply Check</u>. Improper operation of the 8210 may be caused by incorrect d.c. operating voltages. Before proceeding with any other electrical checks, perform the power-supply checks given in Table 4-2.

## \*\*\* WARNING \*\*\*

Line voltages up to 240 volts, a.c., may be encountered in the power-supply circuits. To protect against electrical shock, observe suitable precautions when connecting and disconnecting test equipment, and when making voltage measurements.

Table 4-2. Power-Supply Checks

STEP	PROCEDURE	NORMAL INDICATION
1)	Set the LINE switch to ON. Using a digital voltmeter, measure the d.c. voltage at the +15 V supply rail, A4TP5.	14.75 to 15.25 V
2)	Using a digital voltmeter, measure the d.c. voltage at the -15 V supply rail, A4TP2.	-14.75 to -15.25 V
3)	Using a digital voltmeter, measure the d.c. voltage at the +5 V supply rail, A4TP4.	4.90 to 5.10 V
4)	Using a digital voltmeter, measure the d.c. voltage at the -7.5 V supply rail, A4TP3.	-7.33 to -7.68 V
5)	Using a digital voltmeter, measure the d.c. voltage of the +5(L) supply (pin 24, A4Ull).	4.75 to 5.25 V
6)	Using an oscilloscope, measure the a.c. ripple at the +15, -15, +5 and -7.5 V supply rails.	Less than 1 mV peak-to-peak.

In case of abnormal indications, refer to Table 4-11, a systematic trouble-shooting chart for the power supplies.

# 4-7. TROUBLESHOOTING

- a. Concepts. Logical trouble-localization involves three major procedures:
  - symptomatic troubleshooting, used to localize the cause of a malfunction to a major circuit group;
  - (2) systematic troubleshooting within the affected circuit group, used to localize the cause to a specific circuit or stage; and,
  - (3) voltage measurements, waveform analysis, or signature analysis--all used to isolate the defective part.
- b. Symptomatic Troubleshooting: Discussion. The design of the Model 8210 facilitates symptomatic troubleshooting. Various "condition codes" are displayed both as a guide to proper operation and to localize a malfunction to a major circuit group (see Table 4-3). Moreover, certain circuit groups can be switched in and out of operation by an internal seven-position Test Switch (refer to Table 4-4). With a grasp of the detailed block diagrams (Figures 3-1 through 3-8), and of the function of each position of the Test Switch, along with manipulation of the front-panel controls, the user is well on the path to localizing the cause of a malfunction to one or more of the major circuit groups. In addition, a variety of symptoms is listed in Table 4-5, together with the probable causes of the malfunctions.
- c. Systematic Troubleshooting: Discussion. Once you have localized the cause of a malfunction to a major circuit group, refer to the appropriate Systematic Troubleshooting Chart (Tables 4-6 through 4-11). These charts give instructions to help further localize a cause of malfunction to a particular stage or even to the component of that stage likely to be causing the trouble.
- d. Measurements and Analyses: Discussion. The 8210 uses both analog and digital circuitry. Tables 4-6 through 4-11, information on the schematic diagrams (Figures 6-1 through 6-7), and waveform data in Table 4-12, are intended to assist in troubleshooting the analog circuits. Frequently this will suffice—without having to look into the digital circuitry. In case the tests in the analog portions have not solved the problem, some of the troubleshooting tables continue with tests (still using an oscilloscope and voltmeter), for the digital portions of the circuits.

However, the digital circuitry of the 8210 uses a microprocessor in a busoriented system. In such circuits, d.c.- and a.c.-measuring instruments are not always adequate to isolating problems, and a new technique, called signature analysis, has been developed. The troubleshooting chart for the 8210's logic circuits accordingly has tests that utilize an oscilloscope, and also has tests that call for signature analysis.

A complete discussion of signature analysis is beyond the scope of this manual; however, a brief description will aid in understanding its use in maintenance of the 8210.

Long, complex data streams are present in any microprocessor bus-oriented system. In signature analysis, with the system operating at normal speed, these data streams are compressed into concise, easy-to-interpret readouts (signatures) measured at pertinent data nodes. By choosing the appropriate measuring periods, or windows, signatures become unique: one, and only one signature occurs at any given node of the instrument in normal operation.

Using a test device known as a signature analyzer you can therefore proceed through the instrument in an orderly fashion: you compare the signature you find at each specified node to the signature that the instrument's manufacturer tells you ought to be at that node, until an improper signature is obtained. Generally, at that point it is possible for you to deduce which component is the most probable cause of the malfunction.

Table 4-3. Condition-Code Displays

DISPLAY	MEANING
CAL	Instrument in calibration (takes approximately 30 seconds).
ccl	8210 has failed to calibrate properly the a.m. channel.
cc2	8210 has failed to calibrate properly the f.m. channel.
	8210 is unlocked, due to improper r.finput frequency or level or to a malfunction in the r.f. circuits.
	8210 is in unleveled state, due to low modulation frequency or to a malfunction in the i.f. circuits.
IFLO	R.F. input too low in amplitude, or there is a malfunction in the r.f. circuits.
IFHI	R.F. input too high in amplitude, or there is a malfunction in the r.f., i.f., or a.f. circuits.
dsp	The panel meter is over-ranged.

Table 4-4. Troubleshooting Test-Switch Chart

SWITCH POSITION	FUNCTION	AID IN TROUBLESHOOTING THE FOLLOWING CIRCUITS
1	Disables the automatic frequency-lock loop.	a) Oscillator b) Band-switching c) Attenuator d) Discriminator e) Integrator f) Logic
2	Disables the automatic gain control loop.	a) Automatic gain control b) Logic
3	Disables the frequency- control loop and the auto-zero circuit.	a) Audio b) Peak Detector c) Voltmeter
4	Operates data-acquisition circuits in an endless loop.	a) Voltmeter b) Logic

Table 4-4. Troubleshooting Test-Switch Chart (Continued)

SWITCH POSITIO	FUNCTION		AID IN TROUBLESHOOTING THE FOLLOWING CIRCUITS
5	LED test: enables the display (lights all segments), decimal points & annunciators.		Logic; ports A, B, & C of Ul7 and associated buffers. Display circuit-board assembly.
5 Plus LEVEL	Tests I/O port of Ul6. Loads three output ports with hex 55 or hex AA, depending upon PEAK setting.	a)	Logic; ports A, B, & C of Ul6used for logic control of r.f., i.f., a.f. and calibrator circuits.
6	8210 displays month and year of the installed program.		Facilitates testing (sig- nature analysis) of special or updated versions. Aids in ordering correct spare PROM's.
7	Operates calibrator circuits in an endless loop.	b)	Calibrator I.F. A.F.

Table 4-5. Symptomatic Troubleshooting Chart

SYMPTOM	PROBABLE CAUSE OF MALFUNCTION	
After power-on, instrument fails to display CAL.	One of the Test Switches (A4S1) is on; or defective logic circuits (refer to Table 4-9).	
During calibration cycle, 8210 displays CCl.	Defective calibrator circuits (see Table 4-10); or defective i.f. circuits (refer to Table 4-7).	
During calibration cycle, 8210 displays CC2.	Defective i.f. circuits (refer to Table 4-7).	
The 8210 fails to exit from CAL mode.	Defective logic circuits (refer to Table 4-9).	
Instrument fails to lock.	Defective r.f. circuits (Table 4-6).	
8210 locks but fails to level properly.	Defective i.f. circuits (refer to Table 4-7).	
8210 displays IFLO when proper signal is applied to RF IN.	Defective i.f. circuits (refer to Table 4-7).	
8210 displays IFHI when proper signal is applied to RF IN.	Defective i.f. circuits (refer to Table 4-7).	

Table 4-5. Symptomatic Troubleshooting Chart (Continued)

SYMPTOM	PROBABLE CAUSE OF MALFUNCTION	
A.M. incorrect or inoperative.	Defective r.f. circuits (Table 4-6); defective a.f. circuits (Table 4-8).	
F.M. incorrect or inoperative.	Defective a.f. circuits (Table 4-8).	
One or more low-pass filters inoperative.	Defective a.f. circuits (refer to Table 4-8).	
One or more peak indications incorrect.	Defective a.f. circuits (refer to Table 4-8).	
One or more panel switches inoperative.	Defective logic circuits (refer to Table 4-9).	
One or more switch annunciators inoperative.	Defective logic circuits (refer to Table 4-9).	
All digital panel-meter displays incorrect or inoperative.	Defective logic circuits (refer to Table 4-9).	
8210 does not range properly.	Defective a.f. circuits (Table 4-8).	
A.F. output missing or incorrect.	Defective a.f. circuits (Table 4-8).	
I.F. output missing or incorrect.	Defective i.f. circuits (Table 4-7).	

Table 4-6. Systematic Troubleshooting Chart: R.F. Circuits

STE	P PROCEDURE	INDICATION IF	INDICATION IS ABNORMAL
•		OSCILLATOR CIRCUITS	•
#1 cov	Power off. Set Test Switch (A4S1) Pos. to "on." Remove r.f. er & turn power on. nect 'scope to A2TP1.	& 38 MHz, > 1 V, p-p.	Isolate defective component in oscil- lator circuit A2Q8 - A2CR10.
2)	Connect 'scope to collector of A2Q7.	TTL signal between 26 & 38 MHz.	Replace A2Q7 or A2CR7.
3)	Connect 'scope to pin 8 of IC A2U3d.	TTL signal between 26 & 38 MHz.	Replace A2U3.
4)	Connect 'scope to pin 9 of A2Ul.	TTL signal between 13 & 19 MHz.	Replace A2Ul.
	Connect 'scope to pin 3 of A2Ul. ress +PEAK button.	TTL signal, approx. 4 MHz.	Replace A2U2, A2U3; or malfunction in logic circuits (Steps 28-33)
6)	Depress 3 kHz button	TTL signal; frequency should decrease.	Same as in Step 5.

Table 4-6. Systematic Troubleshooting Chart: R.F. Circuits (Continued)

STE	P PROCEDURE	INDICATION IS	r INDICATION IS ABNORMAL
•	OSCI	ILLATOR CIRCUITS (CONTINU	JED) •
7)	Depress the 750 µs button.	TTL signal; frequency should decrease.	Same as in Step 5.
8)	Connect 'scope to pin 6 of A2U1.	See Waveform 1, in Table 4-12.	Replace A2U1; or check for open A2R13, A2C15.
•		PULSE GENERATOR	•
9)	Connect 'scope to collector of A2Q1.	See Waveform 2, in Table 4-12.	Check for open A2CR1, A2Q1, A2R1; or replace A2T1 or A2CR3.
10)	Connect 'scope to junction of A2R8 and A2C7.	See Waveform 3, in Table 4-12.	Check for open A2C7, A2R8, A2R9, A2R20; or replace A2T2 or A2CR4.
11)	Connect 'scope to junction of A2C14 and A2R19.	Same as in Step 10,but with reversed polarity.	Check for open A2C14, A2R19.
•	R.F. INPUT,	SAMPLER, AND SAMPLING A	MPLIFIER •
and 2.4	Connect 'scope to junction of A2R12 A2CR2b. Connect a MHz, +7 dBm signal RF IN connector.	2.4 MHz signal, approximately 1.4 V, peak-to-peak.	Check for open A2C3 or A2R3.
and	Connect 'scope to junction of A2C23 A2R32. Depress the µs button.	Approximately 400 kHz, 1.4 V, p-p, with a 2.8 MHz signal added. See Waveform 4, in Table 4-12.	Isolate defective component in sampler or sampling amplifier by d.c. voltage and waveform measurements.
	Connect 'scope to pin 1, A2U4.	Approximately 5 V, d.c.	Defective 16-conductor ribbon cable W4 (or pin connections); or defective A2U4; or malfunction in logic circuit (Table 4-9).
	Connect 'scope to pin 6 of A2U5. ess 10 RANGE button.	Approximately 400 kHz, with a 2.8 MHz signal added; approximately 600 mV, peak-to-peak.	Replace A2U5 or A2U4; refer to Table 4-9.
•	AUTOMATI	C FREQUENCY-LOCK-LOOP CI	RCUITS •
Depr	Connect 'scope to pin 8 of A2U4. ess the 750 µs and +PEAK buttons.	Approximately 5 V, d.c.	Check for open pin 4 in 16-conductor ribbon cable W4; or replace A2U4; or refer to Steps 34-39.

Table 4-6. Systematic Troubleshooting Chart: R.F. Circuits (Continued)

STEP PROCEDURE		F INDICATION IS ABNORMAL
AUTOMATIC FREC	UENCY-LOCK-LOOP CIRCUITS	(CONTINUED) •
17) Connect 'scope to junction of A2L9 & A2R53. Depress the 100 RANGE pushbutton.	300 to 500 kHz, with a 2.8 MHz signal added; approximately 2.5 V, peak-to-peak.	
18) Depress the 3 kHz button.	Very small residual of signal in Step 17.	Replace A2U4, or see Table 4-9.
19) Connect 'scope to junction of A2LlO & A2R55. Change frequency of generator to about 2.9 MHz.	300 to 600 kHz, with a 3.3 MHz signal added; approximately 2.5 V, peak-to-peak.	Check A2L7 or A2L10 for open circuit; or bad A2U4.
20) Connect 'scope to pin 14 of A2U8.	Same as Step 19, but attenuated by 20 dB.	Check for open A2C48.
21) Connect 'scope to pin 8 of A2U8. Set generator frequency to 2.4 MHz. Depress the 750 µs button.	300 to 500 kHz square wave, about 3.5 V, p-p, on top of approx. 12 V, d.c.	Check A2CRl2 for short circuit; or replace A2U8.
22) Connect 'scope to pin 3 of A2U9. Set i.f. to about 400 kHz by varying generator's frequency above or below 2.4 MHz.	400 kHz square wave, approximately -0.5 to +2 volts.	Check for open A2C57, A2CR12, A2CR11; or replace A2U9.
23) Connect 'scope to pin 6 of A2U9.	TTL signal, with pulse about 2.5 µs wide.	Check for open A2R70, A2C58; or replace A2U9.
24) Connect 'scope to pin 7 of A26U. Depress -PEAK button.	400 kHz square wave, approximately 5.5 V, peak-to-peak.	Check for open A2R65. Replace A2U6. Refer to Steps 34-39.
25) Connect 'scope to pin 1 of A2U6. Depress the 3 kHz and +PEAK buttons.	0 volts, d.c., approx.	Replace A2U7 or A2U6; check for open A2R51. Refer to Steps 34-39.
26) Depress the -PEAK & 750 µs buttons. Vary generator's frequency about 50 kHz above & below the initial setting.	A.C. ripple < 400 mV, p-p. D.C. voltage will move below & above the baseline as the frequency of the r.f signal is changed.	Check for open A2C47. Replace A2U7. Refer to Steps 34-39.
27) Reset generator's frequency for 0 V at pin 1 of A2U6. Press the AVG button. Offset the generator frequency by 100 kHz.	Initially, 0 V, d.c., then slowly drifting to approximately ± 2.4 volts, d.c.	Defective A2C47; or replace A2U7 or A2U6. Refer to Steps 34-39.

Table 4-6. Systematic Troubleshooting Chart: R.F. Circuits (Continued)

	EDURE	INDICATION	IF INDICATION IS ABNORM
•	DIGITAL POI	TION: OSCILLAT	TOR BANDSWITCHING
28) Connect pin 2 of Depress 15 kM	A2U3.	volts, d.c.	Repair or replace W4 cable, or refer to Table 4-9.
29) Depress to filter but	the 3 kHz (	volts, d.c.	Same as Step 28.
30) Depress t	the 750 µs s	volts, d.c.	Same as Step 28.
31) Connect 'pin 4 of Depress 15 km	A2U3.	) volts, d.c.	Same as Step 28 or replace defective A2U4
32) Depress t	the 3 kHz	volts, d.c.	Same as Step 31.
33) Depress t	the 750 µs 5	volts, d.c.	Same as Step 31.
• DIGITAL F	PORTION: AUTOM	ATIC FREQUENCY	-LOCK-LOOP SWITCHING LOGIC
34) Connect 'pin 10 of		volts, d.c.	Check for open circuin W4 cable; replace A2U7; or check mal-
DODIESS TREME			function in logic circuits (see Table 4-9)
	he -PEAK 0	volts, d.c.	
35) Depress t button.	}	volts, d.c.	cuits (see Table 4-9)  W4 cable may have a short circuit; or loo for malfunction in the logic circuits (see
35) Depress to button.  36) Depress A	NVG button. 0		cuits (see Table 4-9)  W4 cable may have a short circuit; or loo for malfunction in the logic circuits (see Table 4-9).
35) Depress to button.  36) Depress A  37) Connect 'pin 11 of	Scope to 0	volts, d.c.	cuits (see Table 4-9)  W4 cable may have a short circuit; or loo for malfunction in the logic circuits (see Table 4-9).  Same as Step 34 or 35
35) Depress to button.  36) Depress A  37) Connect 'pin 11 of  38) Depress to	scope to 0 A2U7.	volts, d.c.	cuits (see Table 4-9  W4 cable may have a short circuit; or lo for malfunction in tagic circuits (see Table 4-9).  Same as Step 34 or 3  Same as Step 34 or 3

Table 4-7. Systematic Troubleshooting Chart: I.F. Circuits

STEP PROCEDURE	INDICATION IE	INDICATION IS ABNORMAL
<pre>1) Power off. Set Test     Switch (A4S1) Pos. #7 "on." Power on. Do NOT press LEVEL button.</pre>		
2) Connect 'scope to pin 3 of A3U1. Depress the AM button.	447.4 kHz sine wave, approximately 1.9 V, peak-to-peak.	Open pin 15 in W5, the 16-conductor ribbon cable; or malfunction in calibrator circuits (see Table 4-10, Steps 1 through 9).
3) Connect 'scope to pin 6 of A3Ul.	Same as Step 2, but doubled in amplitude.	Replace A3U1.
4) Connect 'scope to pin 1 or pin 16 of A3U3.	874 Hz TTL signal.	Open pin 13 in the W5 cable; or check for a malfunction in calibrator circuits (Table 4-10, Steps 2 and 5).
5) Depress FM button.	TTL logic 1.	Malfunction in cali- brator circuits (see Table 4-10, Step 8).
6) Depress AM button. Connect 'scope to pin 6 of A3U3.	447 kHz sine wave, audio-modulated at an 874 Hz rate; 1.15 V, p-p. See Waveform 5, Table 4-12.	Check for defective A3R7a through A3R7c; or defective A3U3.
7) Connect 'scope in turn to pins 5 through 12 of A3U4.	On pin 6, a TTL high; on all others, TTL low.	Defective W5 cable; or malfunction in logic circuits (Table 4-9)
8) Connect 'scope to pin 4 of A3U4.	Same waveform as in Step 6; approximately 540 mV, p-p. (Depends upon setting of A3R79.)	Isolate defective component by voltage or waveform measurements. Check for open A3CR13, A3C4, A3C5, A3C6, A3R79; or replace A3U4
9) Connect 'scope to pin 6 of A3U5.	Same as Step 6, but amplified to approx. 2.85 V, peak-to-peak.	Isolate defective component by voltage or waveform measurements.
10) Connect 'scope to the junction of A3C23 and A3CR6.	Same as Step 6, but amplified to approx. 5.7 V, peak-to-peak.	Isolate defective component by voltage or waveform measurements. Check for open A3C19, A3C22, A3C18, A3CR6, or A3CR7.
11) Connect 'scope to the junction of A3CR7 and A3R41.	The above waveform, half-wave rectified; 2.3 V, p-p. See Waveform 6, Table 4-12.	Same as Step 10.

Table 4-7. Systematic Troubleshooting Chart: I.F. Circuits (Continued )

STEP PROCEDURE	INDICATION IF	INDICATION IS ABNORMAL
12) Connect 'scope to pin 11 of A3U10.	5 volts, d.c.	Defective 16-conductor ribbon cable W6 (or pin connections); or malfunction in logic circuits (Table 4-9).
13) Connect 'scope to pin 8 of A3U9.	874 Hz square wave & added 447 kHz sawtooth; about 1.3 V, p-p. See Waveform 7, Table 4-12.	Defective A3C27, A3R47; or replace A3U9.
14) Connect 'scope to pin 3 of A3Ul0.	Same as Step 13.	Replace defective A3U10.
15) Connect 'scope to pin 6 of A3U8.	Same as Step 9.	Defective A3U8; "short' in A3CR9 or A3CR10.
16) Connect 'scope to IF OUT connector.	Same as Step 9.	Defective AlPl, AlWl, or AlJ3.
17) Connect 'scope to collector of A3Ql; Set time-base of 'scope to l µs/div.	447 kHz TTL signal. See Waveform 8 in Table 4-12.	Isolate defective component by voltage or waveform measurements. Suspect A3Ql, A3Q2, A3CR3, A3CR4, or A3CR5.
18) Connect 'scope to pin 1 of A3U7. Time- base at 0.5 µs/div.	A pulse: width about 2.1 to 2.4 µs; amplitude 5 V, p-p.	Width: check timing components A3C20,A3R33 or replace A3U7. Amplitude: check A3R43 through A3R46.
19) Connect 'scope to pin 13 of A3U10. Depress FM pushbutton.	447 kHz sawtooth; -0.5 to -2 volts, p-p.	Isolate defective component by voltage or waveform measurements. Check for open A3C28; or bad logic circuits (see Table 4-9).
20) Set Test-Switch Pos. #7 "off," #2 "on." Power "off," then "on."	12.8 appears on the front-panel display.	Malfunction in logic circuits (Table 4-9).
21) Connect 'scope to junction of A4R20 & A4C15; set for d.c. and V. Sensitivity @ 0.05 V per div. Hold depressed -PEAK button until 8210 displays 1.9 or 2.0.	Approximately 0.25 V, d.c.	Open A3R77; or defect in A1P5, A1W5, A1P8, A4R20, A4C15 or A4U20.
22) Adjust V. Position on 'scope so trace nears bottom of screen. Hold depressed +PEAK pushbutton of 8210.	Rise in d.c. voltage should be smooth (no "steps"), to about 3.5 V, d.c.	Defective A3J1, A1P5, A1W5, A1P8, A4J2, or A3U4; or defective logic circuits (see Table 4-9).

Table 4-71 Systematic Troubleshooting Chart: I.F. Circuits (Continued)

STEP PROCEDURE	INDICATION IF	INDICATION IS ABNORMAL
23) Set Pos. #2 on Test Switch (A4S1) "off." Turn power off, then on. Allow completion of the calibration cycle. To RF IN apply a 30 MHz, -10 dBm signal with 50% 1 kHz a.m. Connect the 'scope to the junction of A3L3 and A3R3.		
24) Connect 'scope to pin 6 of A3U2.	Same as Step 23, but amplitude increased to about 3.5 V, p-p.	Isolate defective com- ponent in circuit of input amplifier, using voltage and waveform measurements.
25) Connect 'scope to pin 8 or 9 of A3U3.	A TTL high.	Defective 16-conductor ribbon cable W5 (or pin connections); or malfunction in logic
26) Connect 'scope to pin 6 or 11 of A3U3.	A TTL low.	circuits (Table 4-9); or replace defective A3U3.
27) Increase level of generator to more than +13 dBm.	Display shows IFHI.	Defect in circuits of: a.f. (see Table 4-8); r.f. (Table 4-6); or logic (Table 4-9).
28) Reduce generator's level to -40 dBm.	Display shows IFLO.	Same as Step 27.

Table 4-8. Systematic Troubleshooting Chart: A.F. Circuits

STEP PROCEDURE	INDICATION	IF INDICATION IS ABNORMAL
A3TP1.* (c) Remove to "on," (e) Set a.f. the a.f. signal to the *Early 8210's do change (f) as fo	A3U10. (d) Set Pos oscillator for 1 kHz	. signal to pin 3 of
NOTE: "INDICA	ATIONS" in this Table	are approximate.
2) Depress the front- panel 10 RANGE push button. Connect 'scope to pin 13 of A3U11.	n- 300 mV, peak-to-pea	ak. Isolate defective component in the filter circuit A3U9c by waveform measurements. See also Steps 33 - 40.

Table 4-8. Systematic Troubleshooting Chart: A.F. Circuits (Continued)

	<u> </u>	
STEP PROCEDURE	INDICATION IF	INDICATION IS ABNORMAL
3) Set a.f. oscillator to about 72 kHz.	72 kHz sine wave; 210 mV (approx.), p-p	Same as Step 2.
4) Set a.f. oscillator to 1 kHz. Connect 'scope to pin 3, A3U11.	l kHz sine wave; 300 mV, peak-to-peak.	Defective A3Ull; or see Steps 33 - 40.
5) Depress 100 RANGE pushbutton.	As above, amplitude reduced by 20 dB (× 0.1).	As above; also check for defective A3R59.
6) Depress 10 RANGE. Connect 'scope to pin 14 of A3U9.	1 kHz sine wave; 3.3 V, peak-to-peak.	Replace A3U9, A3R61,or A3R63. Check for open decoupling capacitors.
7) Connect 'scope to pin 12 of A3U13.	Same as Step 6.	Isolate defective component in A3Ul2a circuit; or defective A3Ul2, A3Ul3.
<ol><li>Set a.f. oscillator to 5 kHz.</li></ol>	5 kHz sine wave; 3.3 V, peak-to-peak.	Same as Step 7.
<ol><li>Set a.f. oscillator to 15.00 kHz.</li></ol>	15 kHz sine wave; 2.25 to 2.41 V, p-p.	Check A3R71 or A3C47.
10) Set a.f. oscillator to 750 Hz. Connect 'scope to pin 14, A3U13.	750 Hz sine wave; 3.3 volts, peak-to-peak.	Isolate defective component in A3U12b circuit; or defective A3U12, A3U13.
<pre>11) Set a.f. oscillator     to 3.00 kHz.</pre>	3 kHz sine wave; 2.25 to 2.41 V, p-p.	Check for defective A3R68 or A3C44.
<pre>12) Set a.f. oscillator     to 50 Hz. Connect 'scope to pin 15, A3U13.</pre>	50 Hz sine wave; 3.3 volts, peak-to-peak.	Check for defective A3R69 or A3C45.
13) Set a.f. oscillator to 212 Hz.	212 Hz sine wave; 2.25 to 2.41 V, p-p.	Same as Step 12.
14) Set a.f. oscillator 5.00 kHz. Connect 'scope to pin 11, A3U13.	5 kHz sine wave; 2.2 volts, peak-to-peak.	Check for open/shorted capacitor, or open resistor. Check A3Ul3.
15) Perform tests given in Steps 38 and 39.		
<pre>16) Set a.f. oscillator     to l kHz. Depress 8210's 15 kHz button. Connect 'scope to A3J4.</pre>	l kHz undistorted waveform; 8.38 volts, peak-to-peak.	Isolate defective com- ponent, by voltage and waveform measurements, in A3U14 circuit.
17) Connect 'scope to pin 3 of A3U15. Depress 3 kHz button.	l kHz sine wave,square- wave modulated; 3.3 V, peak-to-peak.	Isolate bad component, in A3U12-A3U15 circuit, by waveform measurements. See Step 40.

Table 4-8. Systematic Troubleshooting Chart: A.F. Circuits (Continued)

STEP PROCEDURE	INDICATION I	F INDICATION IS ABNORMAL
18) Connect 'scope to A3J5. Depress the button labeled 750 μs.	Same as Step 17, but approximately 670 mV, peak-to-peak.	Defective A3Ul2, or shorted two-conductor cable W7.
19) Connect 'scope to AF OUT. Depress the button labeled 15 kHz.	Same as Step 16.	Defective AlP2, AlW2, or AlJ4.
20) Connect 'scope to A4J5.	Same as Step 17.	Repair or Replace W7 (two-conductor cable).
21) Connect 'scope to pin 10 of A4U22.	5 volt logic signal.	Malfunction in logic circuits (Table 4-9).
22) With a 2nd 'scope probe, connect to pin 6, A4U23 (see Table 4-12, Fig.9, for 'scope settings).Connect r.m.s. voltmeter to AF OUT.Set a.f. oscillator to 50 Hz & adjust output for 2 V, r.m.s., on VM.	See Waveform 9 in Table 4-12.	Isolate defective components by waveform measurements. Suspect A4U22, A4U21, A4U23,or open A4CR4, A4CR6.
23) Connect probe B to pin 6, A4U24. See Table 4-12, Fig.10, for 'scope settings.	See Waveform 10 in Table 4-12.	Isolate defective component by waveform measurements. Suspect A4U22, A4U21, A4U24,or open A4CR5, A4CR7.
24) Connect probe B to pin 3, A4U20.	See Waveform 11 in Table 4-12.	Defective A4U20; or malfunction in logic circuits (Table 4-9).
•	VOLTMETER SECTION	,
25) Power off. Set Test Switch Pos.#4 "on." Power on. "Short" pins 1 and 2 of A4TP6.		
26) Check the logic on pins 9, 10 & 11 of A4U20.	All high.	Malfunction in logic circuits. See Table 4-9, Steps 49 and 50.
27) Connect d.c. volt- meter to junction of A4R20 and A4Cl5.	Indicated d.c. voltage should be approx. 1 V.	Check for open circuit at pin 2 of cable W6 (16-conductor cable).
28) Move VM probe to pin 3 of A4U20.	Same as Step 27.	Replace defective A4U20.
29) Move VM probe to pin 6 of A4U2.	Indicated d.c. voltage 2.4 to 2.47 volts.	Replace defective A4U2.

Table 4-8. Systematic Troubleshooting Chart: A.F. Circuits (Continued)

STEP PROCEDURE	INDICATION I	F INDICATION IS ABNORMAL
• VC	LIMETER SECTION (CONTINU	JED) •
30) Connect 'scope to pin 6, A4U6. Adjust trigger level of 'scope for stationary display.	TTL signal; period approximately 1.5 µs.	Malfunction in logic circuits. Replace de- fective A4U6 or A4Q4.
31) Connect 'scope to collector of A4Q4. Adjust trigger level for stationary display.	Similar to Step 30, but signal swings from +12 to +14 volts.	Replace defective A4Q4 or A4U4.
32) Set 'scope for d.c., V. Sens.@ 0.2 V/div. & 0.05 μs/div. Connect probe to pin 2 of A4U4. Set trigger level for a stationary display.	Approximately 0.6 V, d.c.	Check for open diode A4CR2, or malfunction in logic circuits (see Table 4-9, Steps 1-14); or replace A4U4 or A4U7.
33) Remove short from pins 1 & 2, A4TP6.	D.C. voltage will go negative.	Same as Step 32.
• DIG	ITAL PORTION: A.F. CIRCU	ITS
34) Connect 'scope to pin 11 of A3U10. Depress the FM FUNCTION pushbutton.	CMOS low.	Defective A3J2, A1P6, A1W6, A1P9; or logic-circuit malfunction (refer to Table 4-9).
35) Depress the AM FUNCTION pushbutton.	CMOS high.	Same as Step 34, or defective A3Ul0.
36) Connect 'scope to pin 11, A3U11. De- press 100 RANGE button.	CMOS high.	Same as Step 34, or defective A3Ull.
37) Depress 10 RANGE.	CMOS low.	Same as Step 34.
38) Connect 'scope to pin 10, A3U11.Power off, then on, quickly.	Normal CMOS "low" will move toward "high" as power is switched on.	Same as Step 36.
39) Connect 'scope to pin 10 of A3U13. Depress, in turn: 15 kHz pushbutton; 3 kHz pushbutton; 750 µs pushbutton.	CMOS low. CMOS high. CMOS low.	Same as Step 34. As above, or bad A3Ul3. Same as Step 34.
40) Connect 'scope to pin 9 of A3Ul3. Depress, in turn: 15 kHz pushbutton; 3 kHz pushbutton; 750 µs pushbutton.	CMOS low. CMOS low. CMOS high.	Same as Step 34. Same as Step 34. As above, or bad A3U13
41) Connect 'scope to pin 9 of A3U15.	CMOS logic signal.	Same as Step 34, or defective A3U15.

Table 4-9. Systematic Troubleshooting Chart: Logic Circuits

STEP P	ROCEDURE	INDICATION IF	'INDICATION IS ABNORMA
l) Conne	ct 'scope to 0 of A4U1.	3.579 MHz TTL logic signal.	Replace A4Ul, A4Yl, c
	ct 'scope to of A4Ul.	Same as Step 1.	Replace A4U5.
3) Conne	ct 'scope to of A4U8.	1.789 MHz TTL signal.	Replace A4U5 or A4U9.
	ct 'scope to of A4U3.	Approximately 874 Hz CMOS logic signal.	Replace A4U3.
5) Conne	ct 'scope to of A4U3.	447.35 kHz CMOS logic signal.	Replace A4U3 or A4U12
	ct 'scope to 6 of A4U8.	TTL high.	Replace A4Ul, or chec for shorted A4Cl.
jumpe signature Table 4-9 Run signa	off. Remove r A4J8.Connect analyzer per a. Power on. ture-analysis he address bus.	See Table 4-9a.	Defective A4U8, or a "short" in circuitry.
turn	ct 'scope in to data bus - D7 of A4U8.	TTL signals on all lines.	Same as Step 7.
	ct 'scope in to remaining 4U8.	TTL signals on pins 19, 21, 27 & 28. Pins 17, 18, 20, 22, 24 and 25 are TTL high.	Same as Step 7.
10) Conne pin 8	ct 'scope to of A4U6.	TTL logic signal	Defective A4U6, or a "short" in circuitry.
analy: 4-9b and	ct signature zer per Table run test on er: A4Ul0.	See Table 4-9b.	Defective A4U10, or a "short" in circuitry.
analy:	ct signature zer per Table : PROM A4Ull.	See Table 4-9c.	Defective A4U11, or a "short" in circuitry.
analy:	ct signature zer per Table : PROM A4Ul3.	See Table 4-9c.	Defective A4Ul3, or a "short" in circuitry.
	ce jumper A4J8. ct 'scope to A4U8.	TTL high.	Replace A4U14 or A4U1 or both, or A4U6.
	ct 'scope to of A4U5.	TTL logic signal,	Defective A4Ul, or a "short" in circuitry.

Table 4-9. Systematic Troubleshooting Chart: Logic Circuits (Continued)

STEP	PROCEDURE	INDICATION I	F INDICATION IS ABNORMAL
16) (	Connect 'scope to pin 6 of A4U5.	TTL logic signal, 1.15 ms period.	Replace A4U5, A4U6, or A4U8.
17) C	Connect 'scope to pin 6 of A4U6.	TTL logic signal.	Replace A4U6 or A4Q4.
18) C	Connect 'scope to pin 8 of A4U6.	TTL logic signal.	Defective A4U6, or a "short" in circuitry.
19) C	Connect 'scope to pin 35 of A4Ul6.	TTL low.	Replace A4Ul.
20) C	Connect 'scope to oin 35 of A4U17.	TTL low.	Same as Step 19.
t	Connect 'scope in turn to pins 18 agh 22 of A4U17.	TTL logic signal.	Replace A4U17 or A4U18; or check for a "short". in circuitry.
t	Connect 'scope in curn to pins 11 igh 15 of A4U18.	Same as in Step 21.	Defective A4U18, or a "short" in circuitry; or defective A4R16.
	Connect 'scope to in 4 of A4U17.	TTL low.	Defective A4U17, or a "short" in circuitry.
24) D	epress the 15 kHz bushbutton.	See Waveform 12 in Table 4-12.	Check for open circuit: 16-conductor cable w8 (and its connections); also, A4CR8 & A4S8.
	epress the +PEAK ushbutton.	Same as in Step 24.	As above: W8 (etc.), A4CR9, A4S9.
	epress the FM ushbutton.	Same as in Step 24.	As above: W8 (etc.), A4CR10, A4S10.
	epress the 100 ANGE pushbutton.	Same as in Step 24.	As above: W8 (etc.), A4CRll, A4Sll.
	onnect 'scope to in 3 of A4U17.	TTL low.	Defective A4Ul7, or a "short" in circuitry.
	epress the 3 kHz ushbutton.	Same as in Step 24.	Replace A4Ul7; check for open circuit in W8 (and its connections), or in A4S4.
	epress the -PEAK ushbutton.	Same as in Step 24.	Check for open circuit in W8 (etc.), & A4S5.
	epress the AM ushbutton.	Same as in Step 24.	As above: W8 (etc.), A4S6.
	epress the 10 ANGE pushbutton.	Same as in Step 24.	As above: W8 (etc.), A4S7.

Table 4-9. Systematic Troubleshooting Chart: Logic Circuits (Continued)

STEP PROCEDURE	INDICATION IE	F INDICATION IS ABNORMAL
33) Connect 'scope to pin 2 of A4U17.	TTL low.	Replace A4Ul7; check "short" in circuitry.
34) Depress the 750 μs pushbutton.	Same as in Step 24.	Check for open circuit W8 (etc.), A4S1.
35) Depress the AVG pushbutton.	Same as in Step 24.	As above: W8 (etc.), A4S2.
36) Depress the LEVEL pushbutton.	Same as in Step 24.	As above: W8 (etc.), A4S3.
37) Set "on," one at a time, each position of Test Switch, A4S1; as each one is turned on, connect 'scope in turn to pins 3 through 9 of A4R14.	Same as in Step 24, on each pin, as each Test Switch position is turned 'on."	Replace A4U17, A4S1, or A4R14.
38) Set Test Switch Pos. #5 to "on." Turn power off, then on.	All display segments and legends "on."	Continue Steps 39 - 43 (If "Indication" is good, jump to Step 44.)
39) Connect 'scope in turn to pins 1 through 8 of A4U19.	See Waveform 13 in Table 12.	Replace defective A4U17 or A4U19.
40) As above, pins ll through 18.	See Waveform 14 in Table 4-12.	Defective A4U19, or a "short" in circuitry.
41) Connect 'scope in turn to pins 9 through 16 of A5J1.	Same as in Step 40.	Check for "open" in W8 (etc.); or replace LED A4CR2 through A4CR7.
42) Connect 'scope in turn to pins 14 of A4SD1,A4SD2,A4SD3,A4SD4.	Same as in Step 24.	Check for open circuit in W8 (etc.).
43) Visually inspect display for missing segments or decimal points.	Same as in Step 38.	If the same segment is out on A4SD2 through A4SD4, check for open circuit. If outage is not common, replace
14) Depress the LEVEL pushbutton.		faulty display(s).
15) Depress the +PEAK button. Connect the scope in turn to pins PAO through PA7, A4U16.	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Replace A4Ul6 or A4Ul0; or check for a "short" in their circuitry.
6) Depress the -PEAK button. Connect the scope in turn to pins PAO through PA7, A4U16.	0 1 0 1 0 1 0 1	Same as in Step 45.

Table 4-9. Systematic Troubleshooting Chart: Logic Circuits (Continued)

STEP PROCEDURE	INDICATION IF	INDICATION IS ABNORMAL
47) Connect the 'scope in turn to pins PBO through PB7 of A4U16.	Same as in Step 46.	Defective A4Ul6; or a "short" in circuitry.
48) Depress the +PEAK button. Connect the 'scope in turn to pins PBO through PB7, A4U16.	Same as in Step 45.	Same as in Step 47.
49) Connect the 'scope in turn to pins PC0 through PC7 of A4U16.	Same as in Step 45.	Replace A4U16 or A4U20; or check for a "short" in their circuitry.
50) Depress the -PEAK button. Connect the 'scope in turn to pins PCO through PC7, A4U16.	Same as in Step 46.	Same as above.
51) Set Test Switch Pos. #5 "off." Power off. Power on.	Instrument is returned to operating condition.	

Table 4-9a. Signature-Analysis Chart: Address Field

PROCEDUI	and-Digita]	Circuits boa	ard. Set	located on the the Signature wan below. Turn	Analyzer's	
SIGNATU	SIGNATURE ANALYZER SWITCH SETTINGS & CABLE-CONNECTION POINTS:					
Function	switch	<u>Setting</u>	Cable	Connection		
START		-	Pin	5 of A4U8		
STOP	٦	•	Pin 2	0 of A4U7		
CLOCK	7_		pin 2	l of A4U8		
	SIGNA	TURE ANALYZER	R PROBE C	ONNECTIONS:		
<u>Item</u>	Test Point: Pin on A4U8	Correct Signature	<u>Item</u>	Test Point: Pin on A4U8	Correct Signature	
Common	29	0000	A7	37	A3C1	
V <sub>CC</sub>	11 30	755U H335	AB A9	38	7707	
Al	31	C113	. A9	39 40	577A HH86	
A2	32	7050	All	1	89F1	
A3	33	0772	A12	2	AC99	
A4	A4 34 C4C3 A13 3 PCF3					
A5 A6	35 36	AA08 7211	A14 A15	<b>4</b> 5	1180	
A.		7211	WI 2		755U	

Table 4-9b. Signature-Analysis Chart: Decoder Circuit

PROCEDUI	RE: Same as in	Table 4-9a.			
SIGNATU	RE ANALYZER SWI	TCH SETTINGS	& CABLE-C	CONNECTION POINT	S:
Function Switch Setting Cable Connection					
START	START Pin 5 of A4U8				
STOP	Ţ		Pin 20	of A4U7	
CLOCK			pin 2	of A4U8	
	SIGNA	TURE ANALYZER	PROBE CO	ONNECTIONS:	
Item	Test Point: Pin on A4U10	Correct Signature	<u> Item</u>	Test Point: Pin on A4U10	Correct Signature
Common +5 V CSO CS1	8 16 1 2	0000 755U 4CP2 UlU2	CS2 CS3 CS4	3 5 7	P352 8UH9 F615

Table 4-9c. Signature-Analysis Chart: PROM's A4Ull & A4Ul3 (Sept.,1982\*)

PROCEDUF	RE: Same as in	Table 4-9a.				
SIGNATURE ANALYZER SWITCH SETTINGS & CABLE-CONNECTION POINTS:						
	Cable Connection					
Function	Switch S	Setting .	Testing A	<u>4U11</u>	Tes	ting A4Ul3
START	7_		Pin 1 of	A4U10	Pin	2 of A4U10
STOP		Ţ		A4U10	Pin	2 of A4U10
CLOCK	Ţ		Pin 21 of	A4U8	Pin	21 of A4U8
SIGNATURE ANALYZER PROBE CONNECTIONS:						
<u>Item</u>	Test Point: Pin on A4Ull	Correct Signature	Item	Test Po Pin on		Correct Signature
Common +5 V D0 D1 D2 D3 D4 D5 D6	12 24 9 10 11 13 14 15 16	0000 7A.70 UPU3 1POP 56FP 0104 41C6 1745 F799 900U	Common +5 V DO D1 D2 D3 D4 P5 D6	12 24 9 10 11 13 14 15 16		0000 7A70 27F3 5011 331H 9P80 0A2F 762C 7621 H89F

<sup>\*</sup> To determine date of PROM's: Set Pos. #6 of the Test Switch (A4S1) "on". Turn power off, then on. The date of the PROM's will appear on the 8210's display. Reset the Test Switch (all positions "off").

Table 4-10. Systematic Troubleshooting Chart: Calibrator Circuits

STEP PROCEDURE	INDICATION IF	INDICATION IS ABNORMAL
1) Power off. Set Pos. #7 of Test Switch (A4S1) "on." Power on. Depress LEVEL button. Connect 'scope to pin 2 of A4U9.	1.79 MHz TTL logic signal.	Replace A4U9, or bad logic circuits (see Table 4-9).
2) Connect 'scope to pin 3 of A4U9.	TTL signal, at about 874 Hz.	Replace A4U9 or A4U12; or defective logic circuits (Table 4-9).
3) Connect 'scope to pin 9 of A4U9.	TTL signal, switching from 357.9 to 447.4 kHz at an 874 Hz rate.	Replace A4U9.
4) Connect 'scope to pin 4 of A4U12.	TTL signal, 447.4 kHz.	Replace A4Ul2, or bad logic circuits (see Table 4-9).
5) Connect 'scope to pin 12 of A4U12.	TTL signal, 874 Hz.	Same as in Step 2.
6) Connect 'scope to pin 7 of A4Ul2. Depress the AM button.	TTL signal, 447.4 kHz.	Replace A4Ul2, or bad logic circuits (Table 4-9, Steps 44 - 50).
7) Connect 'scope to pin 9 of A4U12.	TTL signal, 874 Hz.	Same as in Step 6.
8) Depress FM button.	TTL high.	Same as in Step 6.
9) Connect 'scope to pin 3 of A3U1. Depress the AM button.	Sine wave, 447.4 kHz; approximately 1.9 V, peak-to-peak.	Check for open A4L1, A4L2, A4C8, A4C10, A4C11, or 16-conductor cable W5 (or its connections); or replace defective A3U1.
10) Connect 'scope to pin 6 of A3U1.	Same as in Step 9, but doubled in amplitude.	Replace defective A3U1
11) Connect 'scope to IF OUT connector.	See Waveform 15, Table 4-12.	Bad i.f. circuits. Refer to Table 4-7,Steps 4 through 9, and 15.
12) Depress FM button	See Waveform 16, Table 4-12.	Replace A4U9; or bad i.f. circuits (see Table 4-7).
13) Connect 'scope to AF OUT connector. Depress the AM button.	874 Hz, 2.5 V, p-p. See Waveform 17, Table 4-12.	Bad i.f. circuits (refer to Table 4-7, Steps 4 through 10); or bad a.f. circuits (refer to Table 4-8, Steps 1 through 6, and 14 through 16).

Table 4-11. Systematic Troubleshooting Chart: Power Supply

STEP PROCEDURE	INDICATION I	r INDICATION IS ABNORMAL
(Line Voltage = 120)		
1) Connect 'scope to the junction of A4CR8 and A4C23.	8.55 to 9.45 V, d.c.; ripple approximately 350 mV, peak-to-peak.	Isolate defective com- ponent by voltage or waveform measurements.
2) Connect 'scope to the junction of A4CR9 and A4C24.	19.0 to 21.0 V; ripple approximately 350 mV, peak-to-peak.	Same as above.
3) Connect 'scope to the junction of A4CR9 & A4C25.	-19 to -21 V; ripple approximately 800 mV, peak-to-peak.	Same as above.
4) Connect voltmeter to pin 4, 6, or 8 of A4U7.	9.9 to 10.1 V, d.c.	Check A4C34 for short circuit; or defective A4U29, A4U7.
5) Connect VM & 'scope to the junction of A4CR18 and A4C35.	14.75 to 15.25 V; ripple less than 1 mV, peak-to-peak.	Isolate defective com- ponent by voltage measurements.
<ol> <li>Connect VM &amp; 'scope to the junction of A4CR19 and A4C36.</li> </ol>	-14.75 to -15.25 V; ripple less than 1 mV, peak-to-peak.	Same as Step 5.
7) Connect VM & 'scope to pin 7 of A4U29.	7.33 to 7.68 V; ripple less than 1 mV, peak-to-peak.	Same as Step 5.
8) Connect VM & 'scope to the junction of A4CR15 and A4C33.	4.75 to 5.25 V; ripple less than 1 mV, peak-to-peak.	Same as Step 5.
9) Connect VM & 'scope to the junction of A4CR17 and A4C32.	4.90 to 5.10 V; ripple less than 1 mV, peak-to-peak.	Same as Step 5.

4-8. ADJUSTMENT AND ALIGNMENT PROCEDURES
This subsection lists all required adjustments and alignment procedures.
Note, however, that adjustment is not a substitute for troubleshooting; be certain that all other possible causes of equipment malfunction have been eliminated before making adjustments.

Connect the equipment, and depress the switches, as shown in Figure 4-3.

# a. I.F. Adjustment.

- (1) Remove the r.f.-assembly cover (¶4-4b).
- (2) Set the output frequency of the signal generator to 100 MHz, c.w., and the output level to 0 dBm.
- (3) Adjust potentiometer A2R65 for a reading of 400 kHz,  $\pm$  5 kHz, on the frequency counter.

# §4-8, Continued.

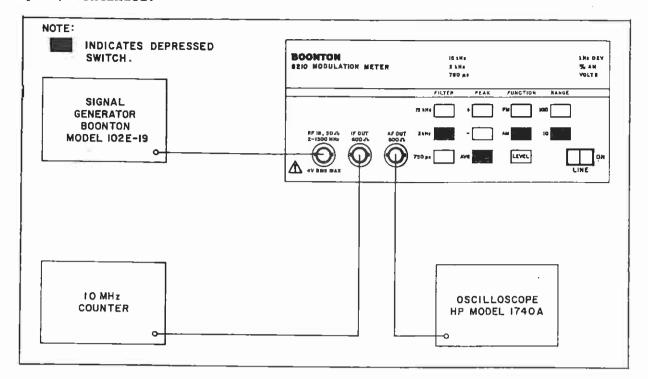


Figure 4-3. Test Setup: Adjustment and Alignment

# b. R.F. Efficiency and F.M. Rejection.

- (1) Replace the r.f.-assembly cover.
- (2) Set the oscilloscope to 0.05 V/division and 1 ms/division.
- (3) Set the signal generator to 2 MHz, 0 dBm. Apply 100 kHz deviation at a 1 kHz rate. Let the i.f. to settle to within ± 5 kHz of 400 kHz (or, disconnect the 8210's r.f. input, then reconnect it).
- (4) Adjust potentiometer A2R10 for a minimum indication on the 'scope.
- (5) Set 102E-19's r.f. to 3.5 MHz. Wait 'til i.f. is  $400 \text{ kHz} \pm 5 \text{ kHz}$ .
- (6) Adjust potentiometer A3R6 for a minimum indication on the 'scope.
- (7) Repeat Steps 4-8b(3) through 4-8b(6) until the adjustment of either potentiometer increases the indication on the oscilloscope.

# c. R.F. Sensitivity Adjustment (excepting early models; see Note, below).

- (1) Set the 102E-19 to 2 MHz, approx. -29.5 dBm. Remove all modulation.
- (2) If the 8210 displays IFLO, slowly adjust potentiometer A3R79\* until a numeric display (i.e., a display of residual modulation) appears.
  \* NOTE: Early model 8210's do not have potentiometer A3R79.

## d. R.F. Balance Adjustment.

- (1) Disconnect the r.f. input to the 8210.
- (2) Disconnect the 'scope from AF OUT and connect it to RF IN.
- (3) Set the 'scope to 0.005 V/div., 50  $\Omega$  input, and 0.5  $\mu$ s/div.
- (4) Adjust potentiometer A2R14 for a minimum indication on the 'scope.

Table 4-12. Systematic Troubleshooting: Waveforms

FIG. REFERENCE: 'SCOPE SETTINGS & # TABLE STEP WAVEFORM SIGNAL CONDITIONS 4-6 8 Vertical: l V/division, d.c. Horizontal: 0.1 µs/division. 2 4-6 9 Vertical: 5 V/division, d.c. Horizontal: 0.1 µs/division. 3 4-6 10 Vertical: 0.5 V/division, a.c. Horizontal: 0.1 µs/division.

Table 4-12. Systematic Troubleshooting: Waveforms (Continued)

FIG. REFERENCE: 'SCOPE SETTINGS & # TABLE STEP WAVEFORM SIGNAL CONDITIONS 4-6 13 Vertical: 0.5 V/division. Horizontal: 1 µs/division. 4-7 6 Vertical: 0.2 V/division. Horizontal: l µs/division. 6 4-7 11 Vertical: l V/division, d.c. Horizontal: l µs/division.

Table 4-12. Systematic Troubleshooting: Waveforms (Continued)

FIG.	REFER TABLE	ENCE: STEP	WAVEFORM	'SCOPE SETTINGS & SIGNAL CONDITIONS
7	4-7	13		Vertical: 0.2 V/division.  Horizontal: 0.2 ms/division.
3	4-7	17		Vertical: l V/division, d.c. Horizontal: l µs/division.
•	4-8	22		Vertical (Channel A) 5 V/division, d.c. Channel-A probe to pin 10 of A4U22. Trigger on A. Negative trigger.  Vertical (Channel B) 0.5 V/division, d.c. Display Channel B.  Horizontal: Uncalibrated, 10 ms per division.

Table 4-12. Systematic Troubleshooting: Waveforms (Continued)

# TABL	ERENCE: E STEP	WAVEFORM	'SCOPE SETTINGS & SIGNAL CONDITIONS
10 4-8	23		Vertical (Channel A): 5 V/division, d.c. Channel-A probe to pin 10 of A4U22. Trigger on Channel A: Negative trigger.  Vertical (Channel B): 0.5 V/division, d.c. Display Channel B.  Horizontal: Uncalibrated, 10 ms per division.
11 4-8	24		Vertical (Channel A) 5 V/division, d.c. Channel-A probe to pin 10 of A4U22. Trigger on Channel A Negative trigger.  Vertical (Channel B) 0.5 V/division, d.c. Display Channel B.  Horizontal: Uncalibrated, 20 ms per division.
12 4-9	24		Vertical: l V/division, d.c. Horizontal: l ms/division.

Table 4-12. Systematic Troubleshooting: Waveforms (Continued)

FIG.		ENCE: STEP	WAVEFORM	'SCOPE SETTINGS & SIGNAL CONDITIONS
13	4-9	39		Vertical: 1 V/division, d.c.  Horizontal: 0.5 ms/division.
14	4-9	40		Vertical: 1 V/division, d.c.  Horizontal: 0.5 ms/division.
15	4-10	11		Vertical: 0.5 V/division.  Horizontal: 0.2 ms/division.

Table 4-12. Systematic Troubleshooting: Waveforms (Continued)

1 1 maple

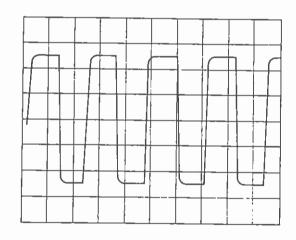
FIG. REFERENCE:
# TABLE STEP WAVEFORM SIGNAL CONDITIONS

16 4-10 12 Vertical:
0.5 V/division.

Horizontal:
1 ms/division.



17 4-10 13



Vertical: 0.5 V/division.

Horizontal: 0.5 ms/division.

### SECTIONV

### PARTS LIST

5-1. INTRODUCTION

The Table of Replaceable Parts begins with the Frame Assembly: the full set of PC-board assemblies, plus all components not mounted on PC boards. Then all the components of the individual PC-board assemblies are listed. To simplify ordering, please note the following:

- a. When ordering a component or an assembly, the BEC Part Number is all that we need. However, part numbers can suffer changes during transmission and it is safer to include also a brief description. For example:

  BEC Part #200050: Mica Capacitor, 470 pF, 1%, 500V.
- b. The number printed on a PC board is NOT an assembly number; it is the number for the bare board, alone. To order a complete assembly—the board with all its components installed—order it by the BEC Part Number given in the Frame Assembly section of this table.
- c. Unless otherwise identified, the number on a schematic diagram or on a parts-location diagram is NOT an assembly number; it is the number for just the diagram itself.

Table 5-1. Manufacturers' Code Numbers

NUMBER	NAME .	ADDRESS			
00853	Sangamo Electric Company	Pickens			
01121	Allen Bradley Company	Milwaukee	SC	29671	
01295	Texas Instruments Semiconductor Compon Div	Dallas	WI	53204	
02114	retroxcube COTP.	Saugerties	TX NY	75222	
02735	RCA Solid State Division	Somerville	NJ	12477 08876	
04222 04713	AVX Ceramics Company	Myrtle Beach	SC	29577	
06383	Motorola Semiconductor Products	Phoenix	AZ	85062	
	Panduit Corp.	Tinley Park	IL	60477	
06665 06776	Precision Monolithics, Inc.	Santa Clara	CA	95050	
07263	Robinson Nugent, Inc.	New Albany	IN	47150	
10236	Fairchild Semiconductor Division	Mountain View	ĊA	94042	
13812	Tally Industries, Electrodynamics Division	Rolling Meadows	IL	60008	
14752	Amperex Electronics Corp., Dialight Division	Brooklyn	NY	11237	
18324	Electro Cube, Inc.	San Gabriel	CA	91776	
19505	Signetics Corp.	Sunnyvale	CA	94086	
19701	Applied Engineering Products	New Haven	CT	06525	
24226	Mepco Electra	Mineral Wells	ТX	76067	
27014	Gowanda Electronics Corp.	Gowanda	ÑŸ	14070	
27264	National Semiconductor Corp.	Santa Clara	CA	95051	
27735	Molex, Inc.	Lisle	IL	60532	
27777	F-Dyne Electronics	Bridgeport	CT	06605	
28480	Varo Semiconductors, Inc.	Garland	Ϋ́X	75040	
31433	Hewlett-Packard Corp.	Palo Alto	ĊÄ	94304	
3 19 18	Union Carbide, Kemet Electronics Division	Greenville	SC	29606	
32997	ITT Schadow, Inc.	Eden Prairie	MN	55343	
34335	Bourns Inc., Trimpot Products Division	Riverside	CA	92507	
34649	Advanced Micro Devices, Inc. Intel Corp.	Sunnyvale	CA	94086	
50316	Mini-Systems, Inc.	Aloha	OR	97005	
1406	Murata Corp. of America	North Attleboro	MA	02761	
51640	Analog Devices, Inc.	Marietta	GA	30067	
6289		Norwood	MA	02062	
6708	Sprague Electric Company Zilog, Inc.	North Adams	MA	01247	
7582	Kahgan Electronics Corp.	Cupertino	CA	95014	
9474	Jeffers Electronics, Inc.	Hempstead	NY	11550	
71450	CTS Corporation	Nogales	AZ	85621	
73138		Elkhart	IN	46514	
2389	Beckman Instruments, Inc., Helipot Division Switchcraft, Inc.	Fullerton	CA	92634	
1418		Chicago	IL	60630	
5712	P. R. Mallory & Co., Radio Materials Co. Div. Bendix Corp., Dage Electric Division	Chicago	IL	60646	
8291	Sealectro Corp.	Franklin	IN	46131	
4217	United Chemicon, Inc.	Mamaronek	NY	10544	
F520	Panel Components Corp.	Rosemont	IL	60018	
	Countries Corb.	Santa Rosa	CA	95401	

Table 5-2. Replaceable Parts

Item	Descript	lon	Mfr.	Mfr's Part #	BEC Part #
A2 A3 A4 A5	R.F. Board Assembly I.FA.F. Board Assembly Digital & Power-Supply Display Board Assembly	FRAME ASSEMBLY (A	BEC BEC BEC BEC		082108 082109 082107 082110
C1 C2	Capacitor, Cer. Capacitor, Cer.	1000 pF, 20%, 1 kV 1000 pF, 20%, 1 kV	91418 91418	Type B Type B	224229 224229
F1	Fuse, Slow-Blow	0.25A (110V Operation)		MDL-1/4-250	545511
F1	or, Fuse, Slow-Blow	0.125A (220V Operation)	)	MDL-1/8-250	545516
J1 J2 J3 J4 J5	Connector, BNC Connector, 50 $\Omega$ Connector, BNC Connector, BNC Connector, 4-pin		95712 19505 95712 95712 27264	081-1 081-1 081-1 03-06-1043	479123 477305 479123 479123 479340
P1 P14 P15	Connector, Power Connector, 5-pin Connector, 4-pin	·	5F520 06383 27264	8843.FS.32.60 CE156F24-5-C 03-06-2043	477368 479394 477306
S1 S2	Switch, Slide Switch, Rocker		82389 13812	47206LFR 572-2121-0103-010	465279 465286
<b>T</b> 1	Transformer, Power		BEC		446093
W1 W2 W3 W4 W5	Cable Assembly Cable Assembly Wire Cable Unit, Flat Cable Unit, Flat	I.F. Out A.F. Out R.F. to I.FA.F. R.F. to Digital I.FA.F. to Digital	BEC BEC BEC BEC BEC		571162 571160  920065 920065
W6 W7 WB W9	Cable Unit, Flat Cable Assembly Cable Unit, Flat Wire	I.FA.F. to Digital I.FA.F. to Digital Digital to Display Digital to Display	BEC BEC BEC		920065 571161 920065
•	R.F. BO	ARD ASSEMBLY (A2); PART	NUMBER	082108	•
C1 C2 C3 C4 C5	Capacitor, Cer. Capacitor, El. Capacitor, Cer. Chip Capacitor, El. Capacitor, Cer. Chip	0.1 µF, 20%, 50V 10 µF, 20%, 25V 0.01 µF, 20%, 100V 10 µF, 20%, 25V 680 pF, 10%, 50V	04222 S4217 31433 S4217 31433	SR215E104MAA SM25-VB-10M C1210C103M5XAH SM25-VB-10M C1210C681K5XAH	224268 283336 224210 283336 224377
C6 C7 C8 C9 C10	Capacitor, Cer. Capacitor, Mica Capacitor, Cer. Capacitor, Mica Capacitor, Tant.	0.01 µF, 20%, 50V 100 pF, 1%, 500V 0.01 µF, 20%, 50V 100 pF, 5%, 300V 1.0 µF, 10%, 35V	51406 51406 56289	DD350A10Y5P103M50V DM15-101F DD350A10Y5P103M50V DM5-FC101J 136D105X9035HA1	224363 200045 224363 205006 283216
C11 C12 C13 C14 C15	Capacitor, El. Capacitor, Mica Capacitor, Tant. Capacitor, Mica Capacitor, Mica	10 µF, 20%, 25V 100 pF, 5%, 300V 1.0 µF, 10%, 35V 100 pF, 1%, 500V 33 pF, 5%, 300V	S4217 56289	SM25-VB-10M DM5-FC101J 196D105X9035HA1 DM15-101F DM5-EC330J	283336 205006 283216 200045 205010
C16 C17 C18 C19 C20	Not Used Capacitor, Mica Capacitor, Cer. Capacitor, El. Capacitor, Cer.	8 pF, 10%, 300V 0.1 µF, 20%, 50V 10 µF, 20%, 25V 0.1 µF, 20%, 50V	04222 S4217 04222	DM5-CC080K SR215E104MAA SM25-VB-10M SR215E104MAA	205001 224268 283336 224268
C21 C22 C23 C24 C25	Capacitor, Mica Capacitor, Cer. Capacitor, Cer. Capacitor, Cer. Capacitor, Cer.	270 pF, 5%, 50V 0.1 µF, 20%, 50V 0.1 µF, 20%, 50V 0.1 µF, 20%, 50V 0.1 µF, 20%, 50V	04222 04222 04222 04222	DM5-FY271J SR215E104MAA SR215E104MAA SR215E104MAA SR215E104MAA SR215E104MAA	205045 224268 224268 224268 224268
C26 C27 C28 C29 C30	Capacitor, Cer. Capacitor, Mica Capacitor, Mica Capacitor, Cer. Capacitor, El.	0.1 μF, 20%, 50V 15 pF, 5%, 300V 47 pF, 5%, 300V 1000 pF, 10%, 100V 10 μF, 20%, 25V	04222 04222 S4217	SR215E104MAA DM5-CC150J DM5-EC470J SR151C102KAA SM25-VB-10M	224268 205035 205018 224270 283336

Table 5-2. Replaceable Parts (Continued)

Thom		Table 5-2. Replaceable Part			
Item •		R.F. BOARD ASSEMBLY (A2); PART	Mfr.	Mfr's Part #	BEC Part
C31 C32 C33 C34 C35	Capacitor, Cer. Capacitor, El. Capacitor, Mica Capacitor, Mica Capacitor, El.	0.01 µF, 10%, 100V 100 µF, 20%, 25V 10 pF, 5%, 300V 22 pF, 5%, 300V 10 µF, 20%, 25V	04222 S4217	SR201C103KAA SM25-VB-100M DM5-CC100J DM5-CC220J	224269 283334 205002 205036 283336
C36 C37 C38 C39 C40	Capacitor, Mica Capacitor, Mica Capacitor, Tant. Capacitor, Cer. Capacitor, El.		56289 04222 54217		205045 205045 283293 224269 283336
C41 C42 C43 C44 C45	Capacitor, Cer. Capacitor, Mica Capacitor, Mica Capacitor, El. Capacitor, Mica			SR201C103KAA DM15-391J DM15-391J SM25-VB-100M DM5-FY271J	224269 200108 200108 283334 205045
C46 C47 C48 C49 C50	Capacitor, Mica Capacitor, MPC Capacitor, Tant. Not Used Capacitor, Tant.	1.0 μr, 10%, 50v 10 μr, 20%, 25v		196D106X0025KA1	205045 234152 283293
C5 1		10 µF, 20%, 25V	56289		283293
C5 2 C5 3 C5 4	Capacitor, Cer. Capacitor, Cer. Capacitor, Cer. Not Used	0.1 µF, 20%, 50V	04222 04222 04222	SR2 15E104MAA	224268 224268 224268
C55	Capacitor, Cer.	0.1 μF, 20%, 50V	04222	SR215E104MAA	224268
C56 C57 C58 C59 C60	Capacitor, Mica Capacitor, Tant. Capacitor, Mica Capacitor, Cer. Capacitor, El.	47 pF, 5%, 300V 1.0 μF, 10%, 35V 100 pF, 5%, 300V 0.1 μF, 20%, 50V 10 μF, 20%, 25V		DM5-EC470J 196D105X9035HA1 DM5-FC101J SR215E104MAA SM25-VB-10M	205018 283216 205006 224268 283336
CR1 CR2 CR3 CR4 CR5	Diode, Signal Diode, Quad Diode, PIN Diode, Signal Diode, Signal	1N6263 5082-2815 5082-0180 1N6263 1N914	28480 28480 28480 28480 01295		530174 530903 530168 530174 530058
CR6 CR7 CR9 CR9 CR10	Diode, Signal Diode, Signal Diode, Signal Diode, Varactor Diode, Varactor	1N914 1N6263 1N6263 MV2115 MV2115	01295 28480 28480 04713 04713		530058 530174 530174 530760 530760
CR11 CR12 CR13	Diode, Signal Diode, Signal Diode, Signal	1N914 1N914 1N6263	01295 01295 28480		530 <b>058</b> 530 <b>058</b> 530174
L1 L2 L3 L4 L5	Choke, R.F. Coil, Osc. Choke, R.F. Choke, R.F. Choke, R.F.	33 µH, 5% 0.72 µH 4.7 µH, 10% 4.7 µH, 10% 5.6 µH, 10%	59474 BEC 59474 24226 59474	4465-2J 4425-14K 10/471 4435-1K	400310 400417 400292 400384 400308
L6 L7 L8 L9 L10	Choke, R.F. Choke, R.F. Choke, R.F. Choke, R.F. Choke, R.F.	68 µН, 10% 39 µН, 10% 5.6 µН, 10% 68 µН, 10% 39 µН, 10%	24226 24226 59474 24226 24226	10/682 10/392 4435-1K 10/682 10/392	400411 400387 400308 400411 400387
L11	Choke, R.F.	5.6 µH, 10%	59474	4435-1K	400308
P 1	Connector, R.F.		98291	52-054-0000	479336
Q1 Q2 Q3 Q4 Q5	Transistor, NPN Transistor, FET Transistor, PNP Transistor, NPN Transistor, NPN	2N3866 2N4416 2N3906 2N3904 2N3904	04713 04713 04713 04713 04713		528116 528072 528076 528071 528071
Q6 Q7 Qв	Transistor, PNP Transistor, NPN Transistor, FET	2N3906 MPS-6507 2N4416	04713 04713 04713		528076 528070 528072

Table 5-2. Replaceable Parts (Continued)

			Table 5-2.	Replaceable Part	g (Cont	inued)	
Item •			scription		Mfr.	Mfr's Part #	
 R1	Postata			Y (A2), CONTINUED		•	
R2	Resistor, Resistor,	Comp.	33 Ω,	5%	01121	CB	343150
R3	Resistor.	Chin	18 N,	, 58 58	01121 50316		343246 339996
R4	Resistor,	Comp.	300 h	5.5%	01121		343246
R5	Resistor, Resistor, Resistor,	Comp.	330 Ω	5% , 5% , 5% , 5% , 5%	01121	СВ	343250
R6 R7	Resistor,	Comp.	100 រា	, 5% Ω, 5% , 5%, 1/8W , 5%, 1/8W , 10%, 0.5W	01121	СВ	343200
R8	Resistor,	Comp.	6.8 k	11, 5%	01121	CB	343380
R9	Resistor.	Comp.	100 1	, 5%, 1/8W	01121	BB	331058
R10	Resistor,	Var.	50 kពី	, 10%, 0.5W	73138	BB 72PR50K	331058 311393
R11	Resistor,	Comp.	7.5 k	Ω, 5% , 5%, 1/8W , 5%, 0.5W Ω, 5%	01121	СВ	343384
R12 R13	Resistor,	Comp.	100 ກ	, 5%, 1/8W	01121	BB	331058
R14	Resistor,	Comp.	33 14,	5%	01121	CB	343150
R15	Resistor,	Comp.	5.1 k	Ω, 5%	01121	72PR10K CB	311328 343368
R16	Resistor,	Comp.	7.5 k	Ω. 5%	01121	СВ	343384
R17	Resistor,	Comp.	100 Ω	, 5%, 1/8W	01121	BB	331058
R18 R19	Resistor,	Comp.	6.8 k	Ω, 5%	01121	CB	343380
R20	Resistor,	Comp.	100 Ω 100 Ω	Ω, 5% , 5%, 1/8W Ω, 5% , 5%, 1/8W , 5%, 1/8W	01121 01121	BB BB	331058 331058
R2 1	Resistor.	Como	100 Ω	59			
R22	Resistor,	Comp.	1 kΩ.	, 5% 5% Ω, 5% , 5% Ω, 5%	01121 01121	CB CB	343200 343300
R23	Resistor,	Comp.	3.9 k	Ω, 5%	01121	CB	343357
R24	Resistor,	Comp.	<b>20</b> kΩ	, 5 <sub>%</sub>	01121	CB	343429
R25	Resistor,	Comp.	7.5 k	Ω, 5%	01121	СВ	343384
R26 R27	Resistor,	Comp.	510 Ω	, 5%	01121		343268
R28	Resistor,	Comp.	22 11,	5%	01121		343123
229	Resistor.	Comp.	210 36 47 Ω	, 5% 5% 1/817	01121		343268
R30	Resistor,	Comp.	510 Ω 22 Ω, 510 Ω 47 Ω, 47 Ω,	, 5% 5% , 5% 5%, 1/8W 5%	01121 01121	BB CB	331050 343165
31	Resistor,	Comp.	<b>47</b> Ω,	5%, 1/8W	01121	ВВ	331050
32	Resistor,	Comp.	<b>22</b> Ω,	5%	01121	CB	343133
333 334	Resistor,	Comp.	100 Ω	, 5%	01121	CB	343200
35	Resistor,	Comp.	<b>510</b> Ω	5%, 1/8W 5% , 5% , 5% , 5%	01121 01121	CB CB	343365 343268
36			510 Ω 15 kΩ 1 kΩ, 511 Ω 3 kΩ,		01121	СВ	343268
ช7	Resistor,	Comp.	15 kΩ	. 5%	01121	CB	343417
38	Resistor,	Comp.	$1 k\Omega_{k}$	5%	01121	CB	343300
₹39 ₹40	Resistor,	MF	511 Ω	, 18		RN55	341268
					01121	СВ	343346
₹4.1 ₹4.2	Resistor,	Comp.	360 Ω	, 5% ςΩ <b>, 1</b> %	01121		343253
143	Resistor.	MF	243 0	536, 1% 19-		RN55	341468
144	Resistor,	MF	47.5	Ω. 1%		RN55 RN55	341237 341465
145	Resistor,	MF	360 Ω, 51.5 Ω 243 Ω, 47.5 Ω	Ω, 1%		RN55	341429
146 147	Resistor, Resistor,	MF	47.5 }	Ω, 1%		RN55	341465
48	Registor.	Comp	90-9 λ 47 Ω	116, 118 59, 17017	01171	RN55	341492
49	Resistor, Resistor,	MF	10.01	5%, 1/8W Ω, 1%	01121	RN55	331050 341400
50	Resistor,	Comp.	1 kΩ,	5%	01121		343300
51	Resistor,	Comp.	5.1 ks	2, 5%	01121	CB	343368
52 53	Resistor,		1 kΩ,	5%	01121	СВ	343300
54	Resistor,	Comp.	510 Ω, 47 Ω,	⊃*i 5%	01121	CB	343268
55	Resistor, Resistor, Resistor,	Comp.	510 W,	5%	01121 01121	CB CB	343165 343268
56	Resistor,	Comp.	10 kΩ, 200 kΩ, 10 kΩ, 2 kΩ,	5%	01121	CB	343400
57	Resistor,	Comp.	200 ks	2,_5%	01121	CB	343529
58 59	Resistor,	Comp.	200 kg 10 kΩ, 2 kΩ,	5%	01121	CB	343400
60	Resistor, (Resistor, (	Comb.	200 ks	2, 5%		CB CB	343329 343529
	Resistor,		10 kΩ	5%	01121	СВ	343400
62	Resistor, (	Comp.	2 kΩ,	5%	01121	CB	343329
63	Resistor,	Comp.	2 kΩ, 820 Ω, 10 kΩ,	5%	01121	CB	343288
-	recorded,	COMP.	10 kΩ,	5%	01121	CB	343400
65	Resistor,	var.	2 ku,	10%, 0.5W	73138	72PR2K	311343
	Resistor, (		1 kΩ,	5% 5%	01121	CB	343300
	Resistor, (		10 kΩ, 1 kΩ,	59	01121	CB	343400
	Resistor, (		4.7 ks	5. 5%	01121 01121	CB CB	343300 343365
	Resistor, 1		4.7 kΩ 24.3 k	Ω, 1%	5 - 12 1	RN55	341437

Table 5-2. Replaceable Parts (Continued)

R.F. BOARD ASSEMBLY (A2), CONTINUED; PART NUMBER 082108  771 Transformer, Pulse Gen. 772 Transformer, Pulse Gen. 773 Transformer, Pulse Gen. 774 Transformer, Pulse Gen. 775 Transformer, Pulse Gen. 775 Transformer, Pulse Gen. 776 Transformer, Pulse Gen. 777 Transformer, Pulse Gen. 778 Transformer, Pulse Gen. 778 Transformer, Pulse Gen. 779 Transformer, Pulse Gen. 770 Transformer, Pulse Gen. 770 Transformer, Pulse Gen. 770 Transformer, Pulse Gen. 771 Transformer, Pulse Gen. 771 Transformer, Pulse Gen. 772 Transformer, Pulse Gen. 773 Transformer, Pulse Gen. 774 Transformer, Pulse Gen. 775 Transformer, Pulse Gen. 775 Transformer, Pulse Gen. 776 Transformer, Pulse Gen. 777 Transformer, Pulse Gen. 777 Transformer, Pulse Gen. 778 Transformer, Pulse Gen. 779 Transformer, Pulse Gen. 779 Transformer, Pulse Gen. 770 Transformer, Pulse Gen. 7		Table	e 5-2.	Replaceable Parts	(Conti	.nued)	
### Resistor, Comp. 39 kR, 56 01121 CB 34345  T1 Transformer, Pulse Gen. ### BEC 41009  T1 Transformer, Pulse Gen. ### BEC 41008  T1 Transformer, Pulse Gen. ### BEC 51427  T1 Transformer, Pulse Gen.				<u></u>			BEC Part
T1 Transformer, Palse Gen.  Transformer, Balun  I Integrated Circuit  SN74ALS74N  0123							
### Transformer, Balun   BEC   41008   ### Transformer, B	R/1	Resistor, Comp.	39 kΩ,	5%	01121	СВ	343457
UI Integrated Circuit SN74ALS78N 01295 3422  UI Integrated Circuit SN74ALS78N 01295 3422  UI Integrated Circuit SN74ALS78N 01295 3468  UA Analog Switch Sw74ALS3NN 27014 55509  UB Oper. Amplifier LF357N 27014 55509  UB Oper. Amplifier TL9353NN 27014 55509  UB Oper. Amplifier CW7072CP 01295 55509  UB Oper. Amplifier MC1955P 04713 55509  UB Oper. Amplifier MC1955P 04					BEC		410090
Integrated Circuit	TZ	Transformer, Balun			BEC		410089
U33 Integrated Circuit	<b>U</b> 1	Integrated Circuit	SN74AL	S74N	01295		534281
USA Analog Switch  USA Oper. Amplifier  USA Oper.		Integrated Circuit Integrated Circuit					
TLO72CP	U4	Analog Switch			27014		535095
Integrated Circuit		Oper. Amplifier	LF357N		27014		535096
Oper.   Amplifier							535092 535709
I.PA.F. BOARD ASSEMBLY (A3); PART NUMBER 082109   C1   Capacitor, Mica   470 pF, 1%, 500V   00853   DM15-47-17   20005   2	U8	Oper. Amplifier					535038
C1 Capacitor, Mica 240 pF, 1%, 500V 0833 D10-FD-241-F03 20005 Capacitor, Mica 240 pF, 1%, 500V 0833 D10-FD-241-F03 20015 Capacitor, Mica 10 pF, 1%, 500V 0833 D10-FD-241-F03 20015 Capacitor, Mica 10 pF, 1%, 500V 04222 SBC-0150VAA 2550 Capacitor, Tant. 1.0 pF, 10%, 35V 56289 196D105X9035HA1 28321 Capacitor, Cer. 0.1 pF, 20%, 25V 5420 D312E1075P104M25V 22436 Capacitor, Tant. 1.0 pF, 10%, 35V 56289 196D105X9035HA1 28321 Capacitor, Mica 100 pF, 5%, 100V DM5-F241513 20500 Capacitor, Mica 100 pF, 5%, 100V DM5-F241513 20500 Capacitor, Mica 100 pF, 5%, 300V DM5-F261313 20500 Capacitor, Mica 33 pF, 5%, 300V DM5-F261313 20500 C11 Capacitor, Mica 33 pF, 5%, 300V DM5-F261313 20500 C12 Capacitor, Mica 33 pF, 5%, 300V DM5-F261313 20500 C12 Capacitor, Cer. 0.1 pF, 20%, 25V S4217 SR25-WP-10M 28333 C13 Capacitor, Cer. 0.1 pF, 20%, 25V S4217 SR25-WP-10M 28333 C13 Capacitor, El. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 C13 Capacitor, El. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 C13 Capacitor, El. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 C13 Capacitor, El. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, Cer. 0.1 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, El. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, Cer. 0.1 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, Cer. 0.1 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, Cer. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, Cer. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, El. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, El. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, El. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, El. 10 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, Cer. 1.0 pF, 20%, 25V S4217 SR25-WP-10M 28333 Capacitor, Mica 47 pF, 5%, 300V DM5-EC3700 ADM5-EC3700 20501 20504 Capacitor, Mica 47 pF, 5%, 300V DM5-EC3700 20501 20504 2050	U9	Integrated Circuit	SN74LS	122N	01295		534 <b>28</b> 0
C1 Capacitor, Mica	•	I.FA.F	- BOARD	ASSEMBLY (A3); PA	RT NUME	ER 082 <b>109</b>	
Capacitor, Mica 15 pf, 58, 3000	C1	Capacitor, Mica	470 pF	, 1%, 500V		DM15-471F	200050
Capacitor, Cer. 0.01 UF, 10%, 100V 04222 SR210c103KAA 22426 Capacitor, El. 100 UF, 20%, 25V 51406 Capacitor, Cer. 0.1 UF, 20%, 25V 51406 Capacitor, Tant. 1.0 UF, 10%, 15V 56289 1960105X9035KA1 23321 CBC Capacitor, Tant. 1.0 UF, 10%, 15V 56289 1960105X9035KA1 23321 Capacitor, Mica 150 PF, 5%, 100V DM5-RC101J 20500 Capacitor, Mica 100 PF, 5%, 300V DM5-RC101J 20500 Capacitor, Mica 33 PF, 5%, 300V DM5-RC101J 20500 Capacitor, Mica 33 PF, 5%, 300V DM5-RC101J 20500 Capacitor, Cer. 0.1 UF, 20%, 25V S4217 SW25-VB-10M 28333 Capacitor, Cer. 0.1 UF, 20%, 25V 51406 DM512E1075F104W25V 22436 Capacitor, Cer. 0.1 UF, 20%, 25V 51406 DM512E1075F104W25V 22436 Capacitor, El. 10 UF, 20%, 25V 51406 DM512E1075F104W25V 22436 Capacitor, Cer. 0.1 UF, 20%, 25V 51406 DM512E1075F104W25V 22436 Capacitor, Cer. 0.1 UF, 20%, 25V 5406 DM512E1075F104W25V 22436 Capacitor, Cer. 0.1 UF, 20%, 25V 5406 DM512E1075F104W25V 22436 Capacitor, Cer. 0.1 UF, 20%, 25V 5406 DM512E1075F104W25V 22436 Capacitor, Cer. 0.1 UF, 20%, 25V 5406 DM512E1075F104W25V 22436 Capacitor, Cer. 0.1 UF, 20%, 25V 5406 DM512E1075F104W25V 22436 Capacitor, Cer. 0.1 UF, 20%, 25V 54289 1960106W0025KA1 28032 Capacitor, Cer. 0.1 UF, 20%, 25V 54289 1960106W0025KA1 28032 Capacitor, Cer. 0.1 UF, 20%, 25V 54289 1960106W0025KA1 28032 Capacitor, Cer. 0.1 UF, 20%, 25V 5427 SW25-VB-100M 28333 Capacitor, Cer. 0.1 UF, 20%, 25V 5427 SW25-VB-100M 28333 Capacitor, Cer. 0.1 UF, 20%, 25V 5427 SW25-VB-100M 28333 Capacitor, Cer. 0.1 UF, 20%, 25V 5427 SW25-VB-100M 28333 Capacitor, Cer. 0.1 UF, 20%, 25V 5427 SW25-VB-100M 28333 Capacitor, Cer. 0.1 UF, 20%, 25V 5427 SW25-VB-100M 28333 Capacitor, Cer. 0.1 UF, 20%, 25V 5427 SW25-VB-100M 28333 Capacitor, Cer. 0.1 UF, 20%, 25V 5427 SW25-VB-100M 28333 Capacitor, Mica 47 pF, 5%, 300V 5422 SW25-VB-100M 28333 Capacitor, Mica 47 pF, 5%, 300V 5422 SW25-VB-100M 28333 Capacitor, Mica 47 pF, 5%, 300V 5422 SW25-VB-100M 28333 Capacitor, Mica 40 pF, 1%, 500V 5425 SW25-VB-100M 28333 Capacitor, Mica 540 pF, 1%, 500V 540 DM5-CC101J 540 DM5-CC101J 540 DM5-CC101J 540 DM5-CC101J 5	C3		15 pF.	5% 300V	00853		205033
C6 Capacitor, El. 100 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 Capacitor, Tant. 10 µF, 10%, 35V 56289 196D105X9935HA1 28321 Capacitor, Mica 150 pF, 5%, 100V DM5-FA151J 20500 DM5-FC101J 20500 DM5-FC101J 20500 DM5-FC10J 2	C4	Capacitor, Cer.	<b>0.</b> 01 μ	F, 10%, 100V		SR201C103KAA	224269
Capacitor, Tant.  1.0 µF, 10%, 35V Capacitor, Mica 150 µF, 5%, 100V Capacitor, Mica 100 µF, 5%, 100V Capacitor, Mica 2050 C11 Capacitor, Mica 23 µF, 5%, 300V C12 Capacitor, Mica 23 µF, 5%, 300V C13 Capacitor, Cer. C1 µF, 20%, 25V Capacitor, Mica Capacitor, El. Capacitor, El. Capacitor, El. Capacitor, Mica Capacitor, Cer. Capacitor, Mica Capacitor, Cer. Capacit					_		
Capacitor, Tant.  1.0 µF, 10%, 35V Capacitor, Mica 150 µF, 5%, 100V Capacitor, Mica 100 µF, 5%, 100V Capacitor, Mica 2050 C11 Capacitor, Mica 23 µF, 5%, 300V C12 Capacitor, Mica 23 µF, 5%, 300V C13 Capacitor, Cer. C1 µF, 20%, 25V Capacitor, Mica Capacitor, El. Capacitor, El. Capacitor, El. Capacitor, Mica Capacitor, Cer. Capacitor, Mica Capacitor, Cer. Capacit	C7						
C10 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C11 Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333 C12 Capacitor, Cer. 0.1 μF, 20%, 55V S4217 SM25-VB-10M 28333 C13 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C15 Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333 C16 Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333 C17 Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333 C18 Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333 C19 Capacitor, Mica 39 pF, 5%, 300V S4217 SM25-VB-10M 28333 C19 Capacitor, Mica 39 pF, 5%, 300V S4217 SM25-VB-10M 28333 C19 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C10 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C11 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C12 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C12 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C12 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C12 Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333 C22 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 C22 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C22 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C22 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C22 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 C22 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 μF, 5%, 300V DM5-CC10JJ 20001 Capacitor, Mica 100 μF, 5%, 300V DM5-CC10JJ 20001 Capacitor, Mica 100 μF, 5%, 300V DM5-CC10JJ 20001 C	C8	Capacitor, Tant.	1.0 µF	, 10%, 35♥		196D105X9035HA1	283216
C11 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 C12 Capacitor, Mica 33 pF, 5%, 300V DM5-EC330J 20501 C13 Capacitor, Cer. 0.1 µF, 20%, 25V S4217 SM25-VB-10M 28333 C15 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 C17 Capacitor, Cer. 0.1 µF, 20%, 25V S4217 SM25-VB-10M 28333 C17 Capacitor, Cer. 0.1 µF, 20%, 25V S4217 SM25-VB-10M 28333 C18 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 C19 Capacitor, Mica 39 pF, 5%, 300V DM5-EC390J 20504 C22 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 C20 Capacitor, Tant. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 C20 Capacitor, Cer. 0.1 µF, 20%, 25V S4217 SM25-VB-10M 28333 C20 Capacitor, Cer. 0.1 µF, 20%, 25V S4217 SM25-VB-10M 28333 C25 Capacitor, Cer. 1.0 µF, 20%, 25V S4217 SM25-VB-10M 28333 C25 Capacitor, Cer. 1.0 µF, 20%, 25V S4217 SM25-VB-10M 28333 C25 Capacitor, Cer. 1.0 µF, 20%, 25V S4217 SM25-VB-10M 28333 C25 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 C25 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 C25 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 C27 Capacitor, Mica 47 pF, 5%, 300V DM5-EC470J 20501 C28 Capacitor, Mica 47 pF, 5%, 300V DM5-EC470J 20501 C28 Capacitor, Cer. 0.1 µF, 20%, 25V S4217 SM25-VB-10M 28333 C25 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 µF,	C10		150 pF	, 5%, 100V , 5%, 300V			205009
C12 Capacitor, Mica	C11	Capacitor. El.			54217		283336
C15 Capacitor, Cer.  O.1 μF, 20%, 25V  S217 SM25-VP-10M  Capacitor, Cer.  O.1 μF, 20%, 25V  S4217 SM25-VP-10M  SM25-VP-10	C12	Capacitor, Mica	33 pF,	5%, 300V		DM5-EC330J	205010
C16 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 C17 Capacitor, El. 10 μF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 C18 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 C19 Capacitor, El. 10 μF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 C20 Capacitor, Mica 39 μF, 5%, 300V DM5-EC390J 20504 C21 Capacitor, Tant. 10 μF, 20%, 25V 56289 196D106X0025KA1 28329 C22 Capacitor, Cer. 0.1 μF, 20%, 50V 04222 SR215E104MAA 22426 C23 Capacitor, Cer. 1.0 μF, 20%, 50V 04222 SR215E104MAA 22426 C24 Capacitor, El. 10 μF, 20%, 50V 04222 SR305E105MAA 22426 C25 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 C26 Capacitor, Mica 47 μF, 5%, 300V DM5-EC470J 20501 C27 Capacitor, Mica 47 μF, 5%, 300V DM5-EC470J 20501 C28 Capacitor, Mica 47 μF, 5%, 300V DM5-EC470J 20501 C29 Capacitor, Cer. 0.1 μF, 20%, 25V 5426 DD312E10Y5P104M25V 22436 C30 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 500 μF, 1%, 500V DM5-EC470J 20501 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28334 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 2832 Capacitor, Mica 100 μF, 20%, 50V	C14	Capacitor, Cer. Capacitor, El.	0.1 μF 10 μF.	, 20%, 50V 20%, 25V			
Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 39 pF, 5%, 300V S4217 SM25-VB-10M 28333 DM5-EC390J 20504 SM21 SM25-VB-10M 28333 DM5-EC470J 20505 SM21 SM25-VB-10M 28333 SM25-VB-10M 2833 SM25-VB-10M 2833 SM25-VB-10M 2833 SM25-VB-10M 28	C15						
C18 Capacitor, Cer. C19 Capacitor, El. C20 Capacitor, El. C20 Capacitor, Mica C21 Capacitor, Mica C21 Capacitor, Mica C22 Capacitor, Mica C22 Capacitor, Cer. C22 Capacitor, Cer. C23 Capacitor, Cer. C24 Capacitor, Cer. C25 Capacitor, Cer. C26 Capacitor, Cer. C27 Capacitor, Cer. C27 Capacitor, Cer. C28 Capacitor, Cer. C29 Capacitor, Mica C29 Capacitor, Mica C29 Capacitor, Cer. C29 Capa	C16		40	000 - 05**	-4047	5405 TD 404	00222
Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 39 μF, 5%, 300V 56289 1960106X0025KA1 28329 Capacitor, Cer. 0.1 μF, 20%, 50V 04222 SR15E104MAA 22426 Capacitor, Cer. 1.0 μF, 20%, 50V 04222 SR305E105MAA 22426 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 47 μF, 5%, 300V DM5-EC470J 20500 229 Capacitor, Mica 47 μF, 5%, 300V DM5-EC470J 20501 229 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 D0312E10Y5P104M25V 22436 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 D0312E10Y5P104M25V 22436 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 D0312E10Y5P104M25V 22436 Capacitor, Cer. 0.1 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 D0312E10Y5P104M25V 22436 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 100 μF, 1%, 100V DM5-FC121J 20502 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28334 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28334 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28334 Capacitor, Mica 100 μF, 20%, 25V S4217 SM25-VB-100M 28334 Capacitor, Mica 100 μF, 1%, 100V DM5-FC101J 20500 Capacitor, Mica 100 μF, 5%, 300V DM5-FC101J 20500 DM5-FC101J 20500 Capacitor, Mica 100 μF, 5%, 300V DM5-FC101J 20500 DM5-FC101J 205	C18						
C21 Capacitor, Tant. 10 µF, 20%, 25V 56289 1960106X0025KA1 28329 C22 Capacitor, Cer. 0.1 µF, 20%, 50V 04222 SR215E104MAA 22426 C23 Capacitor, Cer. 1.0 µF, 20%, 50V 04222 SR305E105MAA 22426 C24 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 C25 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-100M 28333 C26 Capacitor, Mica 47 pF, 5%, 300V DM5-EC470J 20501 229 Capacitor, Mica 47 pF, 5%, 300V DM5-EC470J 20501 229 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 500 pF, 1%, 500V 50853 D15-5-F-501-F-0 20012 Capacitor, Mica 1000 pF, 1%, 500V 50853 D15-5-F-501-F-0 20012 Capacitor, Mica 1000 pF, 1%, 100V 50853 D15-5-F-501-F-0 20012 Capacitor, Mica 1000 pF, 1%, 100V 50853 D15-5-F-501-F-0 20012 Capacitor, Mica 1000 pF, 1%, 500V 50853 D15-5-F-501-F-0 20012 Capacitor, Mica 1000 pF, 1%, 100V 50853 D15-5-F-501-F-0 20012 Capacitor, Mica 1000 pF, 1%, 100V 50853 D15-5-F-501-F-0 20012 Capacitor, Mica 1000 pF, 1%, 500V 50853 D15-5-F-501-F-0 20011 Capacitor, Mica 1000 pF, 1%, 500V 50853 D10-F-D241-F03 20012 Capacitor, Mica 1000 pF, 1%, 500V 50853 D10-F-D241-F03 20012 Capacitor, Mica 1000 pF, 1%, 100V 50855 D10-F-D241-F03 20012 Capacitor, Mica 1000 pF, 1%, 100V 50855 D10-F-D241-F03 20012 Capacitor, Mica 1000 pF, 1%, 100V 50855 D10-F-D241-F03 20012 Capacitor, Mica 1000 pF, 5%, 300V 50853 D10-F-D241-F03 20012 Capacitor, Mica 1000 pF, 5%, 300V 50853 D10-F-D241-F03 20012 Capacitor, Mica 1000 pF, 5%, 300V 50855 D10-F-D241-F03 20011 5085-FC101J 20500 50855 D2650 Capacitor, Mica 1000 pF, 5%, 300V 50855 D10-F-D241-F03 20500 50855 D10-F-D241-F03 20500 5	C19	Capacitor, El.	10 µF,	20%, 25V	S4217		283336
C22 Capacitor, Cer. C23 Capacitor, Cer. C24 Capacitor, Cer. C25 Capacitor, Cer. C26 Capacitor, El. C27 Capacitor, El. C28 Capacitor, El. C29 Capacitor, El. C29 Capacitor, El. C29 Capacitor, El. C20 Capacitor, El. C20 Capacitor, El. C20 Capacitor, El. C20 Capacitor, Mica C27 Capacitor, Mica C27 Capacitor, Mica C28 Capacitor, Mica C29 Capacitor, Cer. C29 Capacitor, Cer. C10 Capacitor, Cer. C11 Capacitor, Cer. C11 Capacitor, Cer. C12 Capacitor, Cer. C12 Capacitor, Cer. C12 Capacitor, Cer. C12 Capacitor, Cer. C13 Capacitor, Cer. C14 Capacitor, Cer. C15 Capacitor, Cer. C16 Capacitor, Cer. C17 Capacitor, Cer. C17 Capacitor, Cer. C18 Capacitor, Cer. C19 Capacitor, Cer. C19 Capacitor, Cer. C10 Capacitor, Cer. C10 Capacitor, Cer. C10 Capacitor, El. C10 Capacitor, Cel. C11 Capacitor, Cel. C11 Capacitor, Cel. C12 Capacitor, Cel. C13 Capacitor, Cel. C14 Capacitor, Cel. C15 Capacitor, Cel. C16 Capacitor, Cel. C17 Capacitor, Cel. C18 Capacitor, Cel. C19 Capacitor, Cel. C19 Capacitor, Cel. C19 Capacitor, Cel. C20 Capacitor, Cel. C		_	_				
C23 Capacitor, Cer.  1.0 μF, 20%, 50V  A24 Capacitor, El.  100 μF, 20%, 25V  A217 SM25-VB-100M  28333  C25 Capacitor, El.  100 μF, 20%, 25V  A217 SM25-VB-100M  28333  C26 Capacitor, Mica  A7 pF, 5%, 300V  DM5-EC470J  C27 Capacitor, Mica  A7 pF, 5%, 300V  DM5-EC470J  C28 Capacitor, Cer.  C11 μF, 20%, 50V  C29 Capacitor, Cer.  C11 μF, 20%, 50V  C29 Capacitor, Cer.  C11 μF, 20%, 25V  A217 SM25-VB-100M  28333  C326 Capacitor, Mica  A7 pF, 5%, 300V  DM5-EC470J  C3501  C327 Capacitor, Cer.  C11 μF, 20%, 50V  C328 Capacitor, Cer.  C11 μF, 20%, 25V  S4217 SM25-VB-10M  C330 Capacitor, El.  C31 Capacitor, El.  C31 Capacitor, El.  C32 Capacitor, El.  C33 Capacitor, El.  C34 Capacitor, El.  C35 Capacitor, El.  C47 CAPACITOR  C48 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C40 CAPACITOR  C40 CAPACITOR  C41 CAPACITOR  C42 CAPACITOR  C44 CAPACITOR  C44 CAPACITOR  C45 CAPACITOR  C46 CAPACITOR  C47 CAPACITOR  C48 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C40 CAPACITOR  C41 CAPACITOR  C42 CAPACITOR  C44 CAPACITOR  C45 CAPACITOR  C46 CAPACITOR  C47 CAPACITOR  C48 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C40 CAPACITOR  C41 CAPACITOR  C42 CAPACITOR  C43 CAPACITOR  C44 CAPACITOR  C45 CAPACITOR  C46 CAPACITOR  C47 CAPACITOR  C48 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C49 CAPACITOR  C40 CAPACITOR  C41 CAPACITOR  C42 CAPACITOR  C43 CAPACITOR  C44 CAPACITOR  C45 CAPACITOR  C46 CAPACITOR  C47 CAPACITOR  C48 CAPACITOR  C49 CAPACITOR  C4	C22		0.1 UF	, 20%, <b>50V</b>			28329. 224268
Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-100M 28333  C26 Capacitor, Mica 47 pF, 5%, 300V DM5-EC470J 20501  C28 Capacitor, Mica 47 pF, 5%, 300V DM5-EC470J 20501  C29 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436  C31 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333  Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333  Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333  Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333  Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333  Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333  Capacitor, Mica 500 pF, 1%, 500V 00853 D15-5-F-501-F-0 20012  C36 Capacitor, Mica 120 pF, 5%, 100V DM5-FC121J 20502  C37 Capacitor, Mica 1000 pF, 1%, 100V DM5-FC121J 20502  C38 Capacitor, Mica 1000 pF, 1%, 100V DM5-102F 20011  Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011  Capacitor, Mica 240 pF, 1%, 500V 00853 D10-FD-241-F03 20012  C41 Capacitor, Mica 1000 pF, 1%, 500V DM5-FC101J 20502  C42 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500  C43 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500  C44 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500  C45 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20501  C46 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20501  C47 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C48 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436  C50 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436	C23	Capacitor, Cer.	1.0 µF	. 20%, 50V	04222	SR305E105MAA	224264
C27 Capacitor, Mica 47 pF, 5%, 300V DM5-EC470J 20501 2026 Capacitor, Mica 47 pF, 5%, 300V DM5-EC470J 20501 2050 Capacitor, Cer. 0.1 μF, 20%, 25V 04222 SR215E104MAA 22426 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 DD312E10YSP104M25V 22436 DD312E10YSP	C25		100 µF	, 20%, 25V			283334
C27 Capacitor, Mica 47 pF, 5%, 300V DM5-EC470J 20501 2026 Capacitor, Mica 47 pF, 5%, 300V DM5-EC470J 20501 2050 Capacitor, Cer. 0.1 μF, 20%, 25V 04222 SR215E104MAA 22426 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 DD312E10YSP104M25V 22436 DD312E10YSP	C26	Capacitor, El.	100 µF	, 20%, 25V	\$4217	SM25-VB-100M	283334
Capacitor, Cer. 0.1 μF, 20%, 50V 04222 SR215E104MAA 22426 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 DD312E10Y5P104M25V 22436  Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333  Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-10M 28333  Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-10M 28333  Capacitor, Mica 500 μF, 20%, 25V S4217 SM25-VB-10M 28333  Capacitor, Mica 500 μF, 1%, 500V 00853 D15-5-F-501-F-0 20011  Capacitor, Mica 120 μF, 5%, 100V DM5-FC121J 20502  Capacitor, Mica 1000 μF, 1%, 100V DM5-FC121J 20502  Capacitor, Mica 1000 μF, 1%, 100V DM15-102F 20011  Capacitor, Mica 240 μF, 1%, 500V 00853 D10-FD-241-F03 20012  Capacitor, Mica 240 μF, 1%, 500V 00853 D10-FD-241-F03 20012  Capacitor, Mica 240 μF, 1%, 500V 00853 D10-FD-241-F03 20012  Capacitor, Mica 240 μF, 1%, 500V 00853 D10-FD-241-F03 20012  Capacitor, Mica 200 μF, 2%, 500V 00853 D10-FD-241-F03 20012  Capacitor, Mica 1000 μF, 1%, 500V 00853 D10-FD-241-F03 20012  Capacitor, Mica 1000 μF, 1%, 500V 00853 D10-FD-241-F03 20012  Capacitor, Mica 1000 μF, 1%, 500V 00853 D10-FD-241-F03 20012  Capacitor, Mica 1000 μF, 1%, 500V 00853 D10-FD-241-F03 20012  Capacitor, Mica 1000 μF, 1%, 100V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 1%, 100V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 1%, 100V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 1%, 100V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 1%, 100V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 5%, 300V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 5%, 300V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 5%, 300V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 5%, 300V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 5%, 300V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 5%, 300V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 5%, 300V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 5%, 300V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 5%, 300V 00853 D10-FD-241-F03 20011  Capacitor, Mica 1000 μF, 5%, 300V 00853 D10-FD-241-F03 20	C27		47 pF,	5%, 300V			205018
Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 10 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 500 pF, 1%, 500V 00853 D15-5-F-501-F-0 20012 Capacitor, Mica 120 pF, 5%, 100V DM5-FC121J 20502 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 2038 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 2040 Capacitor, Mica 240 pF, 1%, 500V 00853 D10-FD-241-F03 20012 Capacitor, Mica 240 pF, 1%, 500V 00853 D10-FD-241-F03 20012 Capacitor, Mica 240 pF, 1%, 500V 00853 D10-FD-241-F03 20012 Capacitor, Mica 200 pF, 2%, 500V 00853 D10-FD-241-F03 20012 Capacitor, Mica 1000 pF, 5%, 300V DM15-102F 20011 20500 244 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 20500 244 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 20500 245 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 20500 245 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500 245 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500 249 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500 249 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500 249 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 µF, 20%,	C29		0.1 µF	, 20%, 50V		SR215E104MAA	224268
Capacitor, El. 10 μF, 20%, 25V S4217 SM25-VB-10M 28333 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, El. 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 500 μF, 100 μF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 500 μF, 100 μF, 20%, 25V 54217 SM25-VB-100M 28333 Capacitor, Mica 500 μF, 1%, 500V 00853 D15-5-F-501-F-0 20012 237 Capacitor, Tant. 10 μF, 20%, 25V 56289 196D106X0025Ka1 28329 Capacitor, Mica 1000 μF, 1%, 100V μM15-102F 20011 2000 Capacitor, Mica 1000 μF, 1%, 100V μM15-102F 20011 2001 Capacitor, Mica 240 μF, 1%, 500V 00853 D10-FD-241-F03 20012 240 μF, 1%, 500V 00853 D10-FD-241-F03 20012 241 Capacitor, Mica 240 μF, 20%, 50V 04222 SR215E104MAA 22426 243 Capacitor, Cer. 0.1 μF, 20%, 50V 04222 SR215E104MAA 22426 243 Capacitor, Mica 1000 μF, 5%, 300V μM5-FC101J 20500 244 Capacitor, Mica 1000 μF, 1%, 100V μM15-102F 20011 20500 244 Capacitor, Mica 1000 μF, 1%, 100V μM5-FC101J 20500 245 Capacitor, Mica 1000 μF, 5%, 300V μM5-FC101J 20500 246 Capacitor, Mica 100 μF, 5%, 300V μM5-FC101J 20500 246 Capacitor, Mica 100 μF, 5%, 300V μM5-FC101J 20500 246 Capacitor, Mica 100 μF, 5%, 300V μM5-FC101J 20500 246 Capacitor, Mica 100 μF, 5%, 300V μM5-FC101J 20500 249 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Cer. 0.1 μF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 250 Capacitor, Tant. 10 μF, 20%, 25V 51406 DD312E10Y5P104M25V 22436	C30	Capacitor, Cer.	0.1 µF	, 20%, 25V	51406	DD312E10Y5P104M25V	224364
Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 500 pF, 1%, 500V 00853 D15-5-F-501-F-O 20012 Capacitor, Mica 120 pF, 5%, 100V DM5-FC121J 20502 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 Capacitor, Mica 240 pF, 1%, 500V 00853 D10-FD-241-F03 20012 Capacitor, Mica 240 pF, 1%, 500V DM15-102F 20011 Capacitor, Mica 200 pF, 2%, 500V DM15-201G 2005 Capacitor, Cer. 0.1 µF, 20%, 50V DM15-201G 2005 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500 DM15-102F 20011 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500 DM15-102F 20011 Capacitor, Mica 1000 pF, 5%, 300V DM15-102F 20011 20500 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 Capacitor, Tant. 10 µF, 20%, 25V 56289 196D106X0025KA1 28329	C3 1						283336
Capacitor, El. 100 µF, 20%, 25V S4217 SM25-VB-100M 28333 Capacitor, Mica 500 pF, 1%, 500V 00853 D15-5-F-501-F-O 20012 20	C3 3						283334
Capacitor, Mica 120 pF, 5%, 100V DM5-FC121J 20502 Capacitor, Tant. 10 µF, 20%, 25V 56289 196D106x0025KA1 28329 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 Capacitor, Mica 240 pF, 1%, 500V 00853 D10-FD-241-F03 20012 C41 Capacitor, Mica 200 pF, 2%, 500V DM15-201G 20005 C42 Capacitor, Cer. 0.1 µF, 20%, 50V 04222 SR215E104MAA 22426 CAPACITOR, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C44 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C45 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C46 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C47 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C48 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500 C49 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500 C49 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500 C49 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 C51 Capacitor, Tant. 10 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436	C34		100 µF	, 20%, 25V			283334
Capacitor, Mica 100 pF, 1%, 100V 00853 D10-FD-241-FO3 20011 20005 Capacitor, Mica 240 pF, 1%, 500V 00853 D10-FD-241-FO3 20012			_	•	00000		
Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 20011 240 pF, 1%, 500V 00853 D10-FD-241-F03 20012 240 pF, 1%, 500V DM15-102F 20012 241 Capacitor, Mica 200 pF, 2%, 500V DM15-201G 20005 242 Capacitor, Cer. 0.1 µF, 20%, 50V DM5-FC101J 20500 DM15-102F 20011 20500 DM			120 pF.	, 5%, 100V 20%, 25V	56289		205022 283293
C40 Capacitor, Mica 240 pF, 1%, 500V 00853 D10-FD-241-FO3 20012 C41 Capacitor, Mica 200 pF, 2%, 500V DM15-201G 20005 C42 Capacitor, Cer. 0.1 µF, 20%, 50V DM22 SR215E104MAA 22426 C43 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C44 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C45 Capacitor, MPC 0.1 µF, 2%, 50V 27735 MPC-531-50-2 23413 C46 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C47 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C48 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C49 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 C51 Capacitor, Tant. 10 µF, 20%, 25V 56289 196D106X0025KA1 28329	C38	Capacitor, Mica	1000 pi	7. 1%. 100V		DM15-102F	200113
C41 Capacitor, Mica 200 pF, 2%, 500V DM15-201G 20005 C42 Capacitor, Cer. 0.1 µF, 20%, 50V 04222 SR215E104MAA 22426 C43 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C44 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C45 Capacitor, MPC 0.1 µF, 2%, 50V 27735 MPC-531-50-2 23413 C46 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C47 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C48 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C49 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 C51 Capacitor, Tant. 10 µF, 20%, 25V 56289 196D106X0025KA1 28329	C39 C40		1000 pl	7, 1%, 100V , 1%, 500V	00853		200113 200124
C42 Capacitor, Cer. 0.1 µF, 20%, 50V 04222 SR215E104MAA 22426 C43 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C44 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C45 Capacitor, MPC 0.1 µF, 2%, 50V 27735 MPC-531-50-2 23413 C46 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C47 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011 C48 Capacitor, Mica 1000 pF, 5%, 300V DM5-FC101J 20500 C49 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 C49 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 C50 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 C51 Capacitor, Tant. 10 µF, 20%, 25V 56289 196D106X0025KA1 28329							
Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500 DM15-102F 20011 20500 DM15-102F 20500 DM1	C42	Capacitor, Cer.	0.1 PF	, 20%, 50V	04222	SR215E104MAA	224268
C45 Capacitor, MPC 0.1 µF, 2%, 50V 27735 MPC-531-50-2 23413  C46 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C47 Capacitor, Mica 1000 pF, 1%, 100V DM15-102F 20011  C48 Capacitor, Mica 100 pF, 5%, 300V DM5-FC101J 20500  C49 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436  C50 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436  C51 Capacitor, Tant. 10 µF, 20%, 25V 56289 196D106X0025KA1 28329	C43 C44		100 pF	, 5%, 300V 5, 1%, 100V			205006 200113
C47 Capacitor, Mica     1000 pf, 1%, 100V     DM15-102F     20011       C48 Capacitor, Mica     100 pf, 5%, 300V     DM5-FC101J     20500       C49 Capacitor, Cer.     0.1 lf, 20%, 25V     51406 DD312E10Y5P104M25V     22436       C50 Capacitor, Cer.     0.1 lf, 20%, 25V     51406 DD312E10Y5P104M25V     22436       C51 Capacitor, Tant.     10 lf, 20%, 25V     56289 196D106X0025KA1     28329	C45		0.1 μF	, 2%, 50V	27735		234139
C47     Capacitor, Mica     1000 pF, 1%, 100V     DM15-102F     20011       C48     Capacitor, Mica     100 pF, 5%, 300V     DM5-FC101J     20500       C49     Capacitor, Cer.     0.1 µF, 20%, 25V     51406 DD312E10Y5P104M25V     22436       C50     Capacitor, Cer.     0.1 µF, 20%, 25V     51406 DD312E10Y5P104M25V     22436       C51     Capacitor, Tant.     10 µF, 20%, 25V     56289 196D106X0025KA1     28329	C46	Capacitor, Mica				DM5-FC101J	205006
250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 251 Capacitor, Tant. 10 µF, 20%, 25V 56289 196D106X0025KA1 28329	C47	Capacitor, Mica	1000 pi	7, 1%, 100V			200113
250 Capacitor, Cer. 0.1 µF, 20%, 25V 51406 DD312E10Y5P104M25V 22436 251 Capacitor, Tant. 10 µF, 20%, 25V 56289 196D106X0025KA1 28329	C49		0.1 µF	, 20%, 25V	51406		
	C50		0.1 μF	, 20%, 25V	51406	DD312E10Y5P104M25V	224364
52 Capacitor, Cer. 0-1 με, 20%, 25V 5140% DD312E10X5F104M25V 22436	C5 1						283293
	U5 2	Capacitor, Cer.	υ. ι με,	, 4UE, 25V	5 1406		224364

Table 5-2. Replaceable Parts (Continued)

T4:			Parts (Continued)	
Item •	Descrip		Mfr. Mfr's Part # NTINUED; PART NUMBER 082109	BEC Part
CR1	Diode, Signal Diode, Signal Diode, Signal Diode, Signal Diode, Signal Diode, Signal	1N9 14	01295	530058
CR2		1N9 14	01295	530058
CR3		1N6 263	28480	530174
CR4		1N6 263	28480	530174
CR5		1N6 263	28480	530174
CR6	Diode, Signal	1N6263	28480	530174
CR7	Diode, Signal	1N6263	28480	530174
CR8	Diode, Signal	1N914	01295	530058
CR9	Diode, Signal	1N914	01295	530058
CR10	Diode, Signal	1N914	01295	530058
CR11	Diode, Signal	1N914	01295	530058
CR12	Diode, Signal	1N914	01295	530058
CR13	Diode, Signal	1N914	01295	530058
J1 J2 J3 J4 J5	Connector, 16-pin Connector, 16-pin Connector, 2-pin Connector, 2-pin Connector, 2-pin		06776 06776 06383 HFAS100-2-C 06383 HFAS100-2-C	473042 473042 477363 477363 477363
L1 L2 L3 L4 L5	Choke, R.F. Choke, R.F. Choke. R.F. Choke, R.F. Choke, Wide-band	100 µH, 5% 91 µH, 5% 20 µH, 5% 150 µH, 5%	59474 1315-12J 59474 1311-11J 59474 4445-6J 59474 1315-16J 02114 VK200-20/4B	400295 400416 400258 400415 400405
L6	Choke, R.F.	5.6 µн, 10%	59474 4435-1K	400308
L7	Choke, R.F.	5.6 µн, 10%	59474 4435-1K	400308
L8	Choke, R.F.	5.6 µн, 10%	59474 4435-1K	400308
L9	Choke, R.F.	5.6 µн, 10%	59474 4435-1K	400308
21	Transistor, NPN Transistor, PNP Transistor, NPN Transistor, PNP Transistor, PNP	2N3904	04713	52807
22		2N3906	04713	52807
23		2N3904	04713	52807
24		2N3906	04713	52807
25		2N3906	04713	52807
26	Transistor, NPN	2N3904	04713	52807
R1 R2 R3 R4 R5	Resistor, Comp. Resistor, Comp. Resistor, Comp. Resistor, Comp. Resistor, Comp.	330 $\Omega$ , 5%, 1/8W 10 $k\Omega$ , 5% 220 $\Omega$ , 5% 200 $\Omega$ , 5% 10 $k\Omega$ , 5%	01121 BB 01121 CB 01121 CB 01121 CB 01121 CB	331070 343400 34323 343229 343400
R6	Resistor, Var.	100 $\Omega$ , 10%, 0.5%	32997 3329H-1-101	311406
R7	Resistor Network	500 $\Omega$ , 0.5%, 0.5%	73138 694-3-R500D	345035
R8	Resistor, Comp.	2 $k\Omega$ , 5%	01121 CB	343329
R9	Resistor, Comp.	5.1 $k\Omega$ , 5%	01121 CB	343368
R10	Resistor, Comp.	1 $k\Omega$ , 5%	01121 CB	343300
R11	Resistor, Comp.	10 $k\Omega$ , 5%	01121 CB	343400
R12	Resistor, Comp.	10 $k\Omega$ , 5%	01121 CB	343400
R13	Resistor, Comp.	100 $\Omega$ , 5%	01121 CB	343200
R14	Resistor, Comp.	15 $k\Omega$ , 5%	01121 CB	343417
R15	Resistor, Comp.	1.8 $k\Omega$ , 5%	01121 CB	343325
116	Resistor, Comp.	1.5 $k\Omega$ , 5% 470 $\Omega$ , 5% 10 $k\Omega$ , 5% 3.3 $k\Omega$ , 5% 6.2 $k\Omega$ , 5%	01121 CB	343317
117	Resistor, Comp.		01121 CB	343265
118	Resistor, Comp.		01121 CB	343400
119	Resistor, Comp.		01121 CB	343350
120	Resistor, Comp.		01121 CB	343376
121	Resistor, Comp. Resistor, Comp. Resistor, Comp. Resistor, Comp. Resistor, Comp.	510 $\Omega$ , 5%	01121 CB	343268
122		470 $\Omega$ , 5%	01121 CB	343265
123		1.5 $k\Omega$ , 5%	01121 CB	343317
124		47 $\Omega$ , 5%	01121 CB	343165
125		2.2 $k\Omega$ , 5%	01121 CB	343333
126	Resistor, Comp. Resistor, Comp. Resistor, Comp. Resistor, Comp. Resistor, Comp.	2 k $\Omega$ , 5%	01121 CB	343329
127		1 k $\Omega$ , 5%	01121 CB	343300
128		47 $\Omega$ , 5%	01121 CB	343165
129		100 $\Omega$ , 5%	01121 CB	343200
130		15 k $\Omega$ , 5%	01121 CB	343417
	Resistor, Comp. Resistor, Comp.	6.2 kΩ, 5% 15 kΩ, 5%	01121 СВ 01121 СВ	343376 343417

•	Ite	B De	scription	eabla Parts (Continued)	
	•			Mfr. Mfr's Part # CONTINUED: PART NUMBER 082108	BEC Part
	R7 1	Resistor, Comp.	39 kg, 5%	01121 CB	343457
	T1 T2	Transformer, Pulse Transformer, Balur	Gen.	BEC BEC	410090 410089
	U1 U2 U3 U4 U5	Integrated Circuit Integrated Circuit Integrated Circuit Analog Switch Oper. Amplifier	SN74T-9163N	01295 01295 01295 27014 27014	534281 534279 534167 535095 535096
	06 07 08 09	Oper. Amplifier Integrated Circuit Oper. Amplifier Integrated Circuit	WC1 1865	01295 02735 04713 01295	535092 535209 535038 534280
		I.F	-A.F. BOARD ASSEMBLY	(A3); PART NUMBER 082109	
1	C1 C2 C3 C4 C5	Capacitor, Mica Capacitor, Mica Capacitor, Mica Capacitor, Car. Capacitor, Tant.	470 pr. 19, 50 240 pr. 19, 50 15 pr. 59, 300 0.01 µr. 109, 1.0 µr. 108, 3	Day Burger (Ed.)	200050 200124 205035 224269 283216
mich	C6 C7 C8 C9 C1 0	Capacitor, El. Capacitor, Cer. Capacitor, Tant. Capacitor, Mica Capacitor, Mica	100 pr, 201, 2 0-1 pr, 201, 2 1.0 pr, 101, 3 150 pr, 51, 10 100 pr, 51, 30	5V 51406 DD312E10Y5F104M25V 5V 56289 1960105X9035RA1	283334
9 8	211 212 213 214 215	Capacitor, El. Capacitor, Mica Capacitor, Cer. Capacitor, El. Capacitor, Cer.	10 MF, 20%, 25 33 pF, 5%, 300 0.1 MF, 20%, 5 10 MF, 20%, 25 0.1 MF, 20%, 25	DM5-EC3307 DV 04222 SR215E104MAA	283336 205010 224268 283336
	20	Not Used Capacitor, El. Capacitor, Cer. Capacitor, El. Capacitor, Mica	10 µF, 20%, 25% 0.1 µF, 20%, 25% 10 µF, 20%, 25% 39 pF, 5%, 300%	51406 DD312E10V5F104M25V	283336 224364 283336 205044
U g	22 23 24 25	Capacitor, Tant. Capacitor, Cer. Capacitor, Cer. Capacitor, El. Capacitor, El.	10 µF, 20%, 25v 0.1 µF, 20%, 50 1.0 µF, 20%, 50 10 µF, 20%, 25v 100 µF, 20%, 25v	V 04222 SR215E104MAA V 04222 SR305E105MAA	283293 224268 224264 283336 283334
	29	Capacitor, El. Capacitor, Mica Capacitor, Mica Capacitor, Cer. Capacitor, Cer.	100 µF, 20%, 25 47 pF, 5%, 300V 47 pF, 5%, 300V 0.1 µF, 20%, 50 0.1 µF, 20%, 25V	V 54217 SM25-VB-100M DM5-EC470J DM5-EC470J V 04222 SR215E104MAA V 51406 DD312E10Y5P104M25V	283334 205018 205018 224268 224364
	13 (	Capacitor, El. Capacitor, El. Capacitor, El. Capacitor, El. Capacitor, Mica	10 µF, 20%, 25V 10 µF, 20%, 25V 100 µF, 20%, 25V 100 µF, 20%, 25V 500 µF, 1%, 500V	7 94217 SM25-VB-100M	283336 283336 283334 283334 200123
C3 C3 C3 C4	7 c 9 c	Capacitor, Mica Capacitor, Tant. Capacitor, Mica Capacitor, Mica Capacitor, Mica	120 pF, 5%, 100V 10 pF, 20%, 25V 1000 pF, 1%, 100 1000 pF, 1%, 100 240 pF, 1%, 500V	DM5-FC121J 56289 196D106x0025KA1 V DM15-102F V DM15-102F 00853 D10-FD-241-F03	205022 203293 200113 200113 200124
C4: C4: C4: C4:	2 0	apacitor, Mica apacitor, Cer. apacitor, Mica apacitor, Mica apacitor, MPC	200 pr, 2%, 500v 0.1 kr, 20%, 50v 100 pr, 5%, 300v 1000 pr, 1%, 100 0.1 ur, 2%, 50v	DM15-201G 04222 SR215E104MAA	200053 224269 205006 200113 <b>2341</b> 39
C46 C47 C48 C49 C50	7 000	apacitor, Mica apacitor, Mica apacitor, Mica apacitor, Cer. apacitor, Cer.	100 pF, 54, 300V 1000 pF, 14, 100V 100 pF, 54, 300V 0.1 µF, 204, 25V 0.1 µF, 204, 25V	DM5-FC101J DM15-102F DM5-FC101J	205006 200113 205006
C51		apacitor, Tant- apacitor, Cer.	10 MF, 20%, 25V 0-1 MF, 20%, 25V	56289 1960106Y0025V74	283293 224364

Table 5-2. Replaceable Parts (Continued)

		able 5-2. Replace	able Parts (Continued)	
Item	DCBCL	iption	Mfr. Mfr's Part #	
R33			), CONTINUED; PART NUMBER 082109	
R34 R35	Resistor, MF Resistor, Comp. Resistor, Comp.	39.2 kΩ, 1% 47 Ω, 5% 470 Ω, 5%	RN55 01121 CB 01121 CB	34145 34316 34326
R36	Resistor, Comp.	470 Ω, 5%	01121 СВ	34326
R37 R38	Resistor, Comp.	47 Ω, 5%	01121 CB	34316
R39	Resistor, Comp. Resistor, Comp.	2 kΩ, 5% 6.2 kΩ, 5%	01121 CB	343329
R40	Resistor, Comp.	10 kΩ, 5%	01121 CB 01121 CB	34337( 34340)
R4 1 R4 2	Resistor, Comp. Resistor, Comp.	2 kΩ 5%	01121 CB	343329
R43	Resistor, MF	10 kΩ, 5% 243 Ω, 1%	01121 CB RN55	34340 34123
R44 R45	Resistor, MF Resistor, MF	2.0 kΩ, 1% 150 Ω, 1%	RN55 RN55	341329 34131
R46	Resistor. MF	1.0 kΩ. 1%	RN55	34130
R47 R48	Resistor, MF Resistor, MF	52.3 kΩ, 1%	RN5.5	34146
R49	Not Used	52.3 kΩ, 1%	RN55	341469
R50	Resistor, MF	10.0 kΩ, 1%	RN55	341400
R5 1 R5 2	Resistor, MF Resistor, MF	10.0 kΩ, 1%	RN55	341400
R53	Resistor, MF	10.0 kΩ, 1% 15.0 kΩ, 1%	RN55	341400
R54 R55	Not Used Resistor, MF	30.1 kΩ, 1%	RN55 RN55	34141
R56	Resistor, MF	604 Ω, 1%	RN55	341446 341275
R57	Resistor, MF	13.3 kΩ, 1%	RN55	34141
R5 0 R5 9	Resistor, MF Resistor, MF	Β.87 1εΩ 19.	RN55	341391
R60	Resistor, MF	9.000 kΩ, 0.19 1.000 kΩ, 0.19	5, 1/8W PME55-T2 5, 1/8W PME55-T2	324354 324241
R61 R62	Resistor, MF	10.0 kΩ, 1%	RN55	34140
R63*		1.0 kΩ, 1% 26.7 kΩ, 1%	RN55 RN55	341300
R64	Resistor, MF	182 kΩ. 1%	RN55	341441 341525
R65*	<b>,</b>	16.9 %Ω, 1%	RN5 5	341422
- wле R63	en Option -01 is instal Resistor, MF	lled, these compone	nts are changed as follows: RN55	241411
R65	Resistor, MF Resistor, MF	8.25 kΩ, 1%	RN55	341411 341388
R66	Resistor, MF	73.2 kΩ, 1%	RN55	341483
R67 R68	Resistor, Comp.	51 kΩ, 5%	01121 CB	343468
R69	Resistor, MF Resistor, MF	48.7 kΩ, 18 7.50 kΩ, 18	RN55 RN55	341466
R70	Resistor, Comp.	51 kn, 5%	01121 CB	341384 343468
R71*	Resistor, MF	9.53 kΩ, 1%	RN55	341394
R72 R73	Resistor, Comp. Resistor, MF	51 kΩ, 5% 1.54 kΩ, 1%	01121 CB	343468
R74	Resistor, MF	1.0 kΩ, 1%	RN55 RN55	341318 341300
₹75	Resistor, Comp.	100 %17, 5%	01121 CB	343500
R76 R77	Resistor, MF	604 \ \Omega  18	RN55	341275
178	Resistor, Comp. Resistor, Comp.	2 kΩ, 5% 510 kΩ, 5%	01121 CB 01121 CB	343329
179	Resistor, Var.	1 kΩ, 10%, 0.5	01121 CB W 32997 3329H-1-102	343568 311404
Whe	en Option -01 is instal Resistor, MF	led, this component $4.53 \text{ k}\Omega$ , 1%	t changes as follows: RN55	341363
11	Oper. Amplifier	LF356P	01295	535040
12 13	Oper. Amplifier	NE5534AN	18324	535061
14	Analog Switch D-A Converter	LF13333N DAC-08EP	27014 06665	535095
5	Oper. Amplifier	NESS34AN	18324	421037 535061
16 17	Integrated Circuit	SN74LS00N	01295	534167
8	Integrated Circuit Oper. Amplifier	SN74121N LF356P	01295	534038
9	Oper. Amplifier	TL074CN	01295 01295	535040 535082
10	Integrated Circuit	CD4051BE	02735	534209
11	Integrated Circuit Oper. Amplifier	CD4051 <b>BE</b> TL0 <b>74CN</b>	02735 · 01295	534209
12		CD4052BE		535082
13	Integrated Circuit	CD4032BE	02735	2 14 1411
12 13 14 15	Oper. Amplifier Integrated Circuit	LF356P CD4051BE	02735 01295 02735	534140 535040 <b>534209</b>

Table 5-2. Replaceable Parts (Continued)

	Table 5-2. Replaceable Parts (Continued)					
Item	Descript		Mfr.	Mfr's Part #	BEC Part	
•		SUPPLY BOARD ASSEMBLY	(A4); PAR	T NUMBER 082107		
C1 C2 C3 C4 C5	Capacitor, El. Capacitor, Mica Capacitor, El. Capacitor, El. Capacitor, Cer.	10 μF, 20%, 25V 47 pF, 5%, 300V 10 μF, 20%, 25V 10 μF, 20%, 25V 0.1 μF, 20%, 25V	S4217 S4217 S4217 51406	DM5-EC470J SM25-VB-10M SM25-VB-10M	283336 205018 283336 283336 224364	
C6 C7 C8 C9 C10	Capacitor, Mica Capacitor, Cer. Capacitor, MPC Capacitor, Cer. Capacitor, Mica	1100 pF, 5%, 100V 0.1 µF, 20%, 25V 0.002 µF, 2%, 50V 0.001 µF, 10%, 100V 1100 pF, 5%, 100V	27735		200111 224364 234140 224270 200111	
C11 C12 C13 C14 C15	Capacitor, El. Capacitor, Cer. Capacitor, Cer. Capacitor, Cer. Capacitor, Tant.	10 µF, 20%, 25V 0.1 µF, 20%, 25V 0.1 µF, 20%, 25V 0.1 µF, 20%, 25V 10 µF, 20%, 25V	S4217 51406 51406 51406 56289	DD312E10Y5P104M25V DD312E10Y5P104M25V DD312E10Y5P104M25V	224364	
C16 C17 C18 C19 C20	Capacitor, Tant. Capacitor, Mylar Capacitor, Mylar Capacitor, El. Capacitor, El.	1.0 µF, 20%, 35V 0.1 µF, 10%, 100V 0.1 µF, 10%, 100V 10 µF, 20%, 25V 10 µF, 20%, 25V	56289 19701 19701 S4217 S4217	C280MAH/A100K C280MAH/A100K SM25-VB-10M	283216 234080 234080 283336 283336	
C21 C22 C23 C24 C25	Not Used Not Used Capacitor, El. Capacitor, El. Capacitor, El.	4700 μF, 16V 2200 μF, 35V 1000 μF, 35V		KSMM-2200-35 KSMM-1000-35	283351 283351 283350	
C26 C27 C28 C29 C30	Capacitor, Cer. Capacitor, Cer. Capacitor, Cer. Capacitor, Cer. Capacitor, Cer.	0.1 µF, 20%, 25V 0.1 µF, 20%, 25V 0.1 µF, 20%, 25V 0.001 µF, 10%, 100V 0.001 µF, 10%, 100V	51406 51406 51406 04222 04222	DD312E10Y5P104M25V DD312E10Y5P104M25V DD312E10Y5P104M25V SR151C102KAA SR151C102KAA	224364	
C31 C32 C33 C34 C35	Capacitor, Mica Capacitor, Tant. Capacitor, El. Capacitor, Tant. Capacitor, Tant.	47 pF, 5%, 300V 10 μF, 20%, 25V 100 μF, 20%, 25V 10 μF, 20%, 25V 10 μF, 20%, 25V	56289 S4217 56289	DM5-EC470J 196D106X0025KA1 SM25-VB-100M 196D106X0025KA1	205016 283293 283334 283293 283293	
C36 C37	Capacitor, Tant. Capacitor, Cer.	10 με, 20%, 25V 0.001 με, 10%, 100V	56289 04222	196D106X0025KA1 SR151C102KAA	283293 224270	
CR1 CR2 CR3 CR4 CR5	Diode, Signal Diode, Signal Diode, Signal Diode, Signal Diode, Signal	1N9 14 1N9 14 1N9 14 FDH-300 FDH-300	01295 01295 01295 07263 07263		530056 530056 530056 530052 530052	
CR6 CR7 CR8 CR9 CR10	Diode, Signal Diode, Signal Diode Bridge Diode Bridge Diode, Signal	1N9 14 1N9 14 VM-18 VM-18 1N4 00 1	01295 01295 27777 27777 04713		530056 530056 532031 532031 530151	
CR11 CR12 CR13 CR14 CR15	Diode, Signal Diode, Zener Diode, Signal Diode, Zener Diode, Signal	1N4001 1N5242B (12V) 1N4001 1N5242B (12V) 1N4001	04713 04713 04713 04713 04713		530151 530146 530151 530146 530151	
CR16 CR17 CR18 CR19 CR20	Diode, Signal Diode, Signal Diode, Signal Diode, Signal Diode, Signal	1N4001 1N4001 1N4001 1N4001 1N4001	04713 04713 04713 04713 04713		530 151 530 151 530 151 530 151 530 151	
21 22	Choke, R.F. Choke, R.F.	150 μH, 5% 150 μH, 5%	59474 59474	1315-16J 1315-16J	400415 400415	
21	Transistor, NPN	2N3904	04713		52807	
11 12 13 14 15	Resistor, Comp. Resistor, Comp. Resistor, MF Resistor, Comp. Resistor, Comp.	22 $k\Omega$ , 5% 1 $k\Omega$ , 5% 10.0 $k\Omega$ , 1% 1 $k\Omega$ , 5% 1 $k\Omega$ , 5%	01121 01121 01121 01121	CB CB RN55 CB CB	343433 343300 341400 343300 343300	

Table 5-2. Replaceable Parts (Continued)

	T	able 5-2.	Replaceable Pag	rts (Conti	nued)	
Item •		iption		Mfr.	Mfr's Part #	
R6 R7 R8	DIGITAL & POWER-S Resistor, MF Resistor, Comp. Resistor, Comp.	·	kΩ, 1%	, CONTINUE 01121 01121	D; PART NUMBER RN55 CB CB	341414 343300 343300
R9 R10 R11	Resistor Network Resistor, Comp.	3.3 } 1 kΩ,	τΩ <b>, 2%, 1.5</b> ₩ 5%	71450 01121 01121	750-101-R3.3K CB	345030 343300 343250
R12 R13 R14 R15	Resistor, Comp. Resistor, Comp. Resistor Network Resistor Network Resistor Network	10 ks 3.3 k 3.3 k	2, 5% Ω, 2%, 1.5W Ω, 2%, 1.5W Ω, 2%, 2W	01121	CB 750-101-R3.3K 750-101-R3.3K	34340( 34503)
R16 R17 R18 R19 R20	Resistor Network Resistor Network Resistor, MF Resistor, MF Resistor, Comp.	22 Ω, 909 }	:Ω, 1% _kΩ, 1%	73138 73138 01121	898-3-R22 RN60 RN55	34501' 34503' 34259' 34150' 34350'
R2 1 R2 2 R2 3 R2 4 R2 5	Resistor, Comp. Resistor, Comp. Resistor, Comp. Resistor, Comp. Resistor, Comp.	47 ks 22 ks 200 s 200 s 33 ks	1, 5% 2, 5% 1, 5%	01121 01121 01121 01121 01121	CB	343465 343433 343229 343229 343450
R26 R27 R28 R29 R30	Resistor, Comp. Resistor, Comp. Resistor, Comp. Resistor, Comp. Resistor, Comp.	1 kΩ, 1 kΩ, 22 kΩ 22 kΩ 10 kΩ	5% 1, 5% 1, 5%	01121 01121 01121 01121 01121		343300 343300 343433 343433 343400
R3 1 R3 2 R3 3 R3 4 R3 5	Resistor, Comp. Resistor, MF Resistor, MF Resistor, Comp. Resistor, Comp.	10 kg 909 g 2.0 k 360 g 750 g	i, 1% Ω, 1% !, 5%	01121 01121 01121	RN55 RN55	343400 341292 341329 343253 343284
<b>S</b> 1	Switch, DIP	7-sec	tion	71450	206-7	465215
J1 J2 J3 J4 J5	Integrated Circuit Oper. Amplifier Integrated Circuit Oper. Amplifier Integrated Circuit	LF356 CD404 LM311	n Obe n	01295 01295 02735 27014 01295		534155 535040 534275 535035 534157
J6 J7 J8 J9 J10	Integrated Circuit A-D Converter CPU Integrated Circuit Integrated Circuit	SN74L AD565 Z80-C SN74L SN74L	532N AJD/BIN PU-PS 5163AN S42N	01295 24355 56708 01295 01295		534168 421034 534159 534279 534210
J11 J12 J13 J14 J15	EPROM Integrated Circuit EPROM RAM RAM	51174L P2111 P2111		BEC 01295 BEC 34649 34649		534284 534278 534285 534162 534162
116 117 118 119 120	Integrated Circuit Integrated Circuit Integrated Circuit Transistor Array Integrated Circuit	AM825 AM825 UDN29 ULN28 CD405	5AAPC 83A 03A	34335 34335 56289 56289 02735		534171 534171 534255 534274 534209
121 122 123 124 125	Oper. Amplifier Integrated Circuit Oper. Amplifier Oper. Amplifier Voltage Regulator	TL072 CD405 CA308 CA308 MC78M	2BE 0E 0E	01295 02735 02735 02735 02735 04713		535092 534140 535091 535091 535046
127	Voltage Regulator Voltage Regulator Voltage Regulator Oper. Amplifier	µА780. МС78М µА79М LM324)	DSAUC .	04713 04713 04713 27014		535011 535046 535093 535068
1	Crystal	3.579	MHz	10236		547039
-	DISPI	AY BOARD	ASSEMBLY (A5); P	ART NUMBE	R 082110	
R2	Diode, LED Diode, LED Diode, LED	HLMP-	1401 (Yellow) 1301 (Red) 1301 (Red)	28480 28480 28480		536034 536022 536022

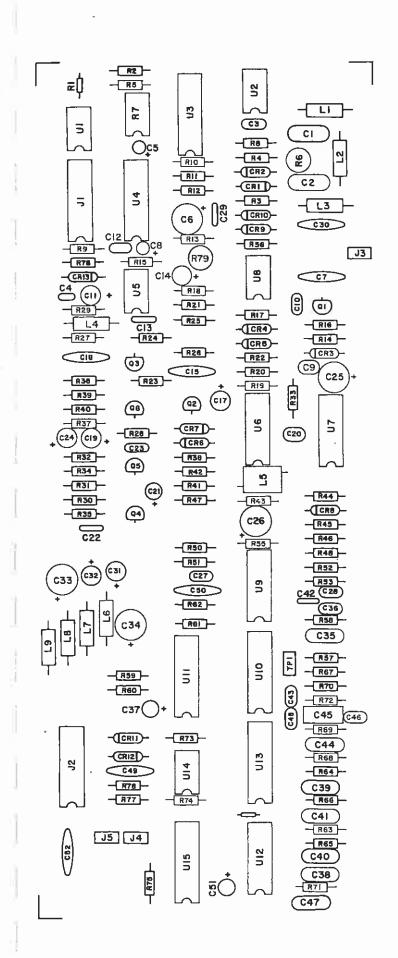
Table 5-2. Replaceable Parts (Continued)

<u>Item</u>	Descrip	tion	Mfr. Mfr's Part	# BEC Part #
•	DISPLAY BOA	RD ASSEMBLY (A5), CON	TINUED; PART NUMBER 0821	110
CR4 CR5	Diode, LED Diode, LED	HLMP-1301 (Red) HLMP-1301 (Red)	28480 28480	536022 536022
CR6 CR7 CR8 CR9 CR10	Diode, LED Diode, LED Diode, Signal Diode, Signal Diode, Signal	HLMP-1301 (Red) HLMP-1301 (Red) 1N914 1N914 1N914	28480 28480 01295 01295 01295	536022 536022 530058 530058 530058
CR11	Diode, Signal	1ท9 14	01295	530058
DS1 DS2 DS3 DS4	Display, Numeric Display, Numeric Display, Numeric Display, Numeric	5082-7656 5082-7651 5082-7651 5082-7651	28480 28480 28480 28480	536812 536811 536811 536811
S1 S2 S3 S4 S5	Switch, Pushbutton Switch, Pushbutton Switch, Pushbutton Switch, Pushbutton Switch, Pushbutton	Type D7 Type D7 Type D7 Type D7 Type D7 Type D7	31918 31918 31918 31918 31918 31918	465287 465287 465287 465287 465287
56 57 58 59 510	Switch, Pushbutton Switch, Pushbutton Switch, Pushbutton Switch, Pushbutton Switch, Pushbutton	Type D7 Type D7 Type D7 Type D7 Type D7	31918 31918 31918 31918 31918	465287 465287 465287 465287 465287
S11	Switch, Pushbutton	Type D7	31918	465287

# S E C T I O N VI SCHEMATIC DIAGRAMS

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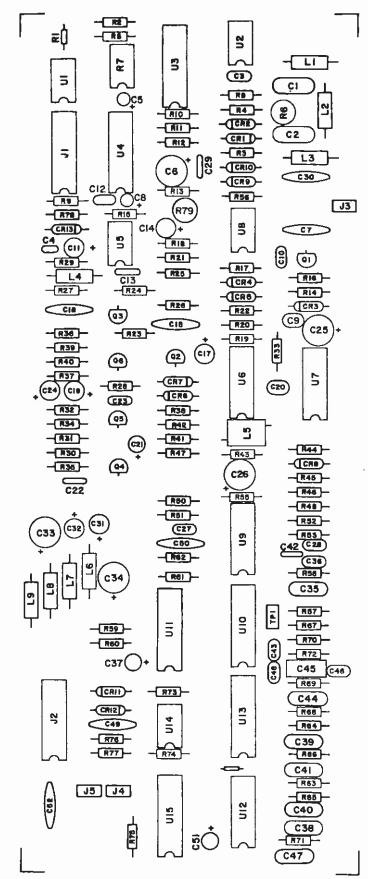


A2 R F P.C.BD, A4 DIGITAL/POWER SUPPLY P.C.BD. IF OUT MED/BLK LIKE RED/WHT 4 A 5 DISPLAY P.C.BD. Figure 6-1.
Main-Frame Schematic (E831193C, Sheet 1 of 4) A3 IF-AF P.C. BD. A3J4
CONNECTS TO
AIWZPZ
ON FRAME SCHEMATIC
#31193
SHT L OF 4 A3J5
CONNECTS TO
AWYPS
ON FRAME SCHEMATIC
831195
SHT L OF 4

Figure 6-2. I.F.-A.F. Board Schematic (E831193C, Sheet 3b of 4)

6-3 & 6-4

I.F.-A.F. Board Parts-Location Diagram (D831244C)



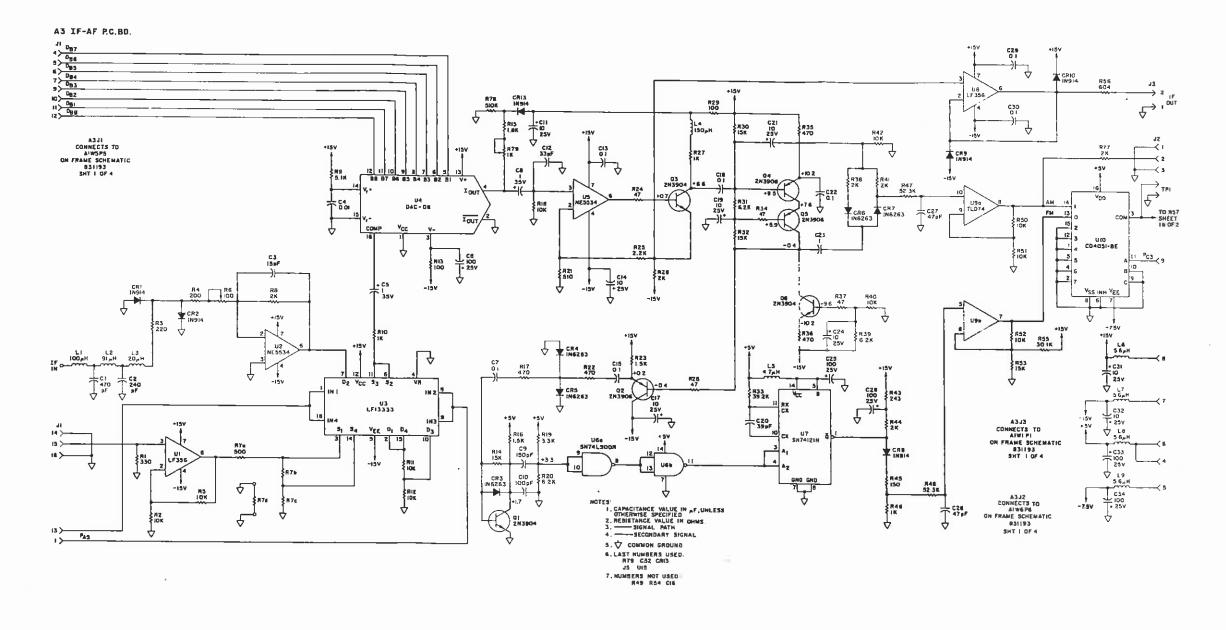
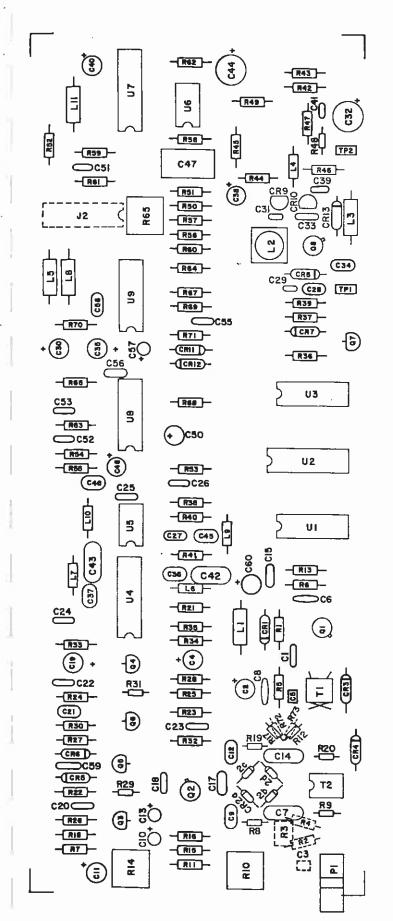


Figure 6-3. I.F.-A.F. Board Schematic (E831193D, Sheet 3a of 4) I.F.-A.F. Board Parts-Location Diagram (D831244C)



R.F. Board Parts-Location Diagram (D831245B)

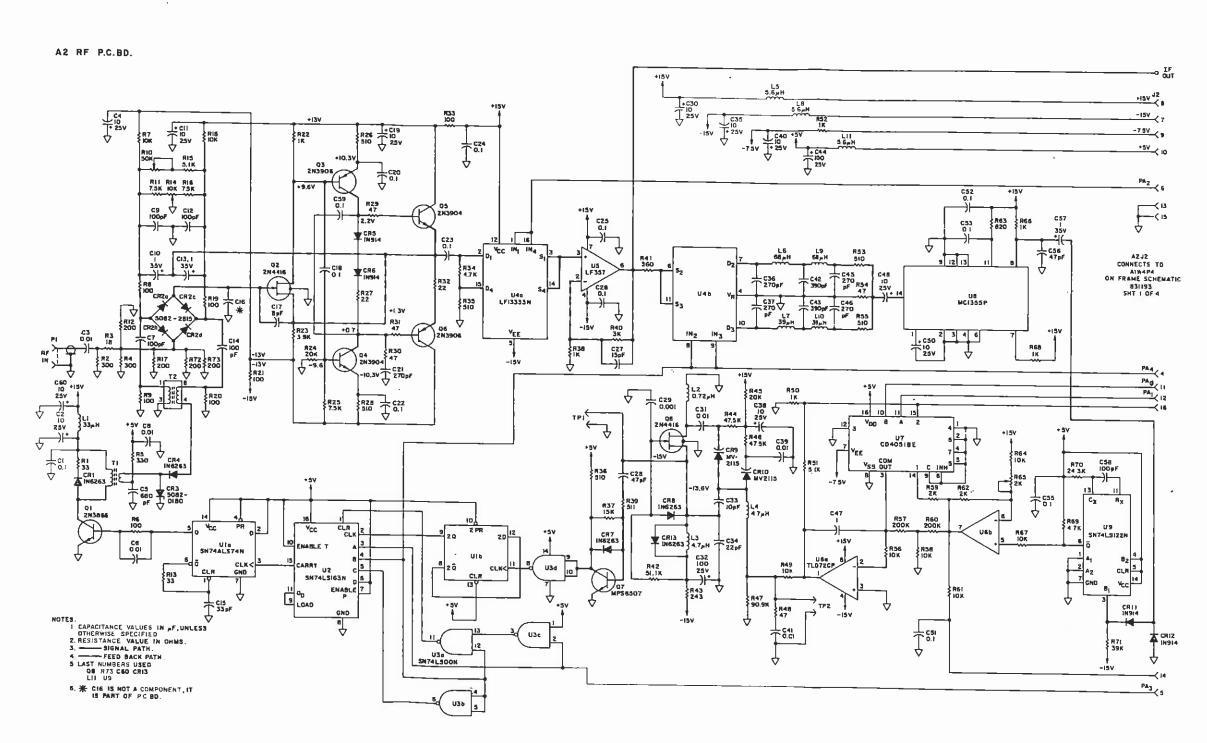
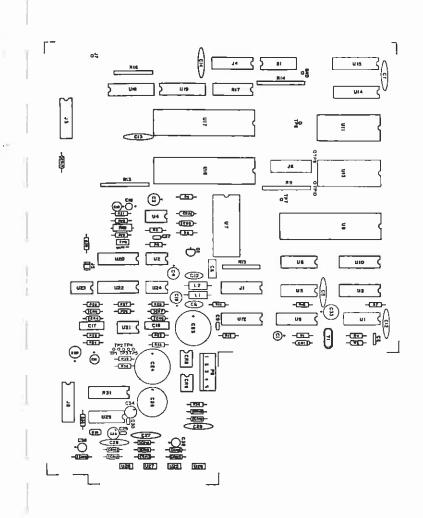


Figure 6-4.
R.F. Board Schematic
(E831193D, Sheet 2 of 4)



Digital & Power-Supply Board Parts-Location Diagram (D831248C)

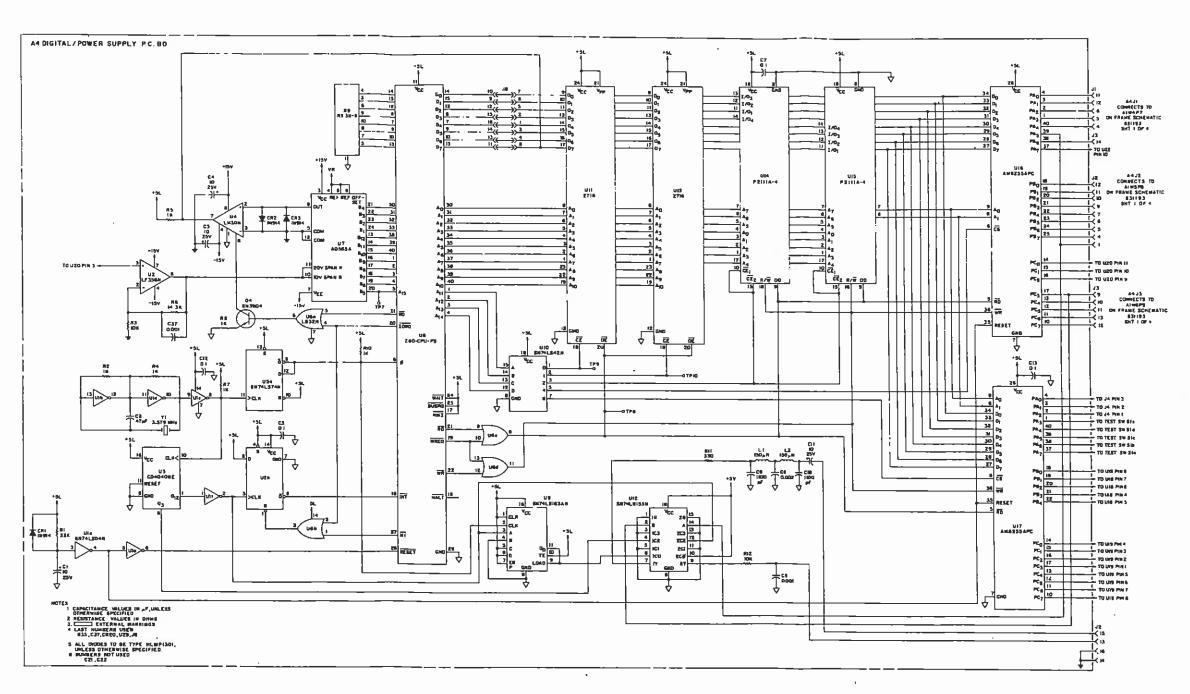


Figure 6-5.
Digital & Power-Supply Board
Schematic (R831193D, Sheet 4a of 4)

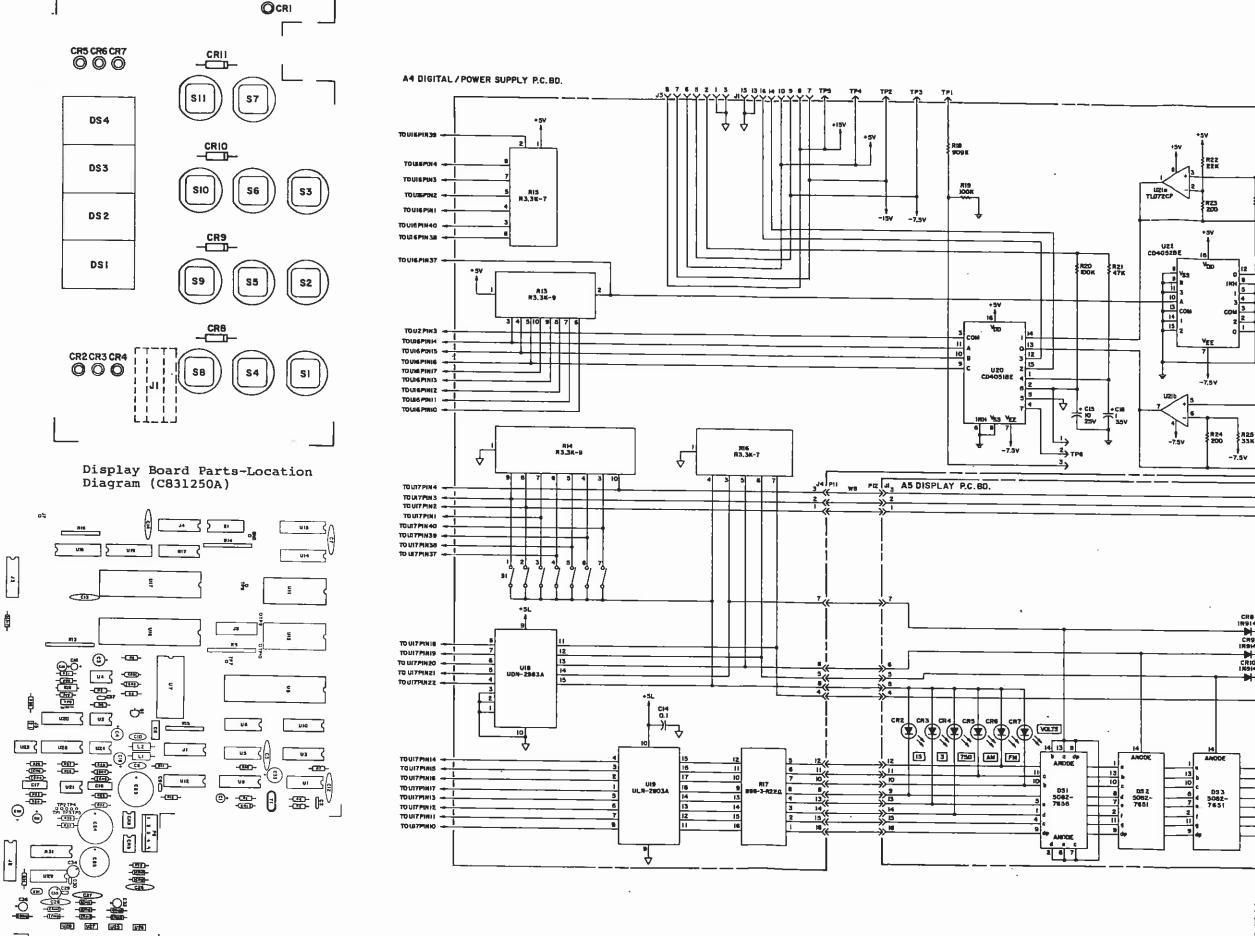


Figure 6-6.
Digital & Power-Supply Board
Schematic (E831193D, Sheet 4b of 4)

UZ3 CA3080E

3 LHz ISLHZ

\$7 SII 0

SiO b...

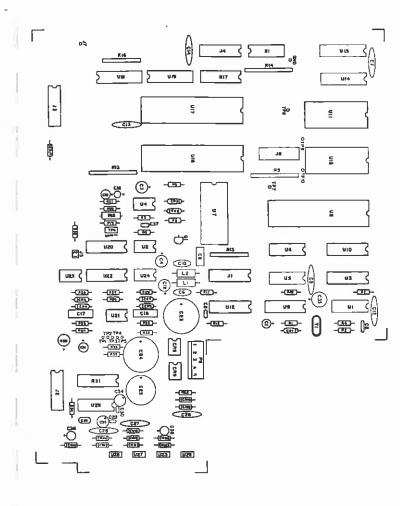
750,3

32 AVG

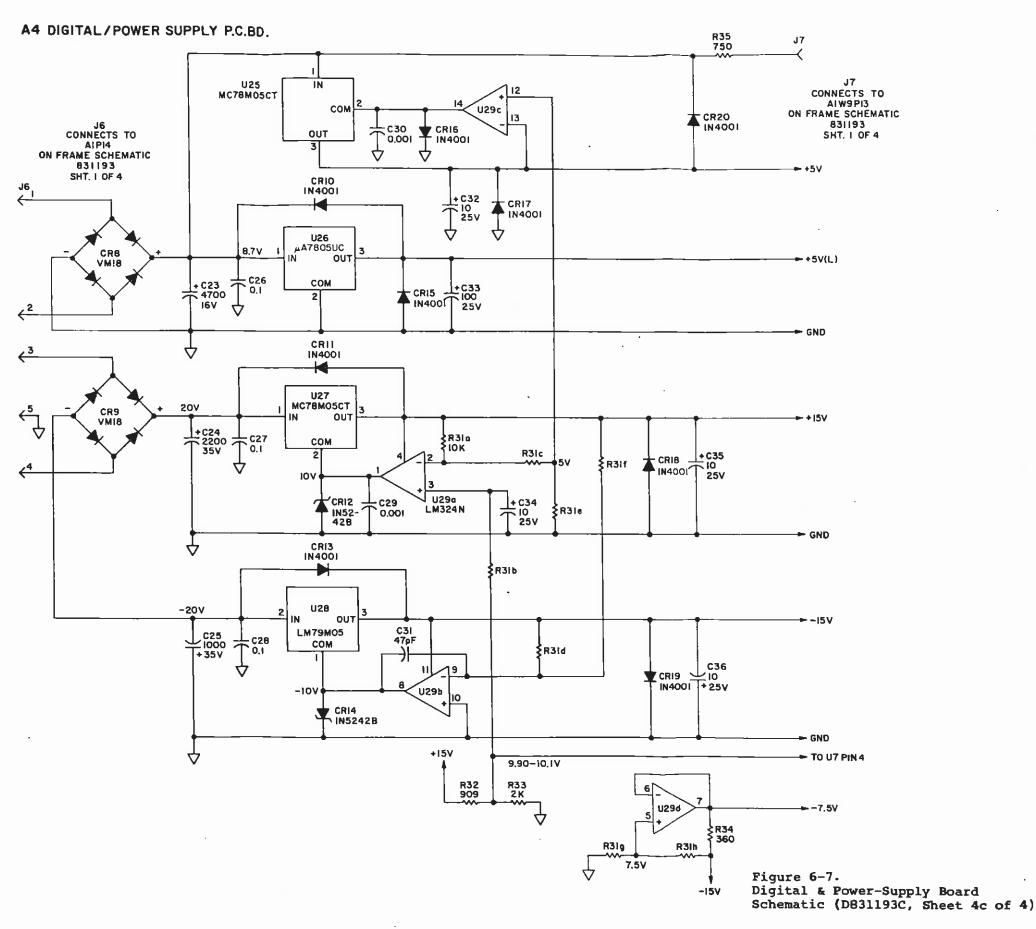
I A4J5
CONNECTS TO
AIW7PIO
OH FRAME SCHEMATIC
B3I193
SHT\_I OF 4

6-11 & 6-12

Digital & Power-Supply Board Parts-Location Diagram (D831248C)



Digital & Power-Supply Board Parts-Location Diagram (D831248C)



### APPENDIX A

### CALIBRATOR OPERATION

#### A-1. INTRODUCTION

The internal calibrators of the Model 8210 provide modulation standards for a.m. and f.m. measurements; they are activated each time the instrument is turned on. This section of the manual provides technical information concerning the operation and design of the calibrators.

### A-2. TECHNICAL DISCUSSION

- a. F.M. Calibrator. The calibration process consists of (1st) applying to the f.m. discriminator, in alternation, two accurately controlled frequencies; (2nd) measuring the resulting recovered modulation information; and (3rd) computing a correction factor for subsequent f.m measurements. As an aid in following this discussion refer to Figure 3-5.
  - (1) The input signal to pin 2 of A4U9 is the microprocessor's crystal-oscillator signal divided by two: 1.79 MHz. The preset inputs, A D, of A4U9 are alternately programmed to be 12 (decimal) or 13 (decimal), depending upon the sense of the signal on pin 3 of A4U9. This latter signal is generated by dividing the 3.58 MHz crystal-oscillator frequency by 4096. The resulting frequency is 874 Hz.
  - (2) When the preset inputs are programmed to decimal 12, five clock cycles (i.e., at 1.79 MHz) are required to cause the counter to overflow. The QD output then goes low, which reloads the preset inputs. Under these conditions, the counter is dividing the signal by a factor of five, resulting in an output frequency of 357.9 kHz. Similarly, when the preset inputs are programmed to decimal 13, the counter divides by four. The resulting frequency is then 447.4 kHz. The "average" frequency, therefore, is 402.6 kHz. The peak-to-peak deviation is 89.5 kHz and peak deviation is 44.75 kHz.
  - (3) To verify the accuracy of the f.m. calibrator, it is required only that the microprocessor's clock frequency be measured accurately. (Naturally, counter U9 must be operating properly as well.) Manual verification of the two (programmed) frequencies can be performed by lifting pin 2 of A4U9, shorting it alternately to +5 V and to ground, and measuring the resulting frequencies.
  - (4) The calibration program accumulates ten readings, and averages them to eliminate the last-digit uncertainty. The voltmeter, however, can resolve the actual deviation only to 1 part in 447. Thus the worst-case quantizing error is ± 0.22%. F.M. noise is of little or no consequence in determining calibrator deviation, since the two frequencies are crystal controlled and the r.f. circuitry is bypassed for calibration.
  - (5) Cross-correlation measurements using a Bessel null technique indicate that the actual calibration uncertainty for 100 calibrations is close to ± 0.11%, or one-half digit. (When employing Bessel null correlation, care should be taken to use a carrier with the lowest possible noise--and to take noise residuals into account--while keeping audio distortion to less than 0.1%.)
- b. A.M. Calibrator. The operation of the a.m. calibrator is similar to that of the f.m. calibrator. Refer to Figure 3-5.
  - (1) During a.m. calibration the count modulus of A4U9 is fixed at four. The resulting frequency, 447.5 kHz, is low-pass filtered by A4L1, L2, C6, C8 and C10 to remove harmonics. The signal's amplitude is

TA-2b(1), Continued.

not critical since the a.g.c. system is used to normalize the a.m. detector output.

- (2) The filtered signal is routed to the i.f.-a.f. circuit board via Cll, which removes any d.c. component, and thence to the input of buffer Ul. Amplifier Ul increases the level of the signal, and more importantly, provides a very low output impedance to drive the voltage divider consisting of A3R7a, b, and c. The signal is kept at a high level in its passage through A3U3 in order to reduce the effects of switching transients and feed-through. The attenuator consisting of Rll & Rl2 reduces the signal to the correct level after modulation.
- (3) The voltage divider comprising A3R7a, b, c, is a precision-resistor array. The absolute value of the resistors, however, is not as important as is the match between them. Thus, resistors R7b and R7c are guaranteed to a ± 0.1% match with R7a.

Maintaining this voltage divider at a constant impedance minimizes the loading effect of attenuator A3R11-R12.

(4) The voltage at the junction of A3R7a and R7b is two-thirds of the output voltage of A3U1; the voltage at the junction of R7b and R7c is one-third. The ratio of these two voltages is 2:1. The equivalent a.m. percentage is then derived as follows:

NOTE:  

$$p_{+} = +peak$$

$$p_{-} = -peak$$

$$p_{-} = \frac{E_{max} - E_{avg}}{E_{avg}} \times 100$$

$$p_{+} = \frac{E_{avg} - E_{min}}{E_{avg}} \times 100$$
(1)

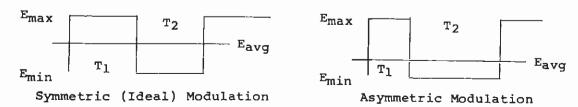
peak average 
$$% = \frac{P + - P_{-}}{2} \times 100$$
 (3)

Therefore, combining Eqs. 1, 2 & 3, for symetrical modulation,

(5) The above equations assume that the modulation is symmetrical (i.e. perfectly so). Should that not be the case, a d.c. shift occurs and the plus and minus peaks are not symmetrical. The calibrator program eliminates such an error by calculating a.m. as:

$$peak average = \frac{p_+ + 2p_-}{3}$$
 (5)

This expression is determined as follows:



Calibrator Modulation Signal

¶A-2b(5), Continued.

Now, since the peak detectors are a.c. coupled,

$$(p_+)(T_1) - (p_-)(T_2) = 0$$
 (0 volts, d.c.) (6)

And:  $T_1 + T_2 = 1$  (7)

$$(p_+)(T_1) - (p_-)(1 - T_1) = 0$$
 (8)

$$T_1 = \frac{p_-}{p_+ + p_-} \tag{9}$$

Now: 
$$E_{avg} = E_{min} + (E_{max} - E_{min}) \frac{T_1}{T_1 + T_2}$$
 (10)

And, in the 8210: 
$$E_{max} = 2E_{min}$$
 (11)

Combining Eqs. 7,10 & 11: 
$$E_{avg} = E_{min} + E_{min} (T_1)$$
 (12)

$$E_{avg} = E_{min} (1 + T_1)$$
 (13)

If symmetry is perfect: 
$$E_{avg} = E_{min}$$
 (1.5) (14)

If symmetry is less than perfect, the d.c. ratio error, R (that is, Eq. 13 vs. Eq. 14), will be:

$$R = (1 + T_1)/1.5 \tag{15}$$

Combining Eqs. 9 & 15: 
$$R = \frac{p_+ + 2 p_-}{1.5 (p_+ + p_-)}$$
 (16)

The uncorrected a.m., 
$$(E_{avg} \text{ normalized to 1}): = \frac{p_+ + p_-}{2}$$
 (17)

The corrected a.m. is then: 
$$= \frac{p_+ + p_-}{2} \times R$$
 (18)

And, from Eqs. 16 & 18, 
$$= \frac{p_+ + 2p_-}{3}$$
 (19)

- (6) It should be noted that only the ratio of the two modulating levels is important—not their absolute values. The two a.m. levels can be measured at the AF OUT connector by manually operating the IC analog switch A3U3 as follows:
  - (a) With power off, set Pos. #7 of Test Switch A4S1 "on."
  - (b) Power on. Connect a voltmeter to the AF OUT connector.
  - (c) Connect a clip lead from pin 1 or 16 of A3U3 to ground. (These pins are resistively isolated, so no harm will occur in grounding them.)
  - (d) Depress the AM FUNCTION button and measure the AF OUT voltage.
  - (e) Disconnect the clip lead from ground and connect it to +5 volts (pin 14 of A3U6).
  - (f) Measure the AF OUT voltage.

The ratio of the two voltages should be exactly 2:1, within ± 0.1% (The voltmeter should be able to resolve a 0.1% error at 447.4 kHz; a thermocouple type is suggested.)

The procedure given above is not intended to be a performance test;

### ¶A-2b(6), Continued.

- it is included only to satisfy one who is curious as to the operation of the calibrator.
- (7) The calibration program accumulates ten readings, and averages them to eliminate the last-digit uncertainty in the scaling operation. The voltmeter, however, can resolve the reading only to 1 part in 333. Therefore, the worst-case quantification error is ± 0.3%. A.M. noise is of little consequence in determining calibrator depth since the level is determined by TTL gates before filtering, and the frequency is crystal-controlled. Actual noise levels are less than 1 part in 3333.
- (8) Cross-correlation measurements using a specially calibrated Model 82AD F.M.-A.M. Modulation Meter (Boonton Electronics) indicate that the actual calibration uncertainty for 100 calibrations is approximately ± 0.15%.
- c. Audio Processing. During calibration, a three-pole gaussian filter is used to remove high-frequency signal components. The filter time-constants are selected so as to provide the required filtering without affecting the absolute peak values of the recovered signal. The use of a gaussian filter ensures that there will be no overshoot on the recovered audio signal.
- d. R.F. Circuitry. The Model 8210's r.f. circuitry is designed to have exceptional linearity so that a.m. performance is not degraded. As noted earlier, however, the r.f. circuits are not included in the modulation-calibration process. Consequently, during a.m. measurements, errors can occur if there is a malfunction in the r.f. section. These errors will usually be obvious to the user.

For f.m. measurements, the bypassing of r.f. circuitry during modulation calibration does not present a problem, since frequency modulation is the same before and after frequency conversion.

## TECHNICAL MANUAL

# CALIBRATION PROCEDURE

FOR

# MODULATION METER

8210, 8210-01-S/3

(BOONTON)



This publication replaces T.O. 33K3-4-3070-1 dated 30 May 1997 and all subsequent changes.

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**30 AUGUST 1999** 

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### MODULATION METER

## 8210, 8210-01-S/3

# (BOONTON)

# 1 CALIBRATION DESCRIPTION:

### Table 1.

Test Instrument (TI) Characteristics	Performance Specifications	Test Method
Carrier Level Sensitivity	Range: 2 MHz to 1500 MHz	Known Signal applied
	Accuracy: 10 mV ( -27 dBm) from 2 MHz to 520 MHz; 30 mV (-17.4 dBm) from 520 to 1500 MHz:	
FM Modulation (8210)	Range: Rates <30 Hz to 15 kHz Range 0 to 150 kHz peak	Compared to a Modulation Analyzer.
	Accuracy:  * ±1% of reading for rates 50 Hz  to 5 kHz;  * ±2% of reading for 5 to 7.5 kHz;	
* Note Peak residuals must be	accounted for to obtain the above accuracy.	
FM Modulation (8210-01)	Range: Rates <30 Hz to 30 kHz Range 0 to 150 kHz peak	Compared to a Modulation Analyzer.
	Accuracy:  * ±1% of reading for rates 50 Hz to 10 kHz:  * ±2% of reading for 10 to 15 kHz:	
* Note Peak residuals must be	accounted for to obtain the above accuracy.	
lesidual FM RF Level >100 mV)	Range: 2 to 1500 MHz	CW Signal applied and residual FM measured
(8210)	Accuracy: 3 kHz Low Pass filter: <150 Hz rms at 1500 MHz linear decreasing to floor of <5 Hz rms	
	15 kHz Low Pass Filter: <200 Hz rms at 1500 MHz linear decreasing to floor of <15 Hz rms	

Table 1. (Cont.)

Test Instrument (TI) Characteristics		Performance Specifications	Test Method	
Residual FM (RF Level >100 mV)		Range: 2 to 1500 MHz	CW Signal applied and Residual FM measured	
(8210-01)		Ассигасу:		
		3 kHz Low Pass filter:		
		<150 Hz rms at 1500 MHz		
		linear decreasing to floor of <5 Hz rms		
		30 kHz Low Pass Filter.		
		<400 Hz rms at 1500 MHz		
		linear decreasing to floor of <25 Hz rms		
AM Rejection		Range:	Known AM signal applied	
		50% AM Depth, 3 kHz Low Pass	and FM Signal Measured	
		Accuracy: <100 Hz deviation at		
		50% AM Modulation (1 kHz rate)		
		(FM Residual subtracted)		
FM Distortion		Range: 75 kHz deviation	Known signal applied and	
		50 to 10 kHz rate	distortion measured	
		Accuracy: <0.25% THD		
AM Modulation		Range: 0 to 100% at	Compared to Modulation	
(8210)		Rates, 50 Hz to 7.5 kHz	Analyzer	
		Accuracy: **		
	Modulation Rate	10% to 90%	<10% & 90%	
▼ 50 Hz to 5 kH		.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	3% of reading	
	* 5 kHz to 7.5 kH	z 2% of reading	6% of reading	
* Note: Peak res: ** Note: Carrier	iduals must be acco frequency <520 M	ounted for to obtain the above accuracy; Hz; with RF levels between -10 and -10	dBm.	
AM Modulation		Range: 0 to 100% at	Compared to Modulation	
8210-01)		Rates, <30 Hz to 30 kHz	Analyzer	
		Accuracy: **		
	Modulation Rate	10% to 90%	<10% & 90%	
	* 50 Hz to 10 kH:		3% of reading	
	* 10 kHz to 15 kH	Iz 2% of reading	6% of reading	

<sup>\*</sup> Note: Peak residuals must be accounted for to obtain the above accuracy; \*\* Note: Carrier frequency <520 MHz; with RF levels between -10 and -10 dBm.

Table 1. (Cont.)

Test Instrument (TI) Characteristics	Performance Specifications	Test Method	
Residual AM (RF Level >100 mV) (8210)	Range: 2 to 1500 MHz  Accuracy: ** 3 kHz Low Pass filter:	CW Signal applied and Residual AM measured	
	<0.15% AM, rms <520 MHz carrier		
	** 15 kHz Low Pass Filter: <0.25% AM, rms <520 MHz Carrier		
** Note: Above 520 MHz carr	ier frequency the AM Residuals increase linearly	with frequency	
Residual AM (RF Level >100 mV)	Range: 2 to 1500 MHz	CW Signal applied and residual FM measured	
(8210-01)	Accuracy: ** <0.15% AM, ms <520 MHz  Carrier		
	** 30 kHz Low Pass Filter: <0.35% AM, rms <520 MHz Carrier		
** Note: Above 520 MHz carr	ier frequency the AM Residuals increase linearly	y with frequency	
FM Rejection	Range: To 150 kHz deviation	Known FM signal applied AM modulation measured	
	Accuracy: <1.0% AM peak		
AM Distortion	Range 0 to 90% depth 50 Hz to 10 kHz rate	Distortion measured with Audio Analyzer	
	Accuracy: ≤0.5%		
Audio Filters (8210)	Range: Lowpass 3 kHz, 15 kHz	Pass frequency set and corner deviation limits measured	
	De-emphasis 750 µs	mas measure	
	Accuracy: ±4% 3 dB corner and time constant		
Audio Filters (8210-01)	Range: Lowpass 3 kHz, 30 kHz	Pass frequency set and corner deviation limits measured	
	De-emphasis 750 μs		
	Accuracy: ±4% 3 dB corner and time constant		

#### T.O. 33K3-4-3070-1

### **2 EQUIPMENT REQUIREMENTS:**

	Noun	Minimum Use Specifications	Calibration Equipment	Sub- Item
2.1	SIGNAL GENERATOR	Range: 0.01 to 1500 MHz  Accuracy: ±5 X 10 <sup>-10</sup>	Hewlett-Packard 8663A Opt 001-002	As Avail.
2.2	TEST OSCILLATOR	Range: 1 MHz to 18 MHz Accuracy: ±1%	Hewlett-Packard 3325A	
2.3	AUDIO ANALYZER	Range: 20 Hz to 40 kHz 0 to 3 Vrms  Accuracy: ±3% Flatness	Hewlett-Packard 8903B	As Avail.
2.4	DIGITAL VOLTMETER	Range: DC 0 to +12 VDC AC 0 to 3 Vrms  Accuracy: DC ±1% AC ±0.1%	Hewlett-Packard 3458A	
2.5	MODULATION ANALYZER	Range: FM Deviation 0 to 200 kHz, Rate 20 to 50 kHz AM Depth 0 to 100%	Hewlett-Packard 8901A/B	
2.6	POWER SPLITTER	Accuracy: FM Deviation; ±2.0% AM Depth; 2.0% Range: 2 to 1500 MHz Accuracy: N/A	Hewlett-Packard 11667A	

### **3 PRELIMINARY OPERATIONS:**

3.1 Review and become familiar with the entire procedure before beginning Calibration Process.



Unless otherwise designated, and prior to beginning the Calibration Process, ensure that all test equipment voltage and/or current outputs are set to zero (0) or turned off, where applicable. Ensure that all equipment switches are set to the proper position before making connections or applying power.

- 3.2 The TI may be equipped with one or more of the following options:
  - A. Option 01, 30 kHz Low Pass Filter. The standard 15 kHz Low Pass Filter is replaced with a 30 kHz Low Pass Filter.
- B. Option S/3, Alkaline Battery internal Power Pack. The TI has an internal Alkaline battery pack.

  3.3 Apply power to Test Equipment and allow a 10 minutes warm-up period.

#### 3.5 SELF TEST CALIBRATION CHECKS:

- 3.5.1 Press and hold the LEVEL switch while pressing the TI LINE switch to the ON position, then release the LEVEL switch. The TI display will indicate CAL which means an internal calibration procedure has begun.
- 3.5.2 Calibration takes approximately 30 seconds and no errors should be displayed. If any errors are noted, TI should be repaired using proper maintenance documents before proceeding with calibration.

#### NOTE

When the TI as no signal applied or the signal applied is below the level required for a measurement the TI display will show a series of dashes to indicate an UNLOCKED condition. The presence of a measurement value indicates a LOCKED condition. If a signal is applied that requires a Automatic Gain Control (AGC) cycle the TI LED display shows two dashes. The two dashes is not an UNLOCK condition, but a normal indication of automatic operation.

- 3.5.3 After calibration completes a series of dashes should appear on the LED to indicated the TI is in a unlocked condition.
- 3.5.4 Complete a TI preliminary functional check as follows:
- 3.5.4.1 Connect Test Oscillator to TI RF IN 50 Ω connector.
- 3.5.4.2 Set Test Oscillator for a 15 MHz -7 dBm (100 mVrms) CW signal to the TI. The TI LED display should indicate the residual modulation.
- 3.5.4.3 Reduce Test Oscillator output amplitude to -33 dBm (5 mVrms). Verify the TI display indicates IFLO.
- 3.5.4.4 Increase Test Oscillator output amplitude to +17 dBm (1.59 Vrms). Verify the TI display indicates IFHI.
- 3.5.4.5 Set Test Oscillator output amplitude to 0 dBm (224 mVrms).
- 3.5.4.6 Depress in turn the three FILTERS switches, and verify the correct annunciator light.
- 3.5.4.7 Depress in turn the three FUNCTION switches, and verify the correct annunciator light.
- 3.5.4.8 Depress in turn the three PEAK switches, and verify the correct annunciator light. A plus sign (+) will be shown for the + PEAK switch, a minus sign (-) for -PEAK, and no sign when the AVG switch is depressed.
- 3.5.4.9 Depress each RANGE switch and verify the decimal point moves right or left as each switch is depressed.
- 3.5.4.10 Set Test Oscillator output to OFF and disconnect from TI.
- 3.5.4.11 Connect Signal Generator RF OUT connector to TI RF IN 50Ω connector.
- 3.5.4.12 Set Signal Generator for a 15 MHz signal with a 0 dBm (224 mVrms) level. Set for AM modulation with a 1 kHz rate and a 50% depth.
- 3.5.4.13 Depress the TI AM FUNCTION, the 100 SCALE, and the 15 kHz FILTER switches. Verify the TI LED display indicates approximately 50% AM modulation.

- 3.5.4.14 Set Signal Generator AM modulation OFF. Set Signal Generator for FM modulation at a 1 kHz rate and a 50 kHz peak deviation.
- 3.5.4.15 Depress TI FM FUNCTION switch, and verify the TI LED display indicates approximately 50 kHz Deviation.
- 3.5.4.16 Set Signal Generator RF output to OFF, and disconnect equipment.
- 3.6 Perform only the sections of this procedure applicable to the TI being calibrated.

#### 4 <u>CALIBRATION PROCESS:</u>

#### NOTE

Unless otherwise specified, verify the results of each test and take corrective action whenever the test requirement is not met, before proceeding.

#### 4.1 <u>CARRIER LEVEL SENSITIVITY CALIBRATION:</u>

- 4.1.1 Connect Signal Generator RF OUT connector to the TI RF IN 50Ω connector.
- 4.1.2 Depress the TI switches as follows:

FILTERS	15 kHz (8210) 30 kHz (8210-01)
PEAK	AVG

FUNCTION FM

RANGE 100

- 4.1.3 Set Signal Generator for a 10 MHz CW output with a level of -27 dBm (10 mVrms).
- 4.1.4 The TI must indicate a LOCKED condition that the TI will make a measurement at the 10 mVrms level.
- 4.1.5 Set Signal Generator for a 500 MHz CW output with a level of -27 dBm (10 mVrms).
- 4.1.6 The TI must indicate a LOCKED condition that the TI will make a measurement a the 10 mVrms level.
- 4.1.7 Set Signal Generator for a 1500 MHz CW output with a level of -17.4 dBm (30 mVrms).
- 4.1.8 The TI must indicate a LOCKED condition that the TI will make a measurement at the 30 mVrms level.

#### 4.2 FM RESIDUAL AND AM RESIDUAL CALIBRATION:

4.2.1 Connect equipment as shown in Figure 1.

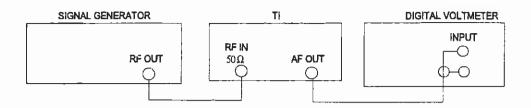


Figure 1.

4.2.2 Depress the TI switches as follows:

FILTERS	15 kHz (8210) 30 kHz (8210-01)
PEAK	AVG
FUNCTION	FM
RANGE	10

- 4.2.3 Set Signal Generator for a 500 MHz CW output with a level of 0 dBm (224 mVrms).
- 4.2.4 Set Digital Voltmeter as required for a AC measurement with a bandpass width of 5 Hz to 100 kHz. Verify the Digital Voltmeter indication (FM Residual) is less than 13.3 mV (26.6 for 8210-01).
- 4.2.5 Record the TI residual FM indication for the 15 kHz Low Pass filter (30 kHz for TI 8210-01).
- 4.2.6 Depress TI 3 kHz FILTER.
- 4.2.7 Verify the Digital Voltmeter indication is less than 10 mV.
- 4.2.8 Record the TI residual FM indication for the 3 kHz Low Pass filter.
- 4.2.9 Depress TI AM FUNCTION switch.
- 4.2.10 Set Digital Voltmeter as required for an AC measurement with a bandpass width of 5 Hz to 100 kHz. Verify the Digital Voltmeter indication (AM residual) is less than 30.0 mV.
- 4.2.11 Depress TI 15 kHz (30 kHz for TI 8210-01) FILTER.
- 4.2.12 Verify the TI residual AM indication for the 15 kHz (30 kHz for TI 8210-01) Low Pass filter is less than 50 mV (70 mV for 8210-01).

#### 4.3 FM MODULATION DEVIATION ACCURACY CALIBRATION:

4.3.1 Connect the equipment as shown in Figure 2.

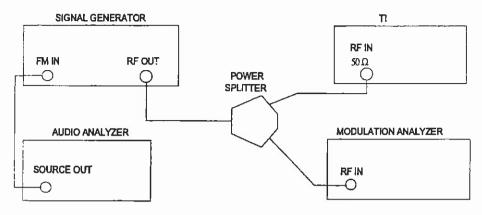


Figure 2.

- 4.3.2 Set the Signal Generator for 500 MHz at +3 dBm, FM to 100 kHz deviation and EXT DC.
  - 4.3.3 Depress the TI switches as follows:

FILTERS	15 kHz (8210) 30 kHz (8210-01)
PEAK	AVG
FUNCTION	FM
RANGE	100

- 4.3.4 Set Modulation Analyzer MEASUREMENT to FM, DETECTOR to PEAK+, HP FILTER to OFF and LP FILTER to >20 kHz.
- 4.3.5 Adjust Audio Analyzer for a output frequency of 1 kHz, and adjust output amplitude for a Modulation Analyzer FM indication of 100 kHz deviation.
- 4.3.6 Subtract the TI residual FM value recorded in step 4.2.5 from the the TI indicated value.
- 4.3.7 Verify the calculated value from 4.3.6 is 99 to 101 kHz.
- 4.3.8 Set Audio Analyzer frequency, TI SCALE, Signal Generator Deviation, as listed in Table 2.

Table 2.

Audio Analyzer (Hz)	Signal Generator (Deviation kHz)	TI SCALE	Modulation Analyzer (kHz)	TI Limits (kHz)
8210 1 k	100	100	100	99.0 to 101.0 *
50	100	100	100	99.0 to 101.0 *

Table 2. (Cont.)

Audio Analyzer (Hz)	Signal Generator (Deviation kHz)	TI SCALE	Modulation Analyzer (kHz)	TI Limits (kHz)
4.9 k	100	100	100	99.0 to 101.0 *
5.1 k	100	100	100	98.0 to 102.0 *
7.5 k	100	100	100	98.0 to 102.0 *
1 k	10	10	10	9.90 to 10.1 *
8210-01 1 k	100	100	100	99.0 to 101.0 *
50	100	100	100	99.0 to 101.0 *
5.0 k	100	100	100	99.0 to 101.0 *
7.5 k	100	100	100	99.0 to 101.0 *
9.9 k	100	100	100	99.0 to 101.0 *
10.1 k	100	100	100	98.0 to 102.0 *
15.0 k	100	100	100	98.0 to 102.0 *
1 k	10	10		9.90 to 10.1 *

<sup>\*</sup> Peak residuals must be accounted for to obtain the listed Accuracy.

#### 4.4 AM REJECTION CALIBRATION:

- 4.4.1 Connect equipment as shown in Figure 3.
- 4.4.2 Set the Signal Generator for a 30 MHz at 0 dBm, AM to 30% and EXT DC.
- 4.4.3 Depress the TI switches as follows:

FILTERS	3 kH2
PEAK	AVG
FUNCTION	AM
RANGE	100

<sup>4.3.9</sup> Set Audio Analyzer and Signal Generator RF Outputs to OFF and disconnect the test setup.

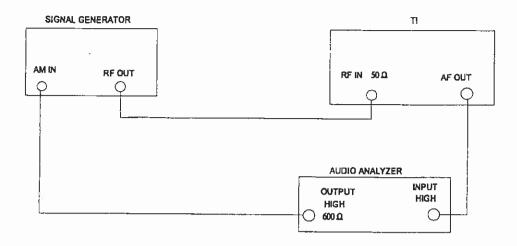


Figure 3.

- 4.4.4 Set Audio Analyzer for a 600  $\Omega$  source output (47.0 Special). Set for a output frequency of 1 kHz, and adjust output amplitude for a TI AM indication of 50% modulation.
- 4.4.5 Depress TI FUNCTION FM switch.
- 4.4.6 Vary Signal Generator amplitude for 0 to +10 dBm as required for a TI FM deviation null (minimum value). Record the TI display value (FM Deviation).
- 4.4.7 Subtract the FM Residual value recorded in step 4.2.5 from the value recorded in 4.4.6 to find AM rejection FM peak deviation.
- 4.4.8 The AM rejection FM peak deviation must be less than 100 Hz Peak.

#### 4.5 AM AUDIO DISTORTION CALIBRATION:

#### NOTE

Distortion will only be checked at 1 kHz because of available generators.

- 4.5.1 Perform AM Audio Distortion calibration with equipment connected as in Figure 3.
- 4.5.2 Set Signal Generator as required for a 30 MHz at 0 dBm, AM to 90% and EXT DC.
  - 4.5.3 Depress the TI switches as follows:

FILTERS	15 kHz (8210) 30 kHz (8210-01)
PEAK	AVG
FUNCTION	AM
RANGE	100

- 4.5.4 Set Audio Analyzer for a 600  $\Omega$  source output (47.0 Special). Set for a output frequency of 1 kHz, and adjust output amplitude for a TI AM indication of 90% modulation.
- 4.5.5 Verify Audio Analyzer Distortion indication is less than 0.5%.

#### 4.6 AUDIO FREQUENCY RESPONSE 15 kHz CALIBRATION:

- 4.6.1 Perform the audio frequency response 15 kHz test, with equipment connected as in Figure 3.
- 4.6.2 Set Signal Generator to 60% AM.
- 4.6.3 Depress the TI switches as follows:

FILTERS 15 kHz (8210) 30 kHz (8210-01)

PEAK AVG

FUNCTION AM

RANGE 100

- 4.6.4 Set Audio Analyzer for a 600  $\Omega$  source output (47.0 Special). Set for a output frequency of I kHz, and adjust output amplitude for a TI AM indication of 60% modulation.
- 4.6.5 While maintaining a constant Audio Analyzer output amplitude, vary the modulation frequency between 50 Hz and 5 kHz for 8210, 50 Hz and 10 kHz for 8210-01.
- 4.6.6 Verify the TI display indication is within 59.4% and 60.6% at all modulation frequencies.
- 4.6.7 While maintaining a constant Audio Analyzer output amplitude, vary the modulation frequency between 5 kHz and 7.5 kHz for 8210, 10 kHz and 15 kHz for 8210-01.
- 4.6,8 Verify the TI display indication is within 58.5% and 61,2% at all modulation frequencies.
- 4.6.9 While maintaining a constant Audio Analyzer output amplitude, set frequency to 15 kHz for 8210, or 30 kHz for 8210-01.
- 4.6.10 Verify the TI display indication is within 40.4% and 44.3%.
- 4.6.11 Set Audio Analyzer and Signal Generator outputs to OFF.
- 4.6.12 Disconnect equipment shown in Figure 3.

#### 4.7 FM DISTORTION CALIBRATION:

- 4.7.1 Connect the equipment as shown in Figure 4.
- 4.7.2 Set Signal Generator as required for a 100 MHz at 0 dBm, FM to 75 kHz deviation and EXT DC.

#### 4.7.3 Depress the Tl switches as follows:

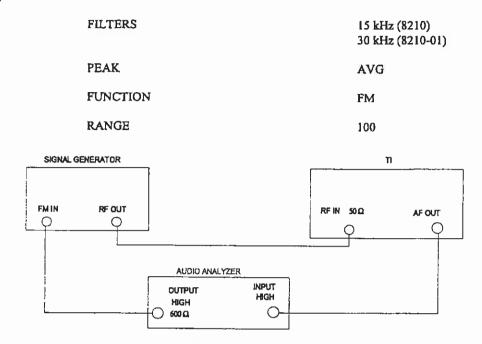


Figure 4.

- 4.7.4 Set Audio Analyzer for a 600  $\Omega$  source output (47.0 Special). Set for a output frequency of 1 kHz, and adjust output amplitude for a TI FM indication of 75 kHz peak deviation.
- 4.7.5 Verify the distortion is less than 0.25%.
- 4.7.6 Repeat steps 4.7.2, 4.7.4 and 4.7.5 for modulation frequency of 50 Hz and 10 kHz.

#### 4.8 FM REJECTION CALIBRATION:

- 4.8.1 With equipment connected as shown in Figure 4 perform the FM rejection calibration.
- 4.8.2 Set Signal Generator as required for a 100 MHz at 0 dBm, FM to 100 kHz deviation.
  - 4.8.3 Depress the TI switches as follows:

FILTERS	15 kHz (8210) 30 kHz (8210-01)
PEAK	AVG
FUNCTION	FM
RANGE	100

4.8.4 Set Audio Analyzer for a 600  $\Omega$  source output (47.0 Special). Set for a output frequency of 1 kHz, and adjust output amplitude for a TI FM indication of 100 kHz peak deviation.

4.8.5 Set TI controls as Follows:

**FUNCTION** 

AM

RANGE

10

4.8.6 Verify the TI display indicated a value less than 1.0% peak.

#### 4.9 AUDIO FREQUENCY RESPONSE 3 kHz LOW PASS FILTER CALIBRATION:

- 4.9.1 With equipment connected as shown in Figure 4 perform the 3 kHz filter calibration.
- 4.9.2 Depress the TI switches as follows:

**FILTERS** 

3 kHz (8210)

3 kHz (8210-01)

**PEAK** 

AVG

**FUNCTION** 

FM

RANGE

100

- 4.9.3 Set Audio Analyzer for a 600  $\Omega$  source output (47.0 Special). Set for a output frequency of 300 Hz, and adjust output amplitude for a TI FM indication of 100 kHz peak deviation.
- 4.9.4 While maintaining a constant Audio Analyzer output amplitude, set the modulation frequency to 3.000 kHz.
- 4.9.5 Verify the TI display indication is within 67.5 to 73.8 kHz.

#### 4.10 AUDIO FREQUENCY RESPONSE 750 µs DE-EMPHASIS CALIBRATION:

- 4.10.1 With equipment connected as shown in Figure 4 perform the de-emphasis calibration.
- 4.10.2 Set Signal Generator as required for a 100 MHz at 0 dBm, FM to 100 kHz deviation and EXT DC.
- 4.10.3 Depress the TI switches as follows:

**FILTERS** 

3 kHz (8210)

3 kHz (8210-01)

**PEAK** 

AVG

**FUNCTION** 

FM

RANGE

100

- 4.10.4 Set Audio Analyzer for a 600  $\Omega$  source output (47.0 Special). Set for a output frequency of 212.2 Hz, and adjust output amplitude for a TI FM indication of 100 kHz peak deviation.
- 4.10.5 Depress TI FILTER, DE-EMPHASIS switch.

- 4.10.6 Verify the TI display indication is within 68.0 to 73.5 kHz.
- 4.10.7 Disconnect equipment shown in Figure 4.

#### 4.11 AM MODULATION DEPTH ACCURACY CALIBRATION:

4.11.1 Connect the equipment as shown in Figure 5.

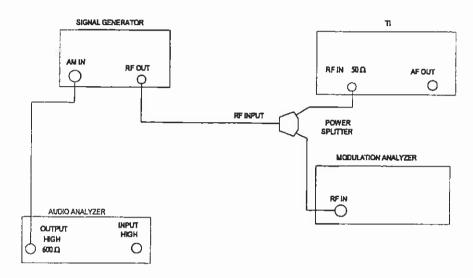


Figure 5.

- 4.11.2 Set the Signal Generator for a 30 MHz, at +3 dBm, AM to 30% and EXT DC.
  - 4.11.3 Depress the TI switches as follows:

FILTERS	15 kHz (8210) 30 kHz (8210-01)
PEAK	AVG
FUNCTION	AM
RANGE	100

- 4.11.4 Adjust Audio Analyzer for a output frequency of 1 kHz, and adjust output amplitude for a Modulation Analyzer AM indication of 30% depth.
- 4.11.5 Verify TI indicates a AM depth 29.7 to 30.3% (See Table 3 Note).
- 4.11.6 Set Audio Analyzer frequency and Modulation Analyzer Depth (%), as listed in Table 3.
- 4.11.7 At each Modulation Rate and Depth verify the TI display indicates a depth value within the limits listed in Table 3.

Table 3.

Signal Gen Output	erator MOD%	Audio Analyzer (Hz)	Modulation Analyzer (%)	Tl Limits (%)
8210				
30 MHz at +3 dBm	30	1 k	30	29.7 to 30.3 *
30 MHz at +3 dBm	50	1 k	50	49.5 to 50.5 *
30 MHz at +3 dBm	70	1 k	70	69.3 ta 70.7 *
30 MHz at +3 dBm	90	1 k	90	89.1 to 90.9 *
30 MHz at +3 dBm	90	6 k	90	88.2 to 91.8 *
30 MHz at +3 dBm	90	7.5 k	90	88.2 to 91.8 *
8210-01				
30 MHz at +3 dBm	30	1 k	30	29.7 to 30.3 *
30 MHz at +3 dBm	50	1 k	50	49.5 to 50.5 *
30 MHz at +3 dBm	70	1 k	70	69.3 to 70.7 *
30 MHz at +3 dBm	90	1 k	90	89.1 to 90.9 *
30 MHz at +3 dBm	90	9.9 k	90	89.1 to 90.9 *
30 MHz at +3 dBm	90	10.1 k	90	88.2 to 91.8 *
30 MHz at +3 dBm	90	15 k	90	88.2 to 91.8 *

<sup>\*</sup> Note: Peak residuals must be accounted for to obtain the listed Accuracy.

#### CALIBRATION PERFORMANCE TABLE

#### 4.1 CARRIER LEVEL SENSITIVITY CALIBRATION:

Frequency (MHz)	<u>Limit (mV)</u>
10 to 500	10
500 to 1500	30

<sup>4.11.8</sup> Set Audio Analyzer and Signal Generator RF Outputs to OFF.

<sup>4.11.9</sup> Set all STANDBY/POWER switches to STANDBY or OFF. Disconnect and secure all equipment.

#### CALIBRATION PERFORMANCE TABLE (Cont.)

#### 4.2 FM RESIDUAL AND AM RESIDUAL CALIBRATION:

FM Residual (8210)

Low Pass Filter	Frequency	Bandwidth	<u>Limits</u>
15 kHz Specification is <200 Hz rms	500 MHz at 1.5 GHz decreasing linearly	100 kHz to a floor of <15 Hz rms.	<13.3 mVrms
3 kHz Specification is <150 Hz rms AM Residual (8210)	500 MHz at 1.5 GHz decreasing linearly	100 kHz to a floor of <5 Hz rms.	<10.0 mVrms
15 kHz Specification is <0.25% for in	500 MHz put level above 100 mV rms.	100 kHz	<50 mVrms
3 kHz Specification is <0.15% for in AM residuals increase linearly		100 kHz uencies above 520 MHz.	<30 mVrms

FM Residual (8210-01)

Low Pass Filter	Frequency	<u>Bandwidth</u>	<u>Limits</u>		
30 kHz Specification is <400 Hz rms	500 MHz at 1.5 GHz decreasing linearly	100 kHz to a floor of <25 Hz ms.	<26.6 mVrms		
3 kHz 500 MHz 100 kHz <10.0 mVrms Specification is <150 Hz rms at 1.5 GHz decreasing linearly to a floor of <5 Hz rms.					
AM Residual (8210-01)					
30 kHz Specification is <0.35% for in	500 MHz put level above 100 mV rms.	100 kHz	<70 mVrms		
3 kHz	500 MHz	100 kHz	<30 mVrms		

Specification is <0.15% for input level above 100 mV rms.

AM residuals increase linearly with frequency at carrier frequencies above 520 MHz.

#### 4.3 FM MODULATION DEVIATION ACCURACY CALIBRATION:

Audio Analyzer (Hz)	Signal Generator (Deviation kHz)	TISCALE	Modulation Analyzer (kHz)	TI Limits (kHz)
8210 1 k	100	100	100	99.0 to 101.0 *
50	100	100	100	99.0 to 101.0 *

See Footnotes at the end of the Table.

#### CALIBRATION PERFORMANCE TABLE (Cont.)

#### 4.3 FM MODULATION DEVIATION ACCURACY CALIBRATION; (Cont.)

Audio Analyzer (Hz)	Signal Generator (Deviation kHz)	TI SCALE	Modulation Analyzer (kHz)	TI Limits (kHz)
8210 (Cont.) 4.9 k	100	100	100	99.0 to 101.0 *
5.1 k	100	100	100	98.0 to 102.0 *
7.5 k	100	100	100	98.0 to 102.0 *
1 k	10	10	10	9.90 to 10.10 *
8210-01 1 k	100	100	100	99.0 to 101.0 *
50	100	100	100	99.0 to 101.0 *
5.0	100	100	100	99.0 to 101.0 *
7.5 k	100	100	100	99.0 to 101.0 *
9.9 k	100	100	100	99.0 to 101.0 *
10.1 k	100	100	100	98.0 to 102.0 *
15.0 k	100	100	100	98.0 to 102.0 *
l k	10	10	10	9.90 to 10.1 *

<sup>\*</sup> Peak residuals must be accounted for to obtain the listed Accuracy.

#### 4.4 AM REJECTION CALIBRATION:

AM Modulation Rate	AM Modulation Depth	<u>Limit</u> (Deviation)
l kHz	50%	<100 Hz Peak

#### 4.5 AM AUDIO DISTORTION CALIBRATION:

RF Frequency	Audio Analyzer	<u>Limits</u>
30 MHz 90% depth	Mod rate (Hz)	(<%)
	l kHz	0.5

#### CALIBRATION PERFORMANCE TABLE (Cont.)

#### 4.6 AUDIO FREQUENCY RESPONSE 15 kHz CALIBRATION:

	30 MHz 60% depth (8210)	Audio Analyzer Mod rate (Hz)	<u>Limits</u> (%)
(0210)	(0210)	50 to 5 kHz	54.9 to 60.6
		5 to 7.5 kHz	58.5 to 61.2
	(8210-01)	15.0 kHz	40.4 to 44.3
	(8210-01)	50 to 10 kHz	54.9 to 60.6
		10 to 15 kHz	58.5 to 61.2
		30 kHz	40.4 to 44.3
4.7 FM DISTOR	TION CALIBRATION:		
	RF Frequency 100 MHz 75 kHz dev	Audio Analyzer (Hz)	Limits (%)
		50	<0.25
		1 k	<0.25
		10 k	<0.25
4.8 FM REJECT	ION CALIBRATION:		

RF Frequency	<u>Audio</u>	<u>Limits</u>
100 MHz 100 kHz dev	Analyzer (kHz)	(AM%)
	1	<1.0

#### 4.9 AUDIO FREQUENCY RESPONSE 3 kHz LOW PASS FILTER CALIBRATION:

RF Frequency 100 MHz 100 kHz dev	Audio Analyzer (Hz)	Limits (DEV (kHz)
3 kHz Low Pass	300	100
	3000	67.5 to 73.8

#### 4.10 AUDIO FREQUENCY RESPONSE 750 µs DE-EMPHASIS CALIBRATION:

RF Frequency 100 MHz 100 kHz dev	<u>Audio</u> <u>Analyzer (Hz)</u>	<u>Limits</u> (DEV (kHz)
3 kHz Low Pass	212.2	100
750 µs De-emphasis	212.2	68.0 to 73.5

#### CALIBRATION PERFORMANCE TABLE (Cont.)

#### 4.11 AM MODULATION DEPTH ACCURACY CALIBRATION:

	Signal Generator	MOD%	Audio Analyzer (Hz)	Modulation Analyzer (%)	TI Limits (%)
82	10				
	30 MHz at +3 dBm	30	1 <b>k</b>	30	29.7 to 30.3 *
	30 MHz at +3 dBm	50	1 k	50	49.5 to 50.5 *
	30 MHz at +3 dBm	70	1 k	70	69.3 to 70.7 *
	30 MHz at +3 dBm	90	1 k	90	89.1 to 90.9 *
	30 MHz at +3 dBm	90	6 k	90	88.2 to 91.8 *
	30 MHz at +3 dBm	90	7.5 k	90	88.2 to 91.8 *
821	10-01				
	30 MHz at +3 dBm	30	1 k	30	29.7 to 30.3 *
	30 MHz at +3 dBm	50	1 k	50	49.5 to 50.5 *
	30 MHz at +3 dBm	70	1 k	70	69.3 to 70.7 *
	30 MHz at +3 dBm	90	1 k	90	89.1 to 90.9 *
	30 MHz at +3 dBm	90	9.9 k	90	89.1 to 90.9 *
	30 MHz at +3 dBm	90	10.1 k	90	88.2 to 91.8 *
	30 MHz at +3 dBm	90	15 k	90	88.2 to 91.8 *

<sup>\*</sup> Note: Peak residuals must be accounted for to obtain the listed Accuracy.

## WARRANTY

Boonton Electronics Corporation warrants its products to the original purchaser to be free from defects in material and workmanship and to operate within applicable specifications for a period of one year from date of shipment, provided they are used under normal operating conditions. This warranty does not apply to active devices that have given normal service, to sealed assemblies which have been opened or to any item which has been repaired or altered without our authorization.

We will repair, or at our option, replace any of our products which are found to be defective under the terms of this warranty.

There will be no charge for parts, labor, or forward and return normal ground transportation during the first three months of this warranty.\*

There will be no charge for parts, labor, or return normal ground transportation during the fourth through twelfth month of this warranty.\*

Except for such repair or replacement, we will not be liable for any incidental damages or for any consequential damages, as those terms are defined in Section 2-715 of the Uniform Commercial Code, in connection with products covered by this warranty.

\*For overseas shipments, there will be no charge for Air Freight during these specified time periods.

### BOONTON

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